

# RENESAS TECHNICAL UPDATE

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Product Category	MPU/MCU		Document No.	TN-RL*-A005A/E	Rev.	1.00
Title	Correction for Incorrect Description Notice RL78/G13 Descriptions in the Hardware User's Manual Rev. 2.10 Changed		Information Category	Technical Notification		
Applicable Product	RL78/G13 R5F100xxx, R5F101xxx	Lot No.	Reference Document	RL78/G13 User's Manual: Hardware Rev.2.10 R01UH0146EJ0210 (Sep. 2012)		
		All lots				

This document describes misstatements found in the RL78/G13 User's Manual: Hardware Rev.2.10 (R01UH0146EJ0210).

## Corrections

Applicable Item	Applicable Page	Contents
3.1.3 Internal data memory space	Page 111	Specifications extended
12. 6. 3 SNOOZE mode function	Pages 658	Specifications changed
18.3.2 STOP mode	Pages 868 and 869	Incorrect descriptions revised
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22.3.6 Invalid memory access detection function	Page 920	Incorrect descriptions revised
Figure 24-3 Format of Option Byte (000C2H/010C2H)	Page 934	Specifications extended
29.3.1 Pin characteristics	Pages 993 and 994	Incorrect descriptions revised
29.3.2 Supply current characteristics	Pages 998 to 1010	Incorrect descriptions revised
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Supply Voltage Rise Time	Page 1045	Specifications added
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Chapter 30 ELECTRICAL SPECIFICATIONS (G: T <sub>A</sub> = -40 to +105°C) (TARGET)	Pages 1048 to 1098	Specifications fixed

## Document Improvement

The above corrections will be made for the next revision of the User's Manual: Hardware.

# Corrections in the User's Manual: Hardware

No.	Corrections and Applicable Items			Pages in this document for corrections
	Document No.	English	R01UH0146EJ0210	
1	3.1.3 Internal data memory space		Page 111	Page 3
2	12. 6. 3 SNOOZE mode function		Pages 658	Pages 4 and 5
3	18.3.2 STOP mode		Pages 868 and 869	Page 6
4	18.3.3 SNOOZE mode		Page 871	Page 7
5	22.3.6 Invalid memory access detection function		Page 920	Pages 8 and 9
6	Figure 24-3 Format of Option Byte (000C2H/010C2H)		Page 934	Page 10
7	29.3.1 Pin characteristics		Pages 993 and 994	Page 11
8	29.3.2 Supply current characteristics		Pages 998 to 1010	Page 11
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12	29.6.1 A/D converter characteristics		Pages 1038 to 1041	Page 11
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15	Supply Voltage Rise Time		Page 1045	Page 12
16	29.7 Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics		Page 1046	Page 12
17	Chapter 30 ELECTRICAL SPECIFICATIONS (G: T <sub>A</sub> = -40 to +105°C) (TARGET)		Pages 1048 to 1098	Page 12

Incorrect: Bold with underline: Correct: Gray hatched

## **Revision History**

RL78/G13 User's Manual: Hardware Rev.2.10 Correction for Incorrect Description Notice

Document Number	Date	Description
TN-RL*-A005A/E	Mar. 15, 2013	First edition issued No.1 to 17 in corrections (This notice)

### 1. 3.1.3 Internal Data Memory Space

#### Incorrect:

**Cautions 2.** The internal RAM in the following products cannot be used as stack area when using the self-programming function and data flash function.

R5F100xA, R5F101xA (x = 6 to 8, A to C, E to G)	: FFE20H to FFEDEFH
R5F100xC, R5F101xC (x = 6 to 8, A to C, E to G, J, L)	: FFE20H to FFEDEFH
R5F100xD, R5F101xD (x = 6 to 8, A to C, E to G, J, L)	: FFE20H to FFEDEFH, FF300H to FF309H
R5F100xE, R5F101xE (x = 6 to 8, A to C, E to G, J, L)	: FFE20H to FFEDEFH, FEF00H to FF309H
R5F100xF, R5F101xF (x = A to C, E to G, J, L, M, P)	: FFE20H to FFEDEFH
R5F100xG, R5F101xG (x = A to C, E to G, J, L, M, P)	: FFE20H to FFEDEFH
R5F100xH, R5F101xH (x = E to G, J, L, M, P, S)	: FFE20H to FFEDEFH
R5F100xJ, R5F101xJ (x = F, G, J, L, M, P)	: FFE20H to FFEDEFH, FAF00H to FB309H
R5F100xK, R5F101xK (x = F, G, J, L, M, P, S)	: FFE20H to FFEDEFH
R5F100xL, R5F101xL (x = F, G, J, L, M, P, S)	: FFE20H to FFEDEFH, F7F00H to F8309H

#### Correct:

**Cautions 2.** While self-programming is being executed or the data flash being rewriting, do not allocate the RAM address which is used in stack, data buffer, the branch of vectored interrupt servicing, or the transfer destination or source by DMA in the address between FFE20H to FFEDEFH.

**3.** The RAM area in the products listed below cannot be used when using the self-programming function or rewriting the data flash, because they are used by libraries.

R5F100xD, R5F101xD (x = 6 to 8, A to C, E to G, J, L)	: FF300H to FF309H
R5F100xE, R5F101xE (x = 6 to 8, A to C, E to G, J, L)	: FEF00H to FF309H
R5F100xJ, R5F101xJ (x = F, G, J, L, M, P)	: FAF00H to FB309H
R5F100xL, R5F101xL (x = F, G, J, L, M, P, S)	: F7F00H to F8309H

## 2. 12.6.3 SNOOZE mode function

### Incorrect:

SNOOZE mode makes UART operate reception by RxDq pin input detection while the STOP mode. Normally UART stops communication in the STOP mode. But, using the SNOOZE mode makes reception UART operate unless the CPU operation by detecting RxDq pin input. Only following channels can be set to the SNOOZE mode.

- **24 to 64-pin products: UART0**
- 80 to 128-pin products: UART0 and UART2

When using the SNOOZE mode function, set the SWCm bit of serial standby control register m (SSCm) to 1 just before switching to the STOP mode.

Cautions: 1. The SNOOZE mode can only be specified when the high-speed on-chip oscillator clock is selected for f<sub>CLK</sub>.  
**2. The maximum transfer rate when using UARTq in the SNOOZE mode is 9600 bps.**

### Correct:

SNOOZE mode makes UART operate reception by RxDq pin input detection while the STOP mode. Normally UART stops communication in the STOP mode. But, using the SNOOZE mode makes reception UART operate unless the CPU operation by detecting RxDq pin input. Only following channels can be set to the SNOOZE mode.

- **20 to 64-pin products: UART0**
- 80 to 128-pin products: UART0 and UART2

**When using UARTq in SNOOZE mode, execute the following settings before entering STOP mode (Refer to Flowcharts of SNOOZE mode operation in Figure 12-93 and Figure 12-95).**

- **In SNOOZE mode, UART reception baud rate must be set differently from normal operation. Refer to Table 12-3 to set registers SPSm and SDRmn [15:9].**
- **Set bits EOCmn and SSECmn to enable or disable the error interrupt (INTSRE0) when a communication error occurs.**
- **Set the SWCm bit in the serial standby control register m (SSCm) to 1 just before entering STOP mode. After initialization, set the SSm1 bit to 1 in the serial channel start register m (SSm).**

**When the MCU detects the RxDq pin edge input (input the start bit) after entering STOP mode, the UART reception is started.**

Cautions: 1. The SNOOZE mode can only be specified when the high-speed on-chip oscillator clock (f<sub>IH</sub>) is selected for f<sub>CLK</sub>.  
**2. The transfer rate in SNOOZE mode is 4800 bps only.**  
**3. When the SWCm bit is 1, UARTq can be used only when the reception is started in STOP mode. If UARTq is used with other SNOOZE function or interrupts concurrently and the reception is started in state other than STOP mode as described below, the UARTq cannot receive data correctly and may cause a framing error or parity error.**

- **The case the UARTq reception is started from the moment the SWCm bit is set to 1 before the MCU enters STOP mode**
- **The case the UARTq reception is started in SNOOZE mode**
- **The case the UARTq reception is started from the moment the MCU exits STOP mode and enters normal mode using interrupts before the SWCm bit is set to 0**

4. When the SSECm bit is 1, if a parity error, framing error, or overrun error occurs, flags PEFmn, FEFmn, or OVFMn is not set, nor an error interrupt (INTSREq) is generated. To set the SSECm bit to 1, clear flags PEFmn, FEFmn, and OVFMn before setting the SWC0 bit to 1, and read bits 7 to 0 (RxDq) in the SDRm1 register.

Table 12-3 UART Reception Baud Rate Setting in SNOOZE Mode

High-speed on-chip oscillator (f <sub>IH</sub> )	UART reception baud rate in SNOOZE mode			
	Baud rate: 4800 bps			
	Operating clock (f <sub>MCK</sub> )	SDRmn [15:9]	Maximum acceptable value	Minimum acceptable value
32 MHz ± 1.0% <sup>(note)</sup>	f <sub>CLK</sub> / 2 <sup>5</sup>	105	2.27%	-1.53%
24 MHz ± 1.0% <sup>(note)</sup>	f <sub>CLK</sub> / 2 <sup>5</sup>	79	1.60%	-2.18%
16 MHz ± 1.0% <sup>(note)</sup>	f <sub>CLK</sub> / 2 <sup>4</sup>	105	2.27%	-1.53%
12 MHz ± 1.0% <sup>(note)</sup>	f <sub>CLK</sub> / 2 <sup>4</sup>	79	1.60%	-2.19%
8 MHz ± 1.0% <sup>(note)</sup>	f <sub>CLK</sub> / 2 <sup>3</sup>	105	2.27%	-1.53%
6 MHz ± 1.0% <sup>(note)</sup>	f <sub>CLK</sub> / 2 <sup>3</sup>	79	1.60%	-2.19%
4 MHz ± 1.0% <sup>(note)</sup>	f <sub>CLK</sub> / 2 <sup>2</sup>	105	2.27%	-1.53%
3 MHz ± 1.0% <sup>(note)</sup>	f <sub>CLK</sub> / 2 <sup>2</sup>	79	1.60%	-2.19%
2 MHz ± 1.0% <sup>(note)</sup>	f <sub>CLK</sub> / 2 <sup>1</sup>	105	2.27%	-1.54%
1 MHz ± 1.0% <sup>(note)</sup>	f <sub>CLK</sub> / 2 <sup>0</sup>	105	2.27%	-1.57%

**Note:** When the high-speed on-chip oscillator clock accuracy is at ± 1.5% or 2.0%, the acceptable range is limited as follows:

- f<sub>IH</sub> ± 1.5%: Subtract 0.5% from the maximum acceptable value of f<sub>IH</sub> ± 1.0%, and add 0.5% to the minimum acceptable value of f<sub>IH</sub> ± 1.0%.
- f<sub>IH</sub> ± 2.0%: Subtract 1.0% from the maximum acceptable value of f<sub>IH</sub> ± 1.0%, and add 1.0% to the minimum acceptable value of f<sub>IH</sub> ± 1.0%.

**Remarks:** Maximum and minimum acceptable values in the above table are the baud rate acceptable values in UART reception. Make sure to set the baud rate for transmission within this range.

### 3. 18.3.2 STOP mode

**Incorrect:**

Figure 18-5 STOP Mode Release by Interrupt Request Generation (1/2)

(1) When high-speed system clock (X1 oscillation) is used as CPU clock  
(omitted)

Notes: 2. STOP mode release time

**Supply of the clock is stopped: 18.96  $\mu$ s to "whichever is longer 28.95  $\mu$ s and the oscillation stabilization time (set by OSTS)"**

Wait

- When vectored interrupt servicing is carried out: 10 to 11 clocks
- When vectored interrupt servicing is not carried out: 4 to 5 clocks

(2) When high-speed system clock (external clock input) is used as CPU clock

(3) When high-speed on-chip oscillator clock is used as CPU clock  
(omitted)

Notes: 2. STOP mode release time

**Supply of the clock is stopped: 19.08 to 32.99  $\mu$ s**

Wait

- When vectored interrupt servicing is carried out: 7 clocks
- When vectored interrupt servicing is not carried out: 1 clock

**Correct:**

Figure 18-5 STOP Mode Release by Interrupt Request Generation (1/2)

(1) When high-speed system clock (X1 oscillation) is used as CPU clock  
(omitted)

Notes: 2. STOP mode release time

**Supply of the clock is stopped: 18  $\mu$ s to "whichever is longer 65  $\mu$ s or the oscillation stabilization time (set by OSTS)"**

Wait

- When vectored interrupt servicing is carried out: 10 to 11 clocks
- When vectored interrupt servicing is not carried out: 4 to 5 clocks

**Remark: The time to stop clock supply varies depending on the temperature conditions and STOP mode time.**

(2) When high-speed system clock (external clock input) is used as CPU clock

(3) When high-speed on-chip oscillator clock is used as CPU clock  
(omitted)

Notes: 2. STOP mode release time

**Supply of the clock is stopped: 18 to 65  $\mu$ s**

Wait

- When vectored interrupt servicing is carried out: 7 clocks
- When vectored interrupt servicing is not carried out: 1 clock

**Remark: The time to stop clock supply varies depending on the temperature conditions and STOP mode time.**

#### 4. 18.3.3 SNOOZE Mode

Incorrect:

In SNOOZE mode transition, wait status to be only following time.  
From STOP to SNOOZE

HS (High-speed main) mode: 18.96 to 28.95  $\mu$ s

LS (Low-speed main) mode: 20.24 to 28.95  $\mu$ s

LV (Low-voltage main) mode: 20.98 to 28.95  $\mu$ s

From SNOOZE to normal operation

- When vectored interrupt servicing is carried out:  
HS (High-speed main) mode: 6.79 to 12.4  $\mu$ s + 7 clocks  
LS (Low-speed main) mode: 2.58 to 7.8  $\mu$ s + 7 clocks  
LV (Low-voltage main) mode: 12.45 to 17.3  $\mu$ s + 7 clocks
- When vectored interrupt servicing is not carried out:  
HS (High-speed main) mode: 6.79 to 12.4  $\mu$ s + 7 clocks  
LS (Low-speed main) mode: 2.58 to 7.8  $\mu$ s + 1 clock  
LV (Low-voltage main) mode: 12.45 to 17.3  $\mu$ s + 1 clock

Correct:

The MCU transits from STOP mode to SNOOZE mode or from SNOOZE mode to normal operation after time shown below elapses.

Transit time from STOP mode to SNOOZE mode: 18 to 65  $\mu$ s

Remark: The transit time from STOP mode to SNOOZE mode varies depending on the temperature conditions and STOP mode time.

Transit time from SNOOZE mode to normal operation:

- When vectored interrupt servicing is carried out:  
HS (High-speed main) mode : "4.99 to 9.44  $\mu$ s" + 7 clocks  
LS (Low-speed main) mode : "1.10 to 5.08  $\mu$ s" + 7 clocks  
LV (Low-voltage main) mode : "16.58 to 25.40  $\mu$ s" + 7 clocks
- When vectored interrupt servicing is not carried out:  
HS (High-speed main) mode : "4.99 to 9.44  $\mu$ s" + 1 clock  
LS (Low-speed main) mode : "1.10 to 5.08  $\mu$ s" + 1 clock  
LV (Low-voltage main) mode : "16.58 to 25.40  $\mu$ s" + 1 clock

5. 22.3.6 Invalid memory access detection function

Incorrect:

Figure 22-10 Invalid access detection area

		Possibility access		Fetching instructions (execute)	
		Read	Write		
FFFFFH	Special function register (SFR) 256 byte	OK	OK	NG	
FFF00H FFEFH	General-purpose register 32 byte			OK	
FFEE0H FFEDFH	RAM <sup>Note</sup>		OK		
yyyyyH	Mirror		NG	NG	
F1000H F0FFFH	Data flash memory		OK	OK	
F0800H F07FFH	Reserved			NG	
F0000H EFFFFH	Special function register (2nd SFR) 2 Kbyte		NG	OK	
EF000H EEFFFH				NG	
Reserved				NG	
xxxxxH				OK	OK
Code flash memory <sup>Note</sup>					
00000H					

Correct:

Figure 22-10 Invalid access detection area

		Read		Write		Instruction fetch (execution)		
FFFFFH	Special function register (SFR) 256 bytes	OK	OK	OK	NG	NG		
FFF00H FFEFH	General-purpose register 32 bytes							
FFEE0H FFEDFH								
	RAM <sup>Note</sup>					OK		
zzzzzH								
≈	Mirror			≈			NG	NG
	Data flash memory					NG		
F1000H F0FFFH								
	Reserved							OK
F0800H F07FFH							OK	
	Special function register (2nd SFR) 2 Kbytes							NG
F0000H EFFFFH								
EF000H EEFFFH								OK
				</				



Note: Code flash memory and RAM address of each product are as follows.

Products	Code flash memory (00000H to xxxxxH)	RAM (yyyyyH to FFEFFH)
R5F100xA, R5F101xA (x = 6 to 8, A to C, E to G)	16384 × 8 bit (00000H to 03FFFFH)	2048 × 8 bit (FF700H to FFEFFH)
R5F100xC, R5F101xC (x = 6 to 8, A to C, E to G, J, L)	32768 × 8 bit (00000H to 07FFFFH)	2048 × 8 bit (FF700H to FFEFFH)
R5F100xD, R5F101xD (x = 6 to 8, A to C, E to G, J, L)	49152 × 8 bit (00000H to 0BFFFFH)	3072 × 8 bit (FF300H to FFEFFH)
R5F100xE, R5F101xE (x = 6 to 8, A to C, E to G, J, L)	65536 × 8 bit (00000H to 0FFFFH)	4096 × 8 bit (FEF00H to FFEFFH)
R5F100xF, R5F101xF (x = A to C, E to G, J, L, M, P)	98304 × 8 bit (00000H to 17FFFFH)	8192 × 8 bit (FDF00H to FFEFFH)
R5F100xG, R5F101xG (x = A to C, E to G, J, L, M, P)	131072 × 8 bit (00000H to 1FFFFH)	12288 × 8 bit (FCF00H to FFEFFH)
R5F100xH, R5F101xH (x = E to G, J, L, M, P, S)	196608 × 8 bit (00000H to 2FFFFH)	16384 × 8 bit (FBF00H to FFEFFH)
R5F100xJ, R5F101xJ (x = F, G, J, L, M, P, S)	262144 × 8 bit (00000H to 3FFFFH)	20480 × 8 bit (FAF00H to FFEFFH)
R5F100xK, R5F101xK (x = F, G, J, L, M, P, S)	393216 × 8 bit (00000H to 5FFFFH)	24576 × 8 bit (F9F00H to FFEFFH)
R5F100xL, R5F101xL (x = F, G, J, L, M, P, S)	524288 × 8 bit (00000H to 7FFFFH)	32768 × 8 bit (F7F00H to FFEFFH)

Note: Code flash memory area, RAM area, and the detected lowest address of each product are as follows.

Products	Code flash memory (00000H to xxxxxH)	RAM (zzzzzH to FFEFFH)	Detected lowest address for read/instruction fetch (execution) (yyyyyH)
R5F100xA, R5F101xA (x = 6 to 8, A to C, E to G)	16384 × 8 bit (00000H to 03FFFFH)	2048 × 8 bit (FF700H to FFEFFH)	10000H
R5F100xC, R5F101xC (x = 6 to 8, A to C, E to G, J, L)	32768 × 8 bit (00000H to 07FFFFH)	2048 × 8 bit (FF700H to FFEFFH)	10000H
R5F100xD, R5F101xD (x = 6 to 8, A to C, E to G, J, L)	49152 × 8 bit (00000H to 0BFFFFH)	3072 × 8 bit (FF300H to FFEFFH)	10000H
R5F100xE, R5F101xE (x = 6 to 8, A to C, E to G, J, L)	65536 × 8 bit (00000H to 0FFFFH)	4096 × 8 bit (FEF00H to FFEFFH)	10000H
R5F100xF, R5F101xF (x = A to C, E to G, J, L, M, P)	98304 × 8 bit (00000H to 17FFFFH)	8192 × 8 bit (FDF00H to FFEFFH)	20000H
R5F100xG, R5F101xG (x = A to C, E to G, J, L, M, P)	131072 × 8 bit (00000H to 1FFFFH)	12288 × 8 bit (FCF00H to FFEFFH)	20000H
R5F100xH, R5F101xH (x = E to G, J, L, M, P, S)	196608 × 8 bit (00000H to 2FFFFH)	16384 × 8 bit (FBF00H to FFEFFH)	30000H
R5F100xJ, R5F101xJ (x = F, G, J, L, M, P, S)	262144 × 8 bit (00000H to 3FFFFH)	20480 × 8 bit (FAF00H to FFEFFH)	40000H
R5F100xK, R5F101xK (x = F, G, J, L, M, P, S)	393216 × 8 bit (00000H to 5FFFFH)	24576 × 8 bit (F9F00H to FFEFFH)	60000H
R5F100xL, R5F101xL (x = F, G, J, L, M, P, S)	524288 × 8 bit (00000H to 7FFFFH)	32768 × 8 bit (F7F00H to FFEFFH)	80000H

# 6. Figure 24-3 Format of Option Byte (000C2H/010C2H)

Old:

Figure 24-3 Format of Option Byte (000C2H/010C2H)

Address: 000C2H/010C2H<sup>note</sup>

7	6	5	4	3	2	1	0
CMODE1	C5MODE0	1	0	FRQSEL3	FRQSEL2	FRQSEL1	FRQSEL0

CMODE1	CMODE0	Setting of flash operation mode		
			Operating Frequency Range	Operating Voltage Range
0	0	LV (low voltage main) mode	1 to 4 MHz	1.6 to 5.5 V
1	0	LS (low speed main) mode	1 to 8 MHz	1.8 to 5.5 V
1	1	HS (high speed main) mode	1 to 16 MHz	2.4 to 5.5 V
			1 to 32 MHz	2.7 to 5.5 V
Other than above		Setting prohibited		

FRQSEL3	FRQSEL2	FRQSEL1	FRQSEL0	Frequency of the high-speed on-chip oscillator
1	0	0	0	32 MHz
0	0	0	0	24 MHz
1	0	0	1	16 MHz
0	0	0	1	12 MHz
1	0	1	0	8 MHz
1	0	1	1	4 MHz
1	1	0	1	1 MHz
Other than above				Setting prohibited

**Note:** Set the same value as 000C2H to 010C2H when the boot swap operation is used because 000C2H is replaced by 010C2H.

**Caution:** Be sure to set bit 5 to 1 and bit 4 to 0.

New:

Figure 24-3. Format of Option Byte (000C2H/010C2H)

Address: 000C2H/010C2H<sup>note</sup>

7	6	5	4	3	2	1	0
CMODE1	C5MODE0	1	0	FRQSEL3	FRQSEL2	FRQSEL1	FRQSEL0

CMODE1	CMODE0	Setting of flash operation mode		
			Operating Frequency Range	Operating Voltage Range
0	0	LV (low voltage main) mode	1 to 4 MHz	1.6 to 5.5 V
1	0	LS (low speed main) mode	1 to 8 MHz	1.8 to 5.5 V
1	1	HS (high speed main) mode	1 to 16 MHz	2.4 to 5.5 V
			1 to 32 MHz	2.7 to 5.5 V
Other than above		Setting prohibited		

FRQSEL3	FRQSEL2	FRQSEL1	FRQSEL0	Frequency of the high-speed on-chip oscillator
1	0	0	0	32 MHz
0	0	0	0	24 MHz
1	0	0	1	16 MHz
0	0	0	1	12 MHz
1	0	1	0	8 MHz
<b>0</b>	<b>0</b>	<b>1</b>	<b>0</b>	<b>6 MHz</b>
1	0	1	1	4 MHz
<b>0</b>	<b>0</b>	<b>1</b>	<b>1</b>	<b>3 MHz</b>
<b>1</b>	<b>1</b>	<b>0</b>	<b>0</b>	<b>2 MHz</b>
1	1	0	1	1 MHz
Other than above				Setting prohibited

**Note:** Set the same value as 000C2H to 010C2H when the boot swap operation is used because 000C2H is replaced by 010C2H.

**Caution:** Be sure to set bit 5 to 1 and bit 4 to 0.

7. 29.3.1 Pin characteristics

**Incorrect:**

Fixed typo in Note 3 in pages 993 and 994

8. 29.3.2 Supply current characteristics

**Incorrect:**

Fixed typo in Notes and typical values of IDD2 and IDD3 in pages 998 to 1010

9. 29.4 AC Characteristics

**Old:**

Specifications of the external system clock frequency and external system clock input high-level width, low-level width in page 1011 extended

10. 29.5.1 Serial array unit

**Incorrect:**

Fixed typo in 29.5.1 Serial array unit in pages 1014 to 1036

11. 29.5.2 Serial Interface IICA

**Incorrect:**

Fixed typo in 29.5.2 Serial interface IICA in page 1037

12. 29.6.1 A/D converter characteristics

**Old:**

Specifications of "29.6.1 A/D converter characteristics" in pages 1038 to 1041 extended

13. 29.6.2 Temperature Sensor/Internal Reference Voltage Characteristics

**Incorrect:**

Fixed typo in 29.6.2 Temperature Sensor/Internal Reference Voltage Characteristics in page 1042

14. 29.6.3 POR circuit characteristics

**Incorrect:**

Fixed typo in 29.6.3 POR circuit characteristics in page 1042

**Correct:**

Refer to pages 6 and 7 in Technical Update Exhibit "Chapter 29 ELECTRICAL SPECIFICATIONS (A, D: T<sub>A</sub> = -40 to + 85°C)" (MCYG-AB-12-0384).

**Correct:**

Refer to pages 11 to 24 in Technical Update Exhibit "Chapter 29 ELECTRICAL SPECIFICATIONS (A, D: T<sub>A</sub> = -40 to + 85°C)" (MCYG-AB-12-0384).

**New:**

Refer to page 25 in Technical Update Exhibit "Chapter 29 ELECTRICAL SPECIFICATIONS (A, D: T<sub>A</sub> = -40 to + 85°C)" (MCYG-AB-12-0384).

**Correct:**

Refer to pages 29 to 56 in Technical Update Exhibit "Chapter 29 ELECTRICAL SPECIFICATIONS (A, D: T<sub>A</sub> = -40 to + 85°C)" (MCYG-AB-12-0384).

**Correct:**

Refer to pages 57 to 60 in Technical Update Exhibit "Chapter 29 ELECTRICAL SPECIFICATIONS (A, D: T<sub>A</sub> = -40 to + 85°C)" (MCYG-AB-12-0384).

**New:**

Refer to pages 61 to 65 in Technical Update Exhibit "Chapter 29 ELECTRICAL SPECIFICATIONS (A, D: T<sub>A</sub> = -40 to + 85°C)" (MCYG-AB-12-0384).

**Correct:**

Refer to page 66 in Technical Update Exhibit "Chapter 29 ELECTRICAL SPECIFICATIONS (A, D: T<sub>A</sub> = -40 to + 85°C)" (MCYG-AB-12-0384).

**Correct:**

Refer to page 66 in Technical Update Exhibit "Chapter 29 ELECTRICAL SPECIFICATIONS (A, D: T<sub>A</sub> = -40 to + 85°C)" (MCYG-AB-12-0384).

15. Supply Voltage Rise Time

**Old:**

Specifications in Supply Voltage Rise Time in page 1045 added

16. 29.7 Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics

**Old:**

Specifications in Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics in page 1046 extended

17. Chapter 30 ELECTRICAL SPECIFICATIONS (G:  $T_A = -40$  to  $+105^{\circ}\text{C}$ ) (TARGET)

**Old:**

Specifications in Chapter 30 ELECTRICAL SPECIFICATIONS (G:  $T_A = -40$  to  $+105^{\circ}\text{C}$ ) in pages 1048 to 1098 fixed

**New:**

Refer to page 68 in Technical Update Exhibit "Chapter 29 ELECTRICAL SPECIFICATIONS (A, D:  $T_A = -40$  to  $+85^{\circ}\text{C}$ )" (MCYG-AB-12-0384).

**New:**

Refer to page 69 in Technical Update Exhibit "Chapter 29 ELECTRICAL SPECIFICATIONS (A, D:  $T_A = -40$  to  $+85^{\circ}\text{C}$ )" (MCYG-AB-12-0384).

**New:**

Refer to pages 2 to 54 in Technical Update Exhibit "Chapter 30 ELECTRICAL SPECIFICATIONS (G:  $T_A = -40$  to  $+105^{\circ}\text{C}$ )" (MCYG-AB-12-0385).

To our valued customers:	<p>RL78/G13 Technical Update Exhibit Chapter 29 ELECTRICAL SPECIFICATIONS (A, D: T<sub>A</sub> = -40 to +85°C)</p>	M C Y G - A B - 1 2 - 0 3 8 4 - 1
		March 15, 2013
		<p>Hiroshi Uchimura Manager 1<sup>st</sup> Solution Business Unit 3<sup>rd</sup> MCU Business Division Brand Strategy Department Renesas Electronics Corporation</p>

(Rep. Seiya Indo)

Thank you for your continued support for Renesas Electronics products.

Please be advised that the misstatements found in the following User's Manual have been fixed.

The second and following pages in this document include "Chapter 29 ELECTRICAL SPECIFICATIONS (A, D: T<sub>A</sub> = -40 to +85°C)" which has been updated by the Correction for incorrect description notice RL78/G13 Descriptions in the User's Manual: Hardware Rev.2.10 changed (TN-RL\*-A005A/E).

1. Applicable products:

**RL78/G13**

R5F100xxA, R5F101xxA

R5F100xxD, R5F101xxD

2. Reference documents:

Correction for incorrect description notice RL78/G13 Descriptions in the User's Manual:  
Hardware Rev.2.10 changed (TN-RL\*-A005A/E)

RL78/G13 User's Manual: Hardware Rev.2.10 (R01UH0146EJ0210)

## CHAPTER 29 ELECTRICAL SPECIFICATIONS (A, D: $T_A = -40$ to $+85^{\circ}\text{C}$ )

This chapter describes the electrical specifications for the products "A: Consumer applications ( $T_A = -40$  to  $+85^{\circ}\text{C}$ )" and "D: Industrial applications ( $T_A = -40$  to  $+85^{\circ}\text{C}$ )".

- Cautions**
1. The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.
  2. With products not provided with an  $\text{EV}_{\text{DD0}}$ ,  $\text{EV}_{\text{DD1}}$ ,  $\text{EV}_{\text{SS0}}$ , or  $\text{EV}_{\text{SS1}}$  pin, replace  $\text{EV}_{\text{DD0}}$  and  $\text{EV}_{\text{DD1}}$  with  $\text{V}_{\text{DD}}$ , or replace  $\text{EV}_{\text{SS0}}$  and  $\text{EV}_{\text{SS1}}$  with  $\text{V}_{\text{SS}}$ .
  3. The pins mounted depend on the product. Refer to 2.1 Port Function to 2.2.1 With functions for each product.

## 29.1 Absolute Maximum Ratings

### Absolute Maximum Ratings (T<sub>A</sub> = 25°C) (1/2)

Parameter	Symbols	Conditions	Ratings	Unit
Supply voltage	V <sub>DD</sub>		-0.5 to +6.5	V
	EV <sub>DD0</sub> , EV <sub>DD1</sub>	EV <sub>DD0</sub> = EV <sub>DD1</sub>	-0.5 to +6.5	V
	EV <sub>SS0</sub> , EV <sub>SS1</sub>	EV <sub>SS0</sub> = EV <sub>SS1</sub>	-0.5 to +0.3	V
REGC pin input voltage	V <sub>IREGC</sub>	REGC	-0.3 to +2.8 and -0.3 to V <sub>DD</sub> +0.3 <sup>Note 1</sup>	V
Input voltage	V <sub>I1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147	-0.3 to EV <sub>DD0</sub> +0.3 and -0.3 to V <sub>DD</sub> +0.3 <sup>Note 2</sup>	V
	V <sub>I2</sub>	P60 to P63 (N-ch open-drain)	-0.3 to +6.5	V
	V <sub>I3</sub>	P20 to P27, P121 to P124, P137, P150 to P156, EXCLK, EXCLKS, RESET	-0.3 to V <sub>DD</sub> +0.3 <sup>Note 2</sup>	V
Output voltage	V <sub>O1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	-0.3 to EV <sub>DD0</sub> +0.3 and -0.3 to V <sub>DD</sub> +0.3 <sup>Note 2</sup>	V
	V <sub>O2</sub>	P20 to P27, P150 to P156	-0.3 to V <sub>DD</sub> +0.3 <sup>Note 2</sup>	V
Analog input voltage	V <sub>AI1</sub>	ANI16 to ANI26	-0.3 to EV <sub>DD0</sub> +0.3 and -0.3 to AV <sub>REF</sub> (+) +0.3 <sup>Notes 2, 3</sup>	V
	V <sub>AI2</sub>	ANI0 to ANI14	-0.3 to V <sub>DD</sub> +0.3 and -0.3 to AV <sub>REF</sub> (+) +0.3 <sup>Notes 2, 3</sup>	V

**Notes 1.** Connect the REGC pin to V<sub>SS</sub> via a capacitor (0.47 to 1 μF). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.

**2.** Must be 6.5 V or lower.

**3.** Do not exceed AV<sub>REF</sub>(+) + 0.3 V in case of A/D conversion target pin.

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**Remarks 1.** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

**2.** AV<sub>REF</sub>(+) : + side reference voltage of the A/D converter.

**3.** V<sub>SS</sub> : Reference voltage

**Absolute Maximum Ratings (T<sub>A</sub> = 25°C) (2/2)**

Absolute Maximum Ratings (TA = 25 °C) (2/2)					
Parameter	Symbols	Conditions		Ratings	Unit
Output current, high	IOH1	Per pin	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	−40	mA
		Total of all pins −170 mA	P00 to P04, P07, P32 to P37, P40 to P47, P102 to P106, P120, P125 to P127, P130, P140 to P145	−70	mA
			P05, P06, P10 to P17, P30, P31, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100, P101, P110 to P117, P146, P147	−100	mA
	IOH2	Per pin	P20 to P27, P150 to P156	−0.5	mA
		Total of all pins		−2	mA
	Output current, low	IOL1	Per pin	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	40
Total of all pins 170 mA			P00 to P04, P07, P32 to P37, P40 to P47, P102 to P106, P120, P125 to P127, P130, P140 to P145	70	mA
			P05, P06, P10 to P17, P30, P31, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100, P101, P110 to P117, P146, P147	100	mA
IOL2		Per pin	P20 to P27, P150 to P156	1	mA
		Total of all pins		5	mA
Operating ambient temperature		TA	In normal operation mode		−40 to +85
	In flash memory programming mode				
Storage temperature	Tstg			−65 to +150	°C

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.



## 29.2 Oscillator Characteristics

### 29.2.1 X1, XT1 oscillator characteristics

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Parameter	Resonator	Conditions	MIN.	TYP.	MAX.	Unit
X1 clock oscillation frequency (f <sub>x</sub> ) <sup>Note</sup>	Ceramic resonator/ crystal resonator	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	1.0		20.0	MHz
		2.4 V ≤ V <sub>DD</sub> < 2.7 V	1.0		16.0	MHz
		1.8 V ≤ V <sub>DD</sub> < 2.4 V	1.0		8.0	MHz
		1.6 V ≤ V <sub>DD</sub> < 1.8 V	1.0		4.0	MHz
XT1 clock oscillation frequency (f <sub>x</sub> ) <sup>Note</sup>	Crystal resonator		32	32.768	35	kHz

**Note** Indicates only permissible oscillator frequency ranges. Refer to AC Characteristics for instruction execution time. Request evaluation by the manufacturer of the oscillator circuit mounted on a board to check the oscillator characteristics.

**Caution** Since the CPU is started by the high-speed on-chip oscillator clock after a reset release, check the X1 clock oscillation stabilization time using the oscillation stabilization time counter status register (OSTC) by the user. Determine the oscillation stabilization time of the OSTC register and the oscillation stabilization time select register (OSTS) after sufficiently evaluating the oscillation stabilization time with the resonator to be used.

**Remark** When using the X1 oscillator and XT1 oscillator, refer to 5.4 System Clock Oscillator.

### 29.2.2 On-chip oscillator characteristics

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Oscillators	Parameters	Conditions		MIN.	TYP.	MAX.	Unit
High-speed on-chip oscillator clock frequency <sup>Notes 1, 2</sup>	f <sub>IH</sub>			1		32	MHz
High-speed on-chip oscillator clock frequency accuracy		-20 to +85 °C	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	-1.0		+1.0	%
			1.6 V ≤ V <sub>DD</sub> < 1.8 V	-5.0		+5.0	%
		-40 to -20 °C	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	-1.5		+1.5	%
			1.6 V ≤ V <sub>DD</sub> < 1.8 V	-5.5		+5.5	%
Low-speed on-chip oscillator clock frequency	f <sub>IL</sub>				15		kHz
Low-speed on-chip oscillator clock frequency accuracy				-15		+15	%

**Notes 1.** High-speed on-chip oscillator frequency is selected by bits 0 to 3 of option byte (000C2H/010C2H) and bits 0 to 2 of HOCODIV register.

**2.** This indicates the oscillator characteristics only. Refer to AC Characteristics for instruction execution time.

## 29.3 DC Characteristics

### 29.3.1 Pin characteristics

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (1/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output current, high <sup>Note 1</sup>	I <sub>OH1</sub>	Per pin for P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		-10.0 <sup>Note 2</sup>	mA
		Total of P00 to P04, P07, P32 to P37, P40 to P47, P102 to P106, P120, P125 to P127, P130, P140 to P145 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		-55.0	mA
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V		-10.0	mA
			1.8 V ≤ EV <sub>DD0</sub> < 2.7 V		-5.0	mA
			1.6 V ≤ EV <sub>DD0</sub> < 1.8 V		-2.5	mA
		Total of P05, P06, P10 to P17, P30, P31, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100, P101, P110 to P117, P146, P147 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		-80.0	mA
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V		-19.0	mA
			1.8 V ≤ EV <sub>DD0</sub> < 2.7 V		-10.0	mA
			1.6 V ≤ EV <sub>DD0</sub> < 1.8 V		-5.0	mA
		Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )	1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		-135.0 <sup>Note 4</sup>	mA
	I <sub>OH2</sub>	Per pin for P20 to P27, P150 to P156	1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V		-0.1 <sup>Note 2</sup>	mA
		Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )	1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V		-1.5	mA

**Notes** 1. Value of current at which the device operation is guaranteed even if the current flows from the EV<sub>DD0</sub>, EV<sub>DD1</sub>, V<sub>DD</sub> pins to an output pin.

2. However, do not exceed the total current value.

3. Specification under conditions where the duty factor ≤ 70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (I<sub>OH</sub> × 0.7)/(n × 0.01)

<Example> Where n = 80% and I<sub>OH</sub> = -10.0 mA

$$\text{Total output current of pins} = (-10.0 \times 0.7)/(80 \times 0.01) \cong -8.7 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

4. The applied current for the products for industrial application (R5F100xxDxx, R5F101xxDxx) is -100 mA.

**Caution** P00, P02 to P04, P10 to P15, P17, P43 to P45, P50, P52 to P55, P71, P74, P80 to P82, P96, and P142 to P144 do not output high level in N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ E<sub>VDD0</sub> = E<sub>VDD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = E<sub>VSS0</sub> = E<sub>VSS1</sub> = 0 V) (2/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output current, low <sup>Note 1</sup>	I <sub>OL1</sub>	Per pin for P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147			20.0 <sup>Note 2</sup>	mA
		Per pin for P60 to P63			15.0 <sup>Note 2</sup>	mA
		Total of P00 to P04, P07, P32 to P37, P40 to P47, P102 to P106, P120, P125 to P127, P130, P140 to P145 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ E <sub>VDD0</sub> ≤ 5.5 V		70.0	mA
			2.7 V ≤ E <sub>VDD0</sub> < 4.0 V		15.0	mA
			1.8 V ≤ E <sub>VDD0</sub> < 2.7 V		9.0	mA
			1.6 V ≤ E <sub>VDD0</sub> < 1.8 V		4.5	mA
		Total of P05, P06, P10 to P17, P30, P31, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100, P101, P110 to P117, P146, P147 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ E <sub>VDD0</sub> ≤ 5.5 V		80.0	mA
			2.7 V ≤ E <sub>VDD0</sub> < 4.0 V		35.0	mA
			1.8 V ≤ E <sub>VDD0</sub> < 2.7 V		20.0	mA
			1.6 V ≤ E <sub>VDD0</sub> < 1.8 V		10.0	mA
		Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )			150.0	mA
	I <sub>OL2</sub>	Per pin for P20 to P27, P150 to P156			0.4 <sup>Note 2</sup>	mA
		Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )	1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V		5.0	mA

- Notes**
- Value of current at which the device operation is guaranteed even if the current flows from an output pin to the E<sub>VSS0</sub>, E<sub>VSS1</sub> and V<sub>SS</sub> pin.
  - However, do not exceed the total current value.
  - Specification under conditions where the duty factor ≤ 70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (I<sub>OL</sub> × 0.7)/(n × 0.01)

<Example> Where n = 80% and I<sub>OL</sub> = 10.0 mA

$$\text{Total output current of pins} = (10.0 \times 0.7)/(80 \times 0.01) \cong 8.7 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (3/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input voltage, high	V <sub>IH1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147	Normal input buffer	0.8EV <sub>DD0</sub>	EV <sub>DD0</sub>	V
	V <sub>IH2</sub>	P01, P03, P04, P10, P11, P13 to P17, P43, P44, P53 to P55, P80, P81, P142, P143	TTL input buffer 4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	2.2	EV <sub>DD0</sub>	V
			TTL input buffer 3.3 V ≤ EV <sub>DD0</sub> < 4.0 V	2.0	EV <sub>DD0</sub>	V
			TTL input buffer 1.6 V ≤ EV <sub>DD0</sub> < 3.3 V	1.5	EV <sub>DD0</sub>	V
	V <sub>IH3</sub>	P20 to P27, P150 to P156	0.7V <sub>DD</sub>		V <sub>DD</sub>	V
	V <sub>IH4</sub>	P60 to P63	0.7EV <sub>DD0</sub>		6.0	V
	V <sub>IH5</sub>	P121 to P124, P137, EXCLK, EXCLKS, RESET	0.8V <sub>DD</sub>		V <sub>DD</sub>	V
Input voltage, low	V <sub>IL1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147	Normal input buffer	0	0.2EV <sub>DD0</sub>	V
	V <sub>IL2</sub>	P01, P03, P04, P10, P11, P13 to P17, P43, P44, P53 to P55, P80, P81, P142, P143	TTL input buffer 4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	0.8	V
			TTL input buffer 3.3 V ≤ EV <sub>DD0</sub> < 4.0 V	0	0.5	V
			TTL input buffer 1.6 V ≤ EV <sub>DD0</sub> < 3.3 V	0	0.32	V
	V <sub>IL3</sub>	P20 to P27, P150 to P156	0		0.3V <sub>DD</sub>	V
	V <sub>IL4</sub>	P60 to P63	0		0.3EV <sub>DD0</sub>	V
	V <sub>IL5</sub>	P121 to P124, P137, EXCLK, EXCLKS, RESET	0		0.2V <sub>DD</sub>	V

**Caution** The maximum value of V<sub>IH</sub> of pins P00, P02 to P04, P10 to P15, P17, P43 to P45, P50, P52 to P55, P71, P74, P80 to P82, P96, and P142 to P144 is EV<sub>DD0</sub>, even in the N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ E<sub>VDD0</sub> = E<sub>VDD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = E<sub>VSS0</sub> = E<sub>VSS1</sub> = 0 V) (4/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output voltage, high	V <sub>OH1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	4.0 V ≤ E <sub>VDD0</sub> ≤ 5.5 V, I <sub>OH1</sub> = -10.0 mA	E <sub>VDD0</sub> - 1.5		V
			4.0 V ≤ E <sub>VDD0</sub> ≤ 5.5 V, I <sub>OH1</sub> = -3.0 mA	E <sub>VDD0</sub> - 0.7		V
			2.7 V ≤ E <sub>VDD0</sub> ≤ 5.5 V, I <sub>OH1</sub> = -2.0 mA	E <sub>VDD0</sub> - 0.6		V
			1.8 V ≤ E <sub>VDD0</sub> ≤ 5.5 V, I <sub>OH1</sub> = -1.5 mA	E <sub>VDD0</sub> - 0.5		V
			1.6 V ≤ E <sub>VDD0</sub> < 5.5 V, I <sub>OH1</sub> = -1.0 mA	E <sub>VDD0</sub> - 0.5		V
	V <sub>OH2</sub>	P20 to P27, P150 to P156	1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V, I <sub>OH2</sub> = -100 μA	V <sub>DD</sub> - 0.5		V
Output voltage, low	V <sub>OL1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	4.0 V ≤ E <sub>VDD0</sub> ≤ 5.5 V, I <sub>OL1</sub> = 20 mA		1.3	V
			4.0 V ≤ E <sub>VDD0</sub> ≤ 5.5 V, I <sub>OL1</sub> = 8.5 mA		0.7	V
			2.7 V ≤ E <sub>VDD0</sub> ≤ 5.5 V, I <sub>OL1</sub> = 3.0 mA		0.6	V
			2.7 V ≤ E <sub>VDD0</sub> ≤ 5.5 V, I <sub>OL1</sub> = 1.5 mA		0.4	V
			1.8 V ≤ E <sub>VDD0</sub> ≤ 5.5 V, I <sub>OL1</sub> = 0.6 mA		0.4	V
			1.6 V ≤ E <sub>VDD0</sub> < 5.5 V, I <sub>OL1</sub> = 0.3 mA		0.4	V
	V <sub>OL2</sub>	P20 to P27, P150 to P156	1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V, I <sub>OL2</sub> = 400 μA		0.4	V
	V <sub>OL3</sub>	P60 to P63	4.0 V ≤ E <sub>VDD0</sub> ≤ 5.5 V, I <sub>OL3</sub> = 15.0 mA		2.0	V
			4.0 V ≤ E <sub>VDD0</sub> ≤ 5.5 V, I <sub>OL3</sub> = 5.0 mA		0.4	V
			2.7 V ≤ E <sub>VDD0</sub> ≤ 5.5 V, I <sub>OL3</sub> = 3.0 mA		0.4	V
			1.8 V ≤ E <sub>VDD0</sub> ≤ 5.5 V, I <sub>OL3</sub> = 2.0 mA		0.4	V
			1.6 V ≤ E <sub>VDD0</sub> < 5.5 V, I <sub>OL3</sub> = 1.0 mA		0.4	V

**Caution** P00, P02 to P04, P10 to P15, P17, P43 to P45, P50, P52 to P55, P71, P74, P80 to P82, P96, and P142 to P144 do not output high level in N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ E<sub>VDD0</sub> = E<sub>VDD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = E<sub>VSS0</sub> = E<sub>VSS1</sub> = 0 V) (5/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit		
Input leakage current, high	I <sub>LIH1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147	V <sub>I</sub> = EV <sub>DD0</sub>		1	μA		
	I <sub>LIH2</sub>	P20 to P27, P137, P150 to P156, RESET	V <sub>I</sub> = V <sub>DD</sub>		1	μA		
	I <sub>LIH3</sub>	P121 to P124 (X1, X2, XT1, XT2, EXCLK, EXCLKS)	V <sub>I</sub> = V <sub>DD</sub>	In input port or external clock input	1	μA		
				In resonator connection	10	μA		
Input leakage current, low	I <sub>LIL1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147	V <sub>I</sub> = EV <sub>SS0</sub>		−1	μA		
	I <sub>LIL2</sub>	P20 to P27, P137, P150 to P156, RESET	V <sub>I</sub> = V <sub>SS</sub>		−1	μA		
	I <sub>LIL3</sub>	P121 to P124 (X1, X2, XT1, XT2, EXCLK, EXCLKS)	V <sub>I</sub> = V <sub>SS</sub>	In input port or external clock input	−1	μA		
				In resonator connection	−10	μA		
On-chip pll-up resistance	R <sub>U</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147	V <sub>I</sub> = EV <sub>SS0</sub> , In input port		10	20	100	kΩ

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

## 29.3.2 Supply current characteristics

## (1) Flash ROM: 16 to 64 KB of 20- to 64-pin products

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ E<sub>VDD0</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = E<sub>VSS0</sub> = 0 V) (1/2)

Parameter	Symbol	Conditions					MIN.	TYP.	MAX.	Unit
Supply current <sup>Note 1</sup>	I <sub>DD1</sub>	Operating mode	HS (high-speed main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 32 MHz <sup>Note 3</sup>	Basic operation	V <sub>DD</sub> = 5.0 V		2.1		mA
						V <sub>DD</sub> = 3.0 V		2.1		mA
					Normal operation	V <sub>DD</sub> = 5.0 V		4.6	7.0	mA
						V <sub>DD</sub> = 3.0 V		4.6	7.0	mA
				f <sub>IH</sub> = 24 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 5.0 V		3.7	5.5	mA
						V <sub>DD</sub> = 3.0 V		3.7	5.5	mA
				f <sub>IH</sub> = 16 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 5.0 V		2.7	4.0	mA
						V <sub>DD</sub> = 3.0 V		2.7	4.0	mA
			LS (low-speed main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 8 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 3.0 V		1.2	1.8	mA
						V <sub>DD</sub> = 2.0 V		1.2	1.8	mA
			LV (low-voltage main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 4 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 3.0 V		1.2	1.7	mA
						V <sub>DD</sub> = 2.0 V		1.2	1.7	mA
			HS (high-speed main) mode <sup>Note 5</sup>	f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		3.0	4.6	mA
						Resonator connection		3.2	4.8	mA
				f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		3.0	4.6	mA
						Resonator connection		3.2	4.8	mA
				f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		1.9	2.7	mA
						Resonator connection		1.9	2.7	mA
				f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		1.9	2.7	mA
						Resonator connection		1.9	2.7	mA
			LS (low-speed main) mode <sup>Note 5</sup>	f <sub>MX</sub> = 8 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		1.1	1.7	mA
						Resonator connection		1.1	1.7	mA
				f <sub>MX</sub> = 8 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 2.0 V	Normal operation	Square wave input		1.1	1.7	mA
						Resonator connection		1.1	1.7	mA
			Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> , T <sub>A</sub> = -40°C	Normal operation	Square wave input		4.1	4.9	μA
						Resonator connection		4.2	5.0	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> , T <sub>A</sub> = +25°C	Normal operation	Square wave input		4.1	4.9	μA
						Resonator connection		4.2	5.0	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> , T <sub>A</sub> = +50°C	Normal operation	Square wave input		4.2	5.5	μA
						Resonator connection		4.3	5.6	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> , T <sub>A</sub> = +70°C	Normal operation	Square wave input		4.3	6.3	μA
						Resonator connection		4.4	6.4	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> , T <sub>A</sub> = +85°C	Normal operation	Square wave input		4.6	7.7	μA
						Resonator connection		4.7	7.8	μA

(Notes and Remarks are listed on the next page.)

- Notes**
1. Total current flowing into V<sub>DD</sub> and EV<sub>DD0</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub> or V<sub>SS</sub>, EV<sub>SS0</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. When high-speed on-chip oscillator and subsystem clock are stopped.
  3. When high-speed system clock and subsystem clock are stopped.
  4. When high-speed on-chip oscillator and high-speed system clock are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation). However, not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
  5. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
    - HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$
    - $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$
    - LS (low-speed main) mode:  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }8\text{ MHz}$
    - LV (low-voltage main) mode:  $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }4\text{ MHz}$

- Remarks**
1. f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2. f<sub>IH</sub>: High-speed on-chip oscillator clock frequency
  3. f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
  4. Except subsystem clock operation, temperature condition of the TYP. value is T<sub>A</sub> = 25°C



**(1) Flash ROM: 16 to 64 KB of 20- to 64-pin products****(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = 0 V) (2/2)**

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit	
Supply current Note 1	I <sub>DD2</sub> Note 2	HALT mode	HS (high-speed main) mode Note 7	f <sub>IH</sub> = 32 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		0.54	1.63	mA	
					V <sub>DD</sub> = 3.0 V		0.54	1.63	mA	
				f <sub>IH</sub> = 24 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		0.44	1.28	mA	
					V <sub>DD</sub> = 3.0 V		0.44	1.28	mA	
				f <sub>IH</sub> = 16 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		0.40	1.00	mA	
					V <sub>DD</sub> = 3.0 V		0.40	1.00	mA	
			LS (low-speed main) mode Note 7	f <sub>IH</sub> = 8 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 3.0 V		260	530	μA	
					V <sub>DD</sub> = 2.0 V		260	530	μA	
			LV (low-voltage main) mode Note 7	f <sub>IH</sub> = 4 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 3.0 V		420	640	μA	
					V <sub>DD</sub> = 2.0 V		420	640	μA	
			HS (high-speed main) mode Note 7	f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		0.28	1.00	mA	
					Resonator connection		0.45	1.17	mA	
				f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		0.28	1.00	mA	
					Resonator connection		0.45	1.17	mA	
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		0.19	0.60	mA	
					Resonator connection		0.26	0.67	mA	
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		0.19	0.60	mA	
					Resonator connection		0.26	0.67	mA	
			LS (low-speed main) mode Note 7	f <sub>MX</sub> = 8 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		95	330	μA	
					Resonator connection		145	380	μA	
				f <sub>MX</sub> = 8 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 2.0 V	Square wave input		95	330	μA	
					Resonator connection		145	380	μA	
			Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> T <sub>A</sub> = −40°C	Square wave input		0.25	0.57	μA	
					Resonator connection		0.44	0.76	μA	
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> T <sub>A</sub> = +25°C	Square wave input		0.30	0.57	μA	
					Resonator connection		0.49	0.76	μA	
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> T <sub>A</sub> = +50°C	Square wave input		0.37	1.17	μA	
					Resonator connection		0.56	1.36	μA	
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> T <sub>A</sub> = +70°C	Square wave input		0.53	1.97	μA	
					Resonator connection		0.72	2.16	μA	
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> T <sub>A</sub> = +85°C	Square wave input		0.82	3.37	μA	
					Resonator connection		1.01	3.56	μA	
	I <sub>DD3</sub> <sup>Note 6</sup>	STOP mode <sup>Note 8</sup>	T <sub>A</sub> = −40°C					0.18	0.50	μA
			T <sub>A</sub> = +25°C					0.23	0.50	μA
			T <sub>A</sub> = +50°C					0.30	1.10	μA
			T <sub>A</sub> = +70°C					0.46	1.90	μA
			T <sub>A</sub> = +85°C					0.75	3.30	μA

(Notes and Remarks are listed on the next page.)

- Notes**
1. Total current flowing into  $V_{DD}$  and  $EV_{DD0}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$ ,  $EV_{DD0}$  or  $V_{SS}$ ,  $EV_{SS0}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. During HALT instruction execution by flash memory.
  3. When high-speed on-chip oscillator and subsystem clock are stopped.
  4. When high-speed system clock and subsystem clock are stopped.
  5. When high-speed on-chip oscillator and high-speed system clock are stopped. When  $RTCLPC = 1$  and setting ultra-low current consumption ( $AMPHS1 = 1$ ). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
  6. Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
  7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.  
HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$   
LS (low-speed main) mode:  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }8\text{ MHz}$   
LV (low-voltage main) mode:  $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }4\text{ MHz}$
  8. Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.

- Remarks 1.** f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
2. f<sub>IH</sub>: High-speed on-chip oscillator clock frequency
3. f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

**(2) Flash ROM: 96 to 256 KB of 30- to 100-pin products****(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (1/2)**

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit
Supply current <sup>Note 1</sup>	I <sub>DD1</sub>	Operating mode	HS (high-speed main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 32 MHz <sup>Note 3</sup>	Basic operation	V <sub>DD</sub> = 5.0 V		2.3	mA
						V <sub>DD</sub> = 3.0 V		2.3	mA
					Normal operation	V <sub>DD</sub> = 5.0 V		5.2	mA
						V <sub>DD</sub> = 3.0 V		5.2	mA
				f <sub>IH</sub> = 24 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 5.0 V		4.1	mA
						V <sub>DD</sub> = 3.0 V		4.1	mA
				f <sub>IH</sub> = 16 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 5.0 V		3.0	mA
						V <sub>DD</sub> = 3.0 V		3.0	mA
			LS (low-speed main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 8 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 3.0 V		1.3	mA
						V <sub>DD</sub> = 2.0 V		1.3	mA
			LV (low-voltage main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 4 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 3.0 V		1.3	mA
						V <sub>DD</sub> = 2.0 V		1.3	mA
			HS (high-speed main) mode <sup>Note 5</sup>	f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		3.4	mA
						Resonator connection		3.6	mA
				f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		3.4	mA
						Resonator connection		3.6	mA
				f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		2.1	mA
						Resonator connection		2.1	mA
				f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		2.1	mA
						Resonator connection		2.1	mA
			LS (low-speed main) mode <sup>Note 5</sup>	f <sub>MX</sub> = 8 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		1.2	mA
						Resonator connection		1.2	mA
				f <sub>MX</sub> = 8 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 2.0 V	Normal operation	Square wave input		1.2	mA
						Resonator connection		1.2	mA
			Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = -40°C	Normal operation	Square wave input		4.8	μA
						Resonator connection		4.9	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +25°C	Normal operation	Square wave input		4.9	μA
						Resonator connection		5.0	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +50°C	Normal operation	Square wave input		5.0	μA
						Resonator connection		5.1	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +70°C	Normal operation	Square wave input		5.2	μA
						Resonator connection		5.3	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +85°C	Normal operation	Square wave input		5.7	μA
						Resonator connection		5.8	μA

(Notes and Remarks are listed on the next page.)

- Notes**
1. Total current flowing into  $V_{DD}$ ,  $EV_{DD0}$ , and  $EV_{DD1}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$ ,  $EV_{DD0}$ , and  $EV_{DD1}$ , or  $V_{SS}$ ,  $EV_{SS0}$ , and  $EV_{SS1}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. When high-speed on-chip oscillator and subsystem clock are stopped.
  3. When high-speed system clock and subsystem clock are stopped.
  4. When high-speed on-chip oscillator and high-speed system clock are stopped. When  $AMPHS1 = 1$  (Ultra-low power consumption oscillation). However, not including the current flowing into the 12-bit interval timer and watchdog timer.
  5. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
    - HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$
    - LS (low-speed main) mode:  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }8\text{ MHz}$
    - LV (low-voltage main) mode:  $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }4\text{ MHz}$

- Remarks**
1.  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2.  $f_{IH}$ : High-speed on-chip oscillator clock frequency
  3.  $f_{SUB}$ : Subsystem clock frequency (XT1 clock oscillation frequency)
  4. Except subsystem clock operation, temperature condition of the TYP. value is  $T_A = 25^{\circ}\text{C}$

**(2) Flash ROM: 96 to 256 KB of 30- to 100-pin products****(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (2/2)**

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit	
Supply current Note 1	I <sub>DD2</sub> Note 2	HALT mode	HS (high-speed main) mode Note 7	f <sub>IH</sub> = 32 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		0.62	1.86	mA	
					V <sub>DD</sub> = 3.0 V		0.62	1.86	mA	
				f <sub>IH</sub> = 24 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		0.50	1.45	mA	
					V <sub>DD</sub> = 3.0 V		0.50	1.45	mA	
				f <sub>IH</sub> = 16 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		0.44	1.11	mA	
					V <sub>DD</sub> = 3.0 V		0.44	1.11	mA	
				LS (low-speed main) mode Note 7	f <sub>IH</sub> = 8 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 3.0 V		290	620	μA
						V <sub>DD</sub> = 2.0 V		290	620	μA
				LV (low-voltage main) mode Note 7	f <sub>IH</sub> = 4 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 3.0 V		440	680	μA
						V <sub>DD</sub> = 2.0 V		440	680	μA
			HS (high-speed main) mode Note 7	f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		0.31	1.08	mA	
					Resonator connection		0.48	1.28	mA	
					f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		0.31	1.08	mA
					Resonator connection		0.48	1.28	mA	
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		0.21	0.63	mA	
					Resonator connection		0.28	0.71	mA	
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		0.21	0.63	mA	
					Resonator connection		0.28	0.71	mA	
			LS (low-speed main) mode Note 7	f <sub>MX</sub> = 8 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		110	360	μA	
					Resonator connection		160	420	μA	
				f <sub>MX</sub> = 8 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 2.0 V	Square wave input		110	360	μA	
					Resonator connection		160	420	μA	
			Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> T <sub>A</sub> = −40°C	Square wave input		0.28	0.61	μA	
					Resonator connection		0.47	0.80	μA	
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> T <sub>A</sub> = +25°C	Square wave input		0.34	0.61	μA	
					Resonator connection		0.53	0.80	μA	
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> T <sub>A</sub> = +50°C	Square wave input		0.41	2.30	μA	
					Resonator connection		0.60	2.49	μA	
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> T <sub>A</sub> = +70°C	Square wave input		0.64	4.03	μA	
					Resonator connection		0.83	4.22	μA	
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> T <sub>A</sub> = +85°C	Square wave input		1.09	8.04	μA	
					Resonator connection		1.28	8.23	μA	
	I <sub>DD3</sub> <sup>Note 6</sup>	STOP mode <sup>Note 8</sup>	T <sub>A</sub> = −40°C					0.19	0.52	μA
			T <sub>A</sub> = +25°C					0.25	0.52	μA
			T <sub>A</sub> = +50°C					0.32	2.21	μA
			T <sub>A</sub> = +70°C					0.55	3.94	μA
			T <sub>A</sub> = +85°C					1.00	7.95	μA

(Notes and Remarks are listed on the next page.)

- Notes**
1. Total current flowing into  $V_{DD}$ ,  $EV_{DD0}$ , and  $EV_{DD1}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$ ,  $EV_{DD0}$ , and  $EV_{DD1}$ , or  $V_{SS}$ ,  $EV_{SS0}$ , and  $EV_{SS1}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. During HALT instruction execution by flash memory.
  3. When high-speed on-chip oscillator and subsystem clock are stopped.
  4. When high-speed system clock and subsystem clock are stopped.
  5. When high-speed on-chip oscillator and high-speed system clock are stopped. When  $RTCLPC = 1$  and setting ultra-low current consumption ( $AMPHS1 = 1$ ). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
  6. Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
  7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.  
HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$   
LS (low-speed main) mode:  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }8\text{ MHz}$   
LV (low-voltage main) mode:  $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }4\text{ MHz}$
  8. Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.

- Remarks 1.**  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
2.  $f_{IH}$ : High-speed on-chip oscillator clock frequency
3.  $f_{SUB}$ : Subsystem clock frequency (XT1 clock oscillation frequency)
4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is  $T_A = 25^{\circ}\text{C}$

**(3) 128-pin products, and flash ROM: 384 to 512 KB of 44- to 100-pin products****(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ E<sub>VDD0</sub> = E<sub>VDD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = E<sub>VSS0</sub> = E<sub>VSS1</sub> = 0 V) (1/2)**

Parameter	Symbol	Conditions					MIN.	TYP.	MAX.	Unit
Supply current <sup>Note 1</sup>	I <sub>DD1</sub>	Operating mode	HS (high-speed main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 32 MHz <sup>Note 3</sup>	Basic operation	V <sub>DD</sub> = 5.0 V		2.6		mA
						V <sub>DD</sub> = 3.0 V		2.6		mA
					Normal operation	V <sub>DD</sub> = 5.0 V		6.1	9.5	mA
						V <sub>DD</sub> = 3.0 V		6.1	9.5	mA
				f <sub>IH</sub> = 24 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 5.0 V		4.8	7.4	mA
						V <sub>DD</sub> = 3.0 V		4.8	7.4	mA
				f <sub>IH</sub> = 16 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 5.0 V		3.5	5.3	mA
						V <sub>DD</sub> = 3.0 V		3.5	5.3	mA
			LS (low-speed main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 8 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 3.0 V		1.5	2.3	mA
						V <sub>DD</sub> = 2.0 V		1.5	2.3	mA
			LV (low-voltage main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 4 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 3.0 V		1.5	2.0	mA
						V <sub>DD</sub> = 2.0 V		1.5	2.0	mA
			HS (high-speed main) mode <sup>Note 5</sup>	f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		3.9	6.1	mA
						Resonator connection		4.1	6.3	mA
					Normal operation	Square wave input		3.9	6.1	mA
						Resonator connection		4.1	6.3	mA
				f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		2.5	3.7	mA
						Resonator connection		2.5	3.7	mA
				f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		2.5	3.7	mA
						Resonator connection		2.5	3.7	mA
			LS (low-speed main) mode <sup>Note 5</sup>	f <sub>MX</sub> = 8 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		1.4	2.2	mA
						Resonator connection		1.4	2.2	mA
				f <sub>MX</sub> = 8 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 2.0 V	Normal operation	Square wave input		1.4	2.2	mA
						Resonator connection		1.4	2.2	mA
			Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = -40°C	Normal operation	Square wave input		5.4	6.5	μA
						Resonator connection		5.5	6.6	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +25°C	Normal operation	Square wave input		5.5	6.5	μA
						Resonator connection		5.6	6.6	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +50°C	Normal operation	Square wave input		5.6	9.4	μA
						Resonator connection		5.7	9.5	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +70°C	Normal operation	Square wave input		5.9	12.0	μA
						Resonator connection		6.0	12.1	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +85°C	Normal operation	Square wave input		6.6	16.3	μA
						Resonator connection		6.7	16.4	μA

(Notes and Remarks are listed on the next page.)

- Notes**
1. Total current flowing into V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, or V<sub>SS</sub>, EV<sub>SS0</sub>, and EV<sub>SS1</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. When high-speed on-chip oscillator and subsystem clock are stopped.
  3. When high-speed system clock and subsystem clock are stopped.
  4. When high-speed on-chip oscillator and high-speed system clock are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation). However, not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
  5. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
    - HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @1 MHz to 32 MHz
    - $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @1 MHz to 16 MHz
    - LS (low-speed main) mode:  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @1 MHz to 8 MHz
    - LV (low-voltage main) mode:  $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @1 MHz to 4 MHz

- Remarks**
1. f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2. f<sub>IH</sub>: High-speed on-chip oscillator clock frequency
  3. f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
  4. Except subsystem clock operation, temperature condition of the TYP. value is T<sub>A</sub> = 25°C



**(3) 128-pin products, and flash ROM: 384 to 512 KB of 44- to 100-pin products****(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (2/2)**

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit	
Supply current Note 1	I <sub>DD2</sub> Note 2	HALT mode	HS (high-speed main) mode Note 7	f <sub>IH</sub> = 32 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.62	1.89	mA	
					V <sub>DD</sub> = 3.0 V		0.62	1.89	mA	
				f <sub>IH</sub> = 24 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.50	1.48	mA	
					V <sub>DD</sub> = 3.0 V		0.50	1.48	mA	
				f <sub>IH</sub> = 16 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.44	1.12	mA	
					V <sub>DD</sub> = 3.0 V		0.44	1.12	mA	
			LS (low-speed main) mode Note 7	f <sub>IH</sub> = 8 MHz Note 4	V <sub>DD</sub> = 3.0 V		290	620	μA	
					V <sub>DD</sub> = 2.0 V		290	620	μA	
			LV (low-voltage main) mode Note 7	f <sub>IH</sub> = 4 MHz Note 4	V <sub>DD</sub> = 3.0 V		460	700	μA	
					V <sub>DD</sub> = 2.0 V		460	700	μA	
			HS (high-speed main) mode Note 7	f <sub>MX</sub> = 20 MHz Note 3, V <sub>DD</sub> = 5.0 V	Square wave input		0.31	1.14	mA	
					Resonator connection		0.48	1.34	mA	
				f <sub>MX</sub> = 20 MHz Note 3, V <sub>DD</sub> = 3.0 V	Square wave input		0.31	1.14	mA	
					Resonator connection		0.48	1.34	mA	
				f <sub>MX</sub> = 10 MHz Note 3, V <sub>DD</sub> = 5.0 V	Square wave input		0.21	0.68	mA	
					Resonator connection		0.28	0.76	mA	
				f <sub>MX</sub> = 10 MHz Note 3, V <sub>DD</sub> = 3.0 V	Square wave input		0.21	0.68	mA	
					Resonator connection		0.28	0.76	mA	
			LS (low-speed main) mode Note 7	f <sub>MX</sub> = 8 MHz Note 3, V <sub>DD</sub> = 3.0 V	Square wave input		110	390	μA	
					Resonator connection		160	450	μA	
				f <sub>MX</sub> = 8 MHz Note 3, V <sub>DD</sub> = 2.0 V	Square wave input		110	390	μA	
					Resonator connection		160	450	μA	
			Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = −40°C	Square wave input		0.31	0.66	μA	
					Resonator connection		0.50	0.85	μA	
				f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = +25°C	Square wave input		0.38	0.66	μA	
					Resonator connection		0.57	0.85	μA	
				f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = +50°C	Square wave input		0.47	3.49	μA	
					Resonator connection		0.66	3.68	μA	
				f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = +70°C	Square wave input		0.80	6.10	μA	
					Resonator connection		0.99	6.29	μA	
				f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = +85°C	Square wave input		1.52	10.46	μA	
					Resonator connection		1.71	10.65	μA	
	I <sub>DD3</sub> Note 6	STOP mode Note 8	T <sub>A</sub> = −40°C					0.19	0.54	μA
			T <sub>A</sub> = +25°C					0.26	0.54	μA
			T <sub>A</sub> = +50°C					0.35	3.37	μA
			T <sub>A</sub> = +70°C					0.68	5.98	μA
			T <sub>A</sub> = +85°C					1.40	10.34	μA

(Notes and Remarks are listed on the next page.)

- Notes**
1. Total current flowing into  $V_{DD}$ ,  $EV_{DD0}$ , and  $EV_{DD1}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$ ,  $EV_{DD0}$ , and  $EV_{DD1}$ , or  $V_{SS}$ ,  $EV_{SS0}$ , and  $EV_{SS1}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. During HALT instruction execution by flash memory.
  3. When high-speed on-chip oscillator and subsystem clock are stopped.
  4. When high-speed system clock and subsystem clock are stopped.
  5. When high-speed on-chip oscillator and high-speed system clock are stopped. When  $RTCLPC = 1$  and setting ultra-low current consumption ( $AMPHS1 = 1$ ). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
  6. Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
  7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
    - HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @1 MHz to 32 MHz
    - $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @1 MHz to 16 MHz
    - LS (low-speed main) mode:  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @1 MHz to 8 MHz
    - LV (low-voltage main) mode:  $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @1 MHz to 4 MHz
  8. Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.

- Remarks 1.**  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
2.  $f_{IH}$ : High-speed on-chip oscillator clock frequency
3.  $f_{SUB}$ : Subsystem clock frequency (XT1 clock oscillation frequency)
4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is  $T_A = 25^{\circ}\text{C}$

**(4) Peripheral Functions (Common to all products)****(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Low-speed on-chip oscillator operating current	I <sub>FIL</sub> <sup>Note 1</sup>				0.20		μA
RTC operating current	I <sub>RTC</sub> <sup>Notes 1, 2, 3</sup>				0.02		μA
12-bit interval timer operating current	I <sub>IT</sub> <sup>Notes 1, 2, 4</sup>				0.02		μA
Watchdog timer operating current	I <sub>WDT</sub> <sup>Notes 1, 2, 5</sup>	f <sub>IL</sub> = 15 kHz			0.22		μA
A/D converter operating current	I <sub>ADC</sub> <sup>Notes 1, 6</sup>	When conversion at maximum speed	Normal mode, AV <sub>REFP</sub> = V <sub>DD</sub> = 5.0 V		1.3	1.7	mA
			Low voltage mode, AV <sub>REFP</sub> = V <sub>DD</sub> = 3.0 V		0.5	0.7	mA
A/D converter reference voltage current	I <sub>ADREF</sub> <sup>Note 1</sup>				75.0		μA
Temperature sensor operating current	I <sub>TMPS</sub> <sup>Note 1</sup>				75.0		μA
LVD operating current	I <sub>LVI</sub> <sup>Notes 1, 7</sup>				0.08		μA
Self-programming operating current	I <sub>FSP</sub> <sup>Notes 1, 9</sup>				2.50	12.20	mA
BGO operating current	I <sub>BGO</sub> <sup>Notes 1, 8</sup>				2.50	12.20	mA
SNOOZE operating current	I <sub>SNOZ</sub> <sup>Note 1</sup>	ADC operation	The mode is performed <sup>Note 10</sup>		0.50	0.60	mA
			The A/D conversion operations are performed, Low voltage mode, AV <sub>REFP</sub> = V <sub>DD</sub> = 3.0 V		1.20	1.44	mA
		CSI/UART operation			0.70	0.84	mA

**Notes** 1. Current flowing to V<sub>DD</sub>.

- When high speed on-chip oscillator and high-speed system clock are stopped.
- Current flowing only to the real-time clock (RTC) (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either I<sub>DD1</sub> or I<sub>DD2</sub>, and I<sub>RTC</sub>, when the real-time clock operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, I<sub>FIL</sub> should be added. I<sub>DD2</sub> subsystem clock operation includes the operational current of the real-time clock.
- Current flowing only to the 12-bit interval timer (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either I<sub>DD1</sub> or I<sub>DD2</sub>, and I<sub>IT</sub>, when the 12-bit interval timer operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, I<sub>FIL</sub> should be added.
- Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The supply current of the RL78 microcontrollers is the sum of I<sub>DD1</sub>, I<sub>DD2</sub> or I<sub>DD3</sub> and I<sub>WDT</sub> when the watchdog timer is in operation.
- Current flowing only to the A/D converter. The supply current of the RL78 microcontrollers is the sum of I<sub>DD1</sub> or I<sub>DD2</sub> and I<sub>ADC</sub> when the A/D converter operates in an operation mode or the HALT mode.

7. Current flowing only to the LVD circuit. The supply current of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$  and  $I_{LVD}$  when the LVD circuit is in operation.
8. Current flowing only during data flash rewrite.
9. Current flowing only during self programming.
10. For shift time to the SNOOZE mode, see **18.3.3 SNOOZE mode**.

- Remarks**
1.  $f_{IL}$ : Low-speed on-chip oscillator clock frequency
  2.  $f_{SUB}$ : Subsystem clock frequency (XT1 clock oscillation frequency)
  3.  $f_{CLK}$ : CPU/peripheral hardware clock frequency
  4. Temperature condition of the TYP. value is  $T_A = 25^{\circ}\text{C}$

## 29.4 AC Characteristics

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)

Items	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Instruction cycle (minimum instruction execution time)	T <sub>cy</sub>	Main system clock (f <sub>MAIN</sub> ) operation	HS (high-speed main) mode	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.03125	1	μs
				2.4 V ≤ V <sub>DD</sub> < 2.7 V	0.0625	1	μs
			LS (low-speed main) mode	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.125	1	μs
			LV (low-voltage main) mode	1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.25	1	μs
		Subsystem clock (f <sub>SUB</sub> ) operation		1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	28.5	30.5 31.3	μs
		In the self programming mode	HS (high-speed main) mode	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.03125	1	μs
				2.4 V ≤ V <sub>DD</sub> < 2.7 V	0.0625	1	μs
			LS (low-speed main) mode	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.125	1	μs
			LV (low-voltage main) mode	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.25	1	μs
External system clock frequency	f <sub>EX</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V		1.0		20.0	MHz
		2.4 V ≤ V <sub>DD</sub> < 2.7 V		1.0		16.0	MHz
		1.8 V ≤ V <sub>DD</sub> < 2.4 V		1.0		8.0	MHz
		1.6 V ≤ V <sub>DD</sub> < 1.8 V		1.0		4.0	MHz
	f <sub>EXS</sub>			32	35		kHz
External system clock input high-level width, low-level width	t <sub>EXH</sub> , t <sub>EXL</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V		24			ns
		2.4 V ≤ V <sub>DD</sub> < 2.7 V		30			ns
		1.8 V ≤ V <sub>DD</sub> < 2.4 V		60			ns
		1.6 V ≤ V <sub>DD</sub> < 1.8 V		120			ns
	t <sub>EXHS</sub> , t <sub>EXLS</sub>			13.7			μs
TI00 to TI07, TI10 to TI17 input high-level width, low-level width	t <sub>TIH</sub> , t <sub>TIL</sub>			1/f <sub>MCK</sub> +10			ns <sup>Note</sup>
TO00 to TO07, TO10 to TO17 output frequency	f <sub>TO</sub>	HS (high-speed main) mode	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V			16	MHz
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V			8	MHz
			1.8 V ≤ EV <sub>DD0</sub> < 2.7 V			4	MHz
			1.6 V ≤ EV <sub>DD0</sub> < 1.8 V			2	MHz
		LS (low-speed main) mode	1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V			4	MHz
			1.6 V ≤ EV <sub>DD0</sub> < 1.8 V			2	MHz
		LV (low-voltage main) mode	1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V			2	MHz
PCLBUZ0, PCLBUZ1 output frequency	f <sub>PCL</sub>	HS (high-speed main) mode	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V			16	MHz
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V			8	MHz
			1.8 V ≤ EV <sub>DD0</sub> < 2.7 V			4	MHz
			1.6 V ≤ EV <sub>DD0</sub> < 1.8 V			2	MHz
		LS (low-speed main) mode	1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V			4	MHz
			1.6 V ≤ EV <sub>DD0</sub> < 1.8 V			2	MHz
		LV (low-voltage main) mode	1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V			4	MHz
Interrupt input high-level width, low-level width	t <sub>INTH</sub> , t <sub>INTL</sub>	INTP0	1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	1			μs
		INTP1 to INTP11	1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	1			μs
Key interrupt input low-level width	t <sub>KR</sub>	KR0 to KR7	1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	250			ns
			1.6 V ≤ EV <sub>DD0</sub> < 1.8 V	1			μs
RESET low-level width	t <sub>RSL</sub>			10			μs

(Note and Remark are listed on the next page.)

**Note** The following conditions are required for low voltage interface when  $E_{VDD0} < V_{DD}$

$1.8\text{ V} \leq E_{VDD0} < 2.7\text{ V}$  : MIN. 125 ns

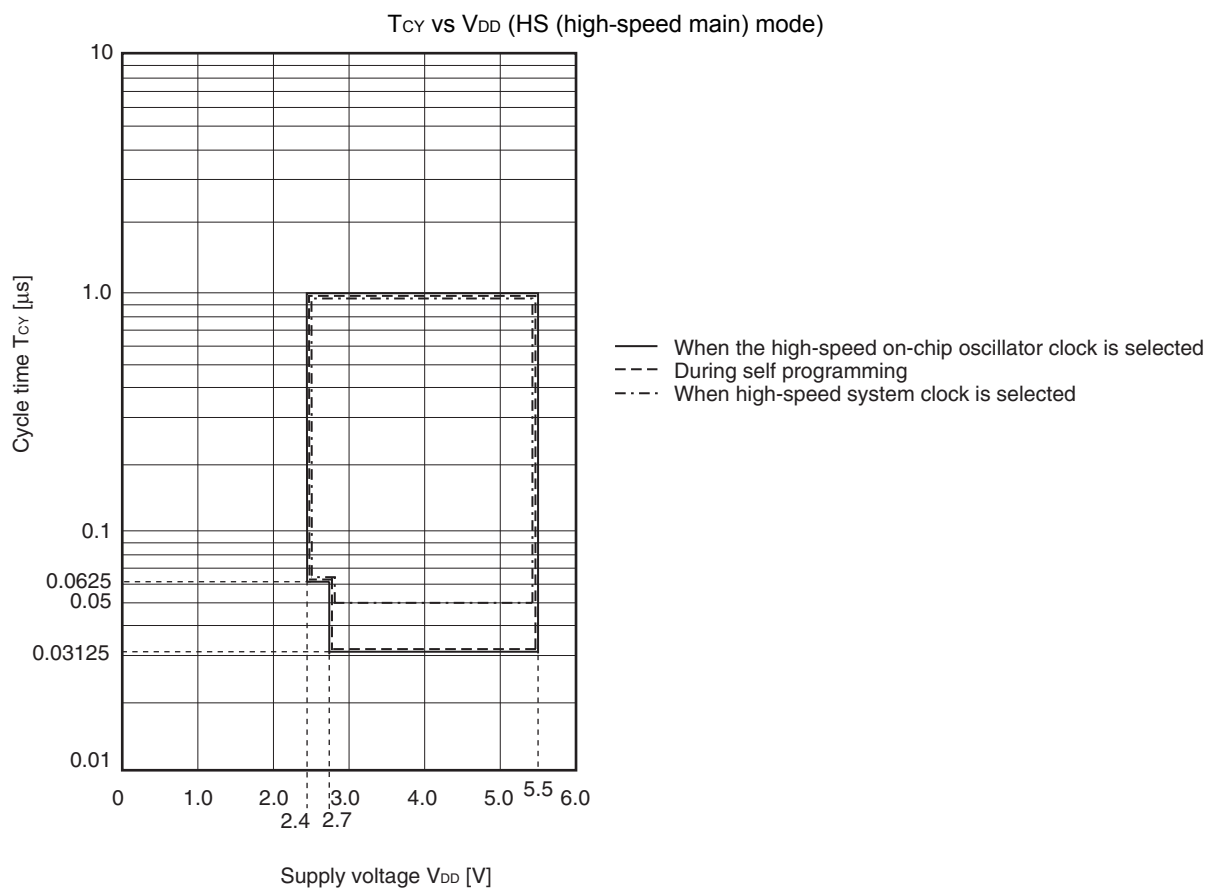
$1.6\text{ V} \leq E_{VDD0} < 1.8\text{ V}$  : MIN. 250 ns

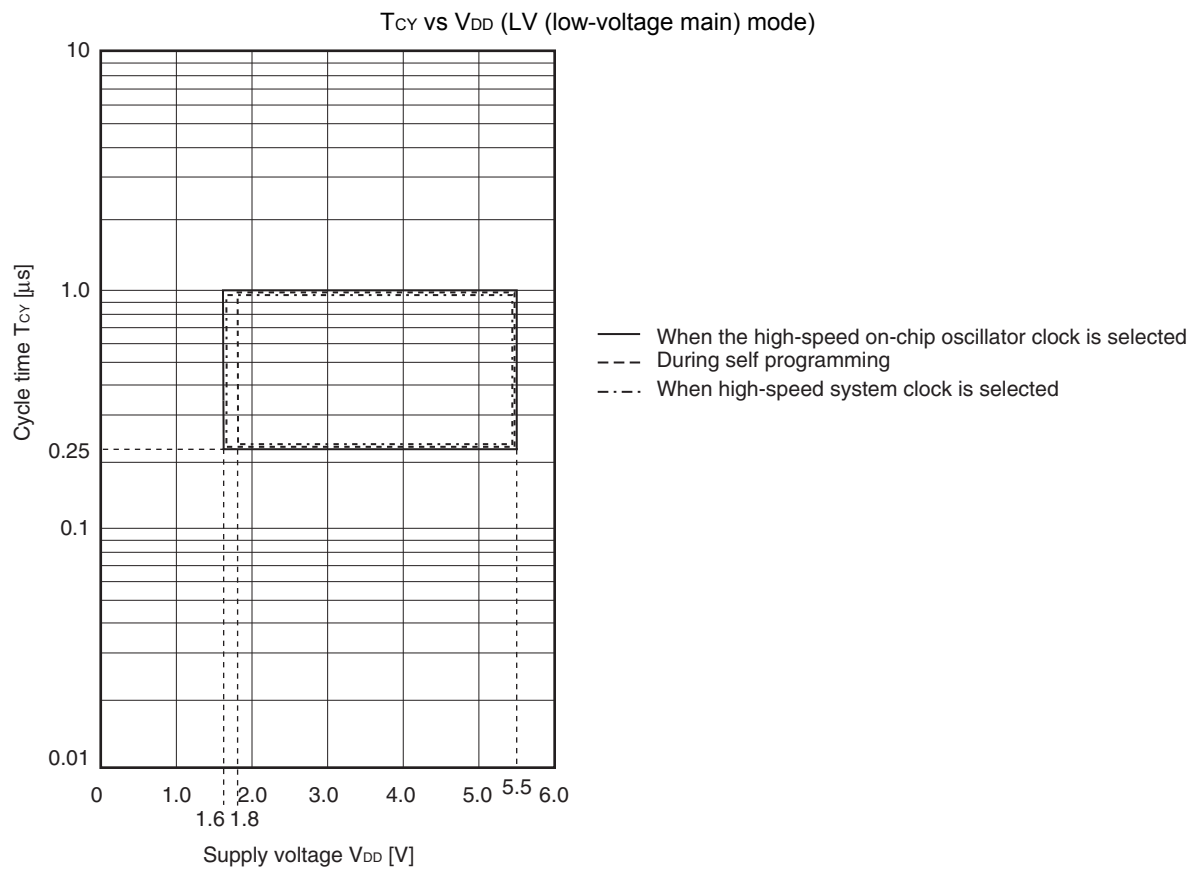
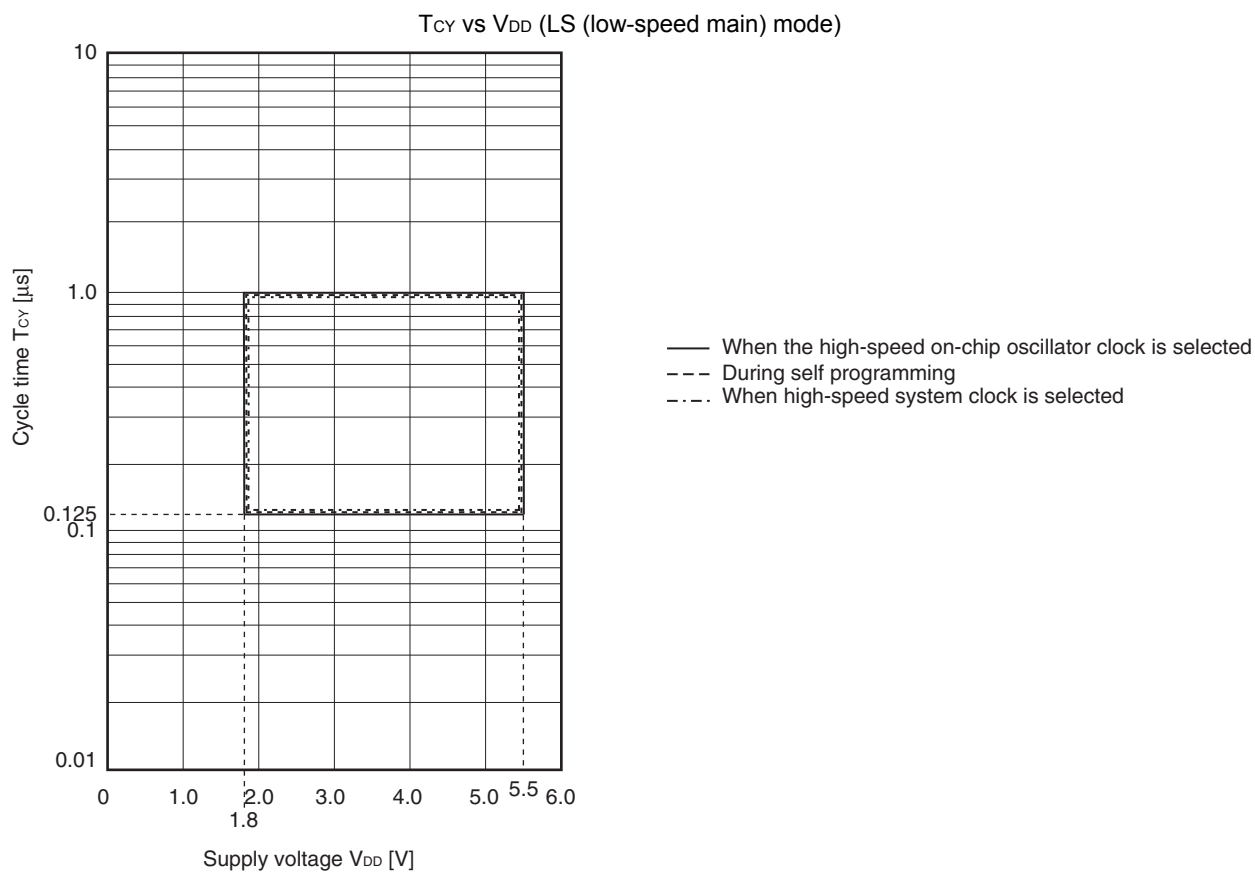
**Remark**  $f_{MCK}$ : Timer array unit operation clock frequency

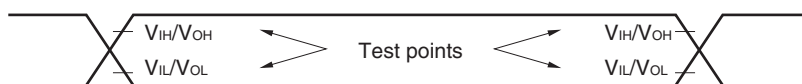
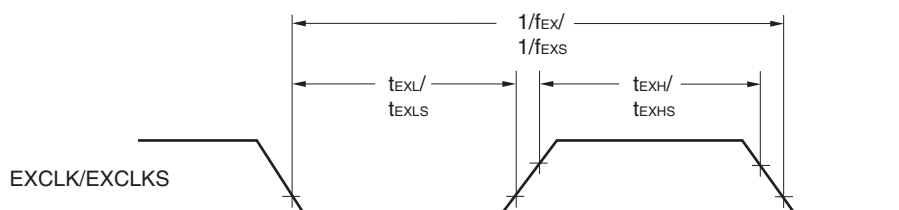
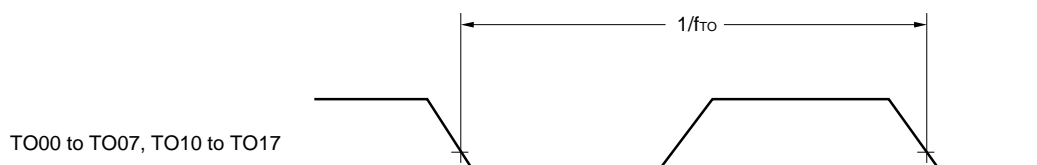
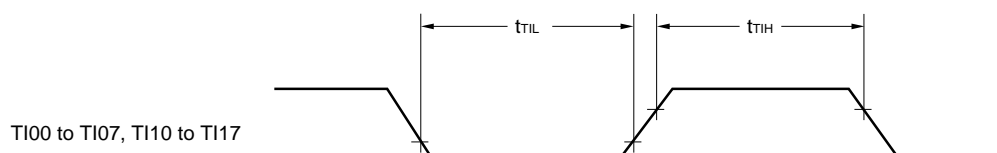
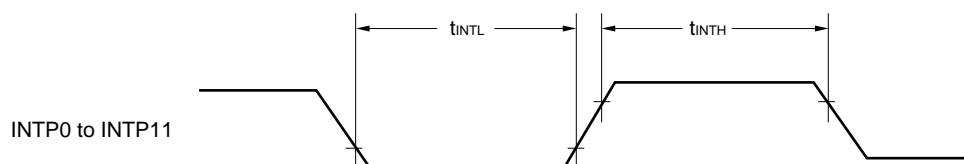
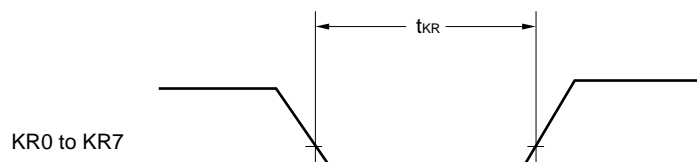
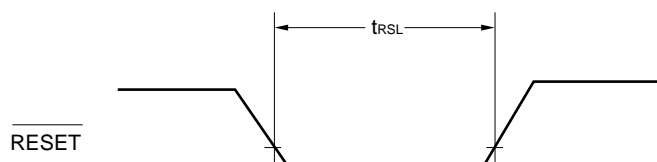
(Operation clock to be set by the CKSmn0, CKSmn1 bits of timer mode register mn (TMRmn).

m: Unit number ( $m = 0, 1$ ), n: Channel number ( $n = 0$  to  $7$ ))

#### Minimum Instruction Execution Time during Main System Clock Operation



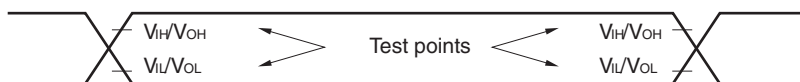


**AC Timing Test Points****External System Clock Timing****TI/TO Timing****Interrupt Request Input Timing****Key Interrupt Input Timing****RESET Input Timing**



## 29.5 Peripheral Functions Characteristics

### AC Timing Test Points



#### 29.5.1 Serial array unit

##### (1) During communication at same potential (UART mode)

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.6\text{ V} \leq E_{VDD0} = E_{VDD1} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = E_{VSS0} = E_{VSS1} = 0\text{ V}$ )

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Transfer rate <sup>Note 1</sup>		$2.4\text{ V} \leq E_{VDD0} \leq 5.5\text{ V}$		$f_{MCK}/6$ <sup>Note 2</sup>		$f_{MCK}/6$ <sup>Note 2</sup>		$f_{MCK}/6$ <sup>Note 2</sup>	bps
		Theoretical value of the maximum transfer rate $f_{MCK} = f_{CLK}$ <sup>Note 3</sup>		5.3		1.3		0.6	Mbps
		$1.8\text{ V} \leq E_{VDD0} \leq 5.5\text{ V}$		$f_{MCK}/6$ <sup>Note 2</sup>		$f_{MCK}/6$		$f_{MCK}/6$	bps
		Theoretical value of the maximum transfer rate $f_{MCK} = f_{CLK}$ <sup>Note 3</sup>		5.3		1.3		0.6	Mbps
		$1.7\text{ V} \leq E_{VDD0} \leq 5.5\text{ V}$		$f_{MCK}/6$ <sup>Note 2</sup>		$f_{MCK}/6$ <sup>Note 2</sup>		$f_{MCK}/6$	bps
		Theoretical value of the maximum transfer rate $f_{MCK} = f_{CLK}$ <sup>Note 3</sup>		5.3		1.3		0.6	Mbps
		$1.6\text{ V} \leq E_{VDD0} \leq 5.5\text{ V}$	—			$f_{MCK}/6$ <sup>Note 2</sup>		$f_{MCK}/6$	bps
		Theoretical value of the maximum transfer rate $f_{MCK} = f_{CLK}$ <sup>Note 3</sup>	—			1.3		0.6	Mbps

**Notes 1.** Transfer rate in the SNOOZE mode is 4800 bps only.

**2.** The following conditions are required for low voltage interface when  $E_{VDD0} < V_{DD}$ .

$2.4\text{ V} \leq E_{VDD0} < 2.7\text{ V}$  : MAX. 2.6 Mbps

$1.8\text{ V} \leq E_{VDD0} < 2.4\text{ V}$  : MAX. 1.3 Mbps

$1.6\text{ V} \leq E_{VDD0} < 1.8\text{ V}$  : MAX. 0.6 Mbps

**3.** The maximum operating frequencies of the CPU/peripheral hardware clock ( $f_{CLK}$ ) are:

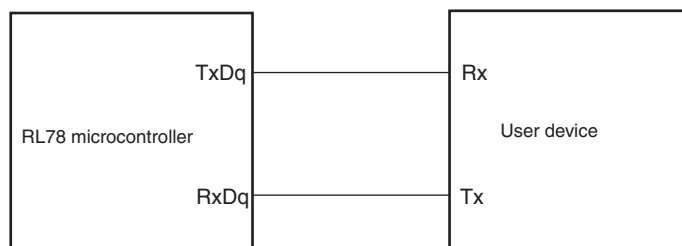
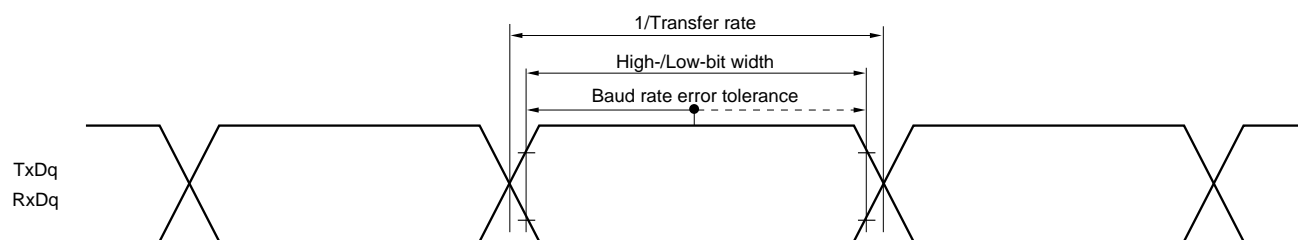
HS (high-speed main) mode: 32 MHz ( $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )

16 MHz ( $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )

LS (low-speed main) mode: 8 MHz ( $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )

LV (low-voltage main) mode: 4 MHz ( $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )

**Caution** Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**UART mode connection diagram (during communication at same potential)****UART mode bit width (during communication at same potential) (reference)**

- Remarks**
1. q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 8, 14)
  2.  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

**(2) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output, corresponding CSI00 only)**

(T<sub>A</sub> = -40 to +85°C, 2.7 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp cycle time	t <sub>KCY1</sub>	t <sub>KCY1</sub> ≥ 2/f <sub>CLK</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	62.5		250		500		ns
			2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	83.3		250		500		ns
SCKp high-/low-level width	t <sub>KH1</sub> , t <sub>KL1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY1</sub> /2 – 7		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		ns
		2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY1</sub> /2 – 10		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		ns
Slp setup time (to SCKp↑) Note 1	t <sub>SIK1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		23		110		110		ns
		2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		33		110		110		ns
Slp hold time (from SCKp↑) Note 2	t <sub>KS1</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		10		10	10			ns
Delay time from SCKp↓ to SOp output Note 3	t <sub>KSO1</sub>	C = 20 pF <sup>Note 4</sup>			10		10		10	ns

- Notes**
1. When DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 0, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 1. The Slp setup time becomes “to SCKp↓” when DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 1, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 0.
  2. When DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 0, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 1. The Slp hold time becomes “from SCKp↓” when DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 1, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 0.
  3. When DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 0, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 1. The delay time to SOp output becomes “from SCKp↑” when DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 1, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 0.
  4. C is the load capacitance of the SCKp and SOp output lines.

**Caution** Select the normal input buffer for the Slp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

- Remarks**
1. This value is valid only when CSI00's peripheral I/O redirect function is not used.
  2. p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0),  
g: PIM and POM numbers (g = 1)
  3. f<sub>MCK</sub>: Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00))

**(3) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output)****(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp cycle time	t <sub>KCY1</sub>	t <sub>KCY1</sub> ≥ 4/f <sub>CLK</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	125		500		1000		ns
			2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	250		500		1000		ns
			1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	500		500		1000		ns
			1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	1000		1000		1000		ns
			1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	—		1000		1000		ns
SCKp high-/low-level width	t <sub>KH1</sub> , t <sub>KL1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY1</sub> /2 – 12		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		ns
		2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY1</sub> /2 – 18		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		ns
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY1</sub> /2 – 38		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		ns
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		ns
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY1</sub> /2 – 100		t <sub>KCY1</sub> /2 – 100		t <sub>KCY1</sub> /2 – 100		ns
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		—		t <sub>KCY1</sub> /2 – 100		t <sub>KCY1</sub> /2 – 100		ns
Slp setup time (to SCKp↑) <small>Note 1</small>	t <sub>SIK1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		44		110		110		ns
		2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		44		110		110		ns
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		75		110		110		ns
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		110		110		110		ns
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		220		220		220		ns
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		—		220		220		ns
Slp hold time (from SCKp↑) <small>Note 2</small>	t <sub>KSI1</sub>	1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		19		19		19		ns
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		—		19		19		ns
Delay time from SCKp↓ to SOp output <small>Note 3</small>	t <sub>KSO1</sub>	1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V C = 30 pF <small>Note 4</small>			25		25		25	ns
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V C = 30 pF <small>Note 4</small>			—		25		25	ns

- Notes**
1. When DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 0, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 1. The Slp setup time becomes “to SCKp↓” when DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 1, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 0.
  2. When DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 0, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 1. The Slp hold time becomes “from SCKp↓” when DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 1, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 0.
  3. When DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 0, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 1. The delay time to SOp output becomes “from SCKp↑” when DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 1, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 0.
  4. C is the load capacitance of the SCKp and SOp output lines.

**Caution** Select the normal input buffer for the Slp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

- Remarks 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), g: PIM and POM numbers (g = 0, 1, 4, 5, 8, 14)
- 2.** f<sub>MCK</sub>: Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

**(4) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input) (1/2)**

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp cycle time Note 5	t <sub>KCY2</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	20 MHz < f <sub>MCK</sub>	8/f <sub>MCK</sub>		—		—		ns
			f <sub>MCK</sub> ≤ 20 MHz	6/f <sub>MCK</sub>		6/f <sub>MCK</sub>		6/f <sub>MCK</sub>		ns
		2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	16 MHz < f <sub>MCK</sub>	8/f <sub>MCK</sub>		—		—		ns
			f <sub>MCK</sub> ≤ 16 MHz	6/f <sub>MCK</sub>		6/f <sub>MCK</sub>		6/f <sub>MCK</sub>		ns
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		6/f <sub>MCK</sub> and 500		6/f <sub>MCK</sub> and 500		6/f <sub>MCK</sub> and 500		ns
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		6/f <sub>MCK</sub> and 750		6/f <sub>MCK</sub> and 750		6/f <sub>MCK</sub> and 750		ns
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		6/f <sub>MCK</sub> and 1500		6/f <sub>MCK</sub> and 1500		6/f <sub>MCK</sub> and 1500		ns
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		—		6/f <sub>MCK</sub> and 1500		6/f <sub>MCK</sub> and 1500		ns
SCKp high-/low-level width	t <sub>KH2</sub> , t <sub>KL2</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY2</sub> /2 - 7		t <sub>KCY2</sub> /2 - 7		t <sub>KCY2</sub> /2 - 7		ns
		2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY2</sub> /2 - 8		t <sub>KCY2</sub> /2 - 8		t <sub>KCY2</sub> /2 - 8		ns
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY2</sub> /2 - 18		t <sub>KCY2</sub> /2 - 18		t <sub>KCY2</sub> /2 - 18		ns
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY2</sub> /2 - 66		t <sub>KCY2</sub> /2 - 66		t <sub>KCY2</sub> /2 - 66		ns
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		—		t <sub>KCY2</sub> /2 - 66		t <sub>KCY2</sub> /2 - 66		ns

(Notes, Caution, and Remarks are listed on the next page.)

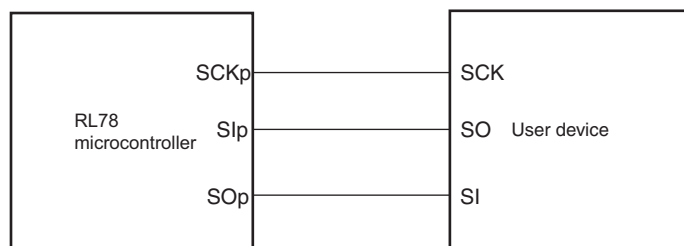
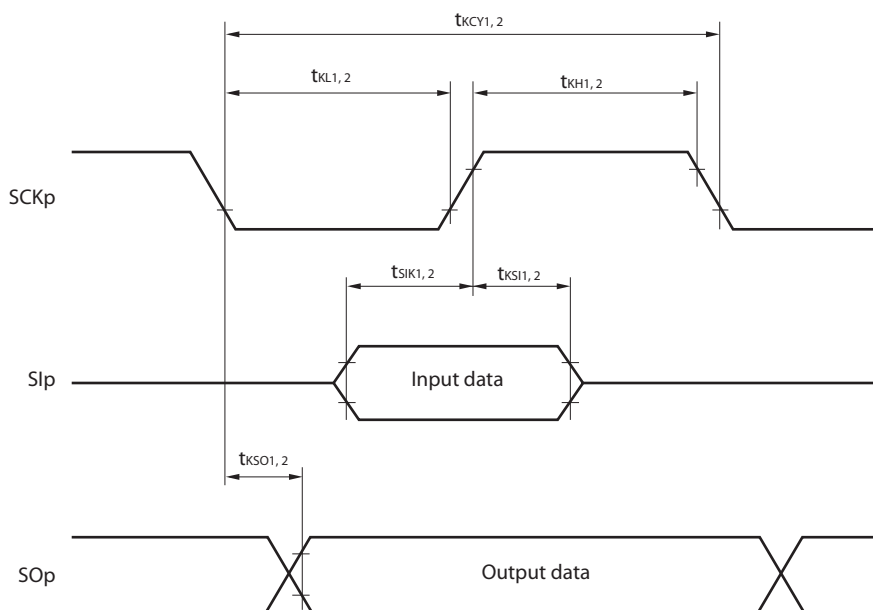
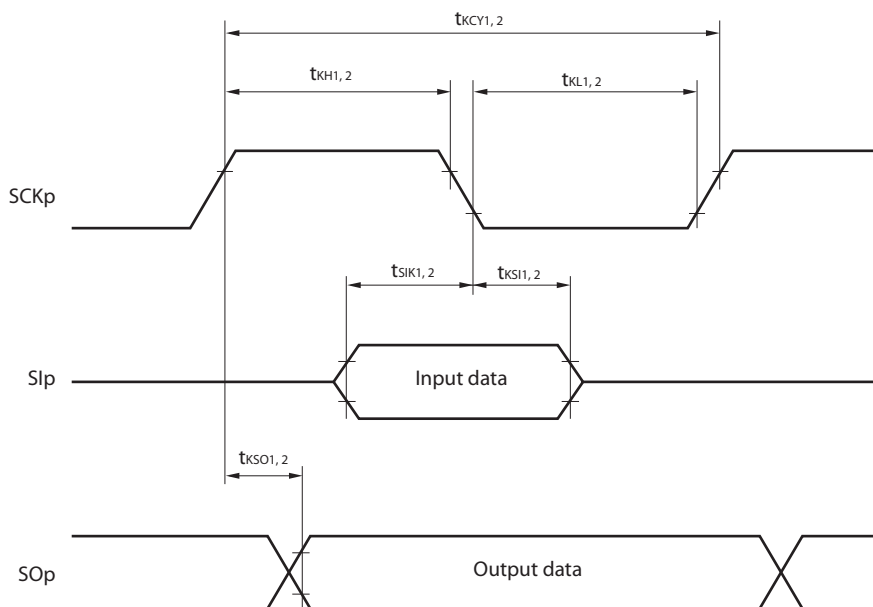
**(4) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input) (2/2)****(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Slp setup time (to SCKp↑) <sup>Note 1</sup>	t <sub>SIK2</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		1/f <sub>MCK</sub> +20		1/f <sub>MCK</sub> +30		1/f <sub>MCK</sub> +30		ns
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		1/f <sub>MCK</sub> +30		1/f <sub>MCK</sub> +30		1/f <sub>MCK</sub> +30		ns
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		1/f <sub>MCK</sub> +40		1/f <sub>MCK</sub> +40		1/f <sub>MCK</sub> +40		ns
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		—		1/f <sub>MCK</sub> +40		1/f <sub>MCK</sub> +40		ns
Slp hold time (from SCKp↑) <sup>Note 2</sup>	t <sub>SI2</sub>	1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		1/f <sub>MCK</sub> +31		1/f <sub>MCK</sub> +31		1/f <sub>MCK</sub> +31		ns
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		1/f <sub>MCK</sub> + 250		1/f <sub>MCK</sub> + 250		1/f <sub>MCK</sub> + 250		ns
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		—		1/f <sub>MCK</sub> + 250		1/f <sub>MCK</sub> + 250		ns
Delay time from SCKp↓ to SOp output <sup>Note 3</sup>	t <sub>KSO2</sub>	C = 30 pF <sup>Note 4</sup>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		2/f <sub>MCK</sub> + 44		2/f <sub>MCK</sub> + 110		2/f <sub>MCK</sub> + 110	ns
			2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		2/f <sub>MCK</sub> + 44		2/f <sub>MCK</sub> + 110		2/f <sub>MCK</sub> + 110	ns
			1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		2/f <sub>MCK</sub> + 110		2/f <sub>MCK</sub> + 110		2/f <sub>MCK</sub> + 110	ns
			1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		2/f <sub>MCK</sub> + 220		2/f <sub>MCK</sub> + 220		2/f <sub>MCK</sub> + 220	ns
			1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		—		2/f <sub>MCK</sub> + 220		2/f <sub>MCK</sub> + 220	ns

- Notes**
1. When DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 0, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 1. The Slp setup time becomes “to SCKp↓” when DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 1, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 0.
  2. When DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 0, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 1. The Slp hold time becomes “from SCKp↓” when DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 1, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 0.
  3. When DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 0, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 1. The delay time to SOp output becomes “from SCKp↑” when DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 1, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 0.
  4. C is the load capacitance of the SOp output lines.
  5. Transfer rate in the SNOOZE mode: MAX. 1 Mbps

**Caution** Select the normal input buffer for the Slp pin and SCKp pin and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

- Remarks**
1. p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1),  
n: Channel number (n = 0 to 3), g: PIM number (g = 0, 1, 4, 5, 8, 14)
  2. f<sub>MCK</sub>: Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

**CSI mode connection diagram (during communication at same potential)2912**
**CSI mode serial transfer timing (during communication at same potential)**  
**(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**

**CSI mode serial transfer timing (during communication at same potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**


- Remarks** 1. p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31)  
 2. m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13)

**(5) During communication at same potential (simplified I<sup>2</sup>C mode) (1/2)**

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>BD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCLr clock frequency	f <sub>SCL</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ		1000 Note 1		400 Note 1		400 Note 1	kHz
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 3 kΩ		400 Note 1		400 Note 1		400 Note 1	kHz
		1.8 V ≤ EV <sub>DD0</sub> < 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5 kΩ		300 Note 1		300 Note 1		300 Note 1	kHz
		1.7 V ≤ EV <sub>DD0</sub> < 1.8 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5 kΩ		250 Note 1		250 Note 1		250 Note 1	kHz
		1.6 V ≤ EV <sub>DD0</sub> < 1.8 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5 kΩ		—		250 Note 1		250 Note 1	kHz
Hold time when SCLr = "L"	t <sub>LOW</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	475		1150		1150		ns
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 3 kΩ	1150		1150		1150		ns
		1.8 V ≤ EV <sub>DD0</sub> < 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5 kΩ	1550		1550		1550		ns
		1.7 V ≤ EV <sub>DD0</sub> < 1.8 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5 kΩ	1850		1850		1850		ns
		1.6 V ≤ EV <sub>DD0</sub> < 1.8 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5 kΩ	—		1850		1850		ns
Hold time when SCLr = "H"	t <sub>HIGH</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	475		1150		1150		ns
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 3 kΩ	1150		1150		1150		ns
		1.8 V ≤ EV <sub>DD0</sub> < 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5 kΩ	1550		1550		1550		ns
		1.7 V ≤ EV <sub>DD0</sub> < 1.8 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5 kΩ	1850		1850		1850		ns
		1.6 V ≤ EV <sub>DD0</sub> < 1.8 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5 kΩ	—		1850		1850		ns

(Notes and Caution are listed on the next page, and Remarks are listed on the page after the next page.)



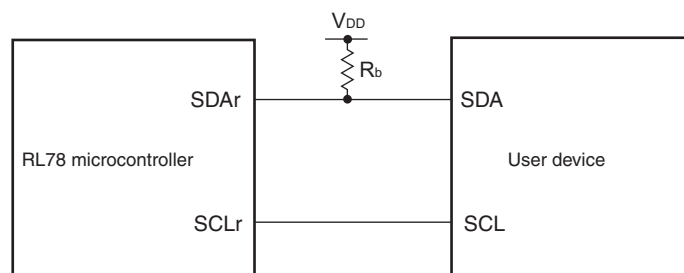
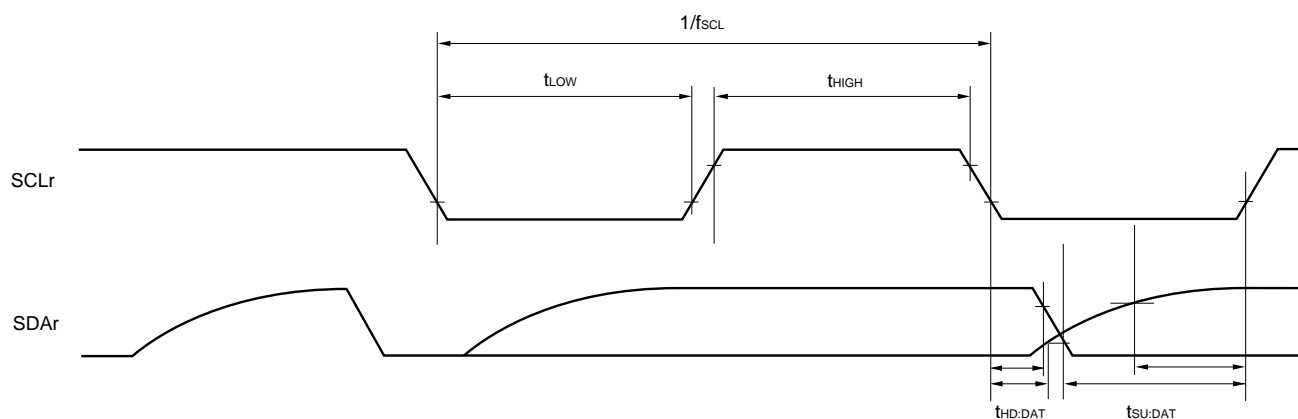
**(5) During communication at same potential (simplified I<sup>2</sup>C mode) (2/2)****(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Data setup time (reception)	t <sub>SU:DAT</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	1/f <sub>MCK</sub> + 85 Note2		1/f <sub>MCK</sub> + 145 Note2		1/f <sub>MCK</sub> + 145 Note2		ns
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 3 kΩ	1/f <sub>MCK</sub> + 145 Note2		1/f <sub>MCK</sub> + 145 Note2		1/f <sub>MCK</sub> + 145 Note2		ns
		1.8 V ≤ EV <sub>DD0</sub> < 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5 kΩ	1/f <sub>MCK</sub> + 230 Note2		1/f <sub>MCK</sub> + 230 Note2		1/f <sub>MCK</sub> + 230 Note2		ns
		1.7 V ≤ EV <sub>DD0</sub> < 1.8 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5 kΩ	1/f <sub>MCK</sub> + 290 Note2		1/f <sub>MCK</sub> + 290 Note2		1/f <sub>MCK</sub> + 290 Note2		ns
		1.6 V ≤ EV <sub>DD0</sub> < 1.8 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5 kΩ	—		1/f <sub>MCK</sub> + 290 Note2		1/f <sub>MCK</sub> + 290 Note2		ns
Data hold time (transmission)	t <sub>HD:DAT</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	0	305	0	305	0	305	ns
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 3 kΩ	0	355	0	355	0	355	ns
		1.8 V ≤ EV <sub>DD0</sub> < 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5 kΩ	0	405	0	405	0	405	ns
		1.7 V ≤ EV <sub>DD0</sub> < 1.8 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5 kΩ	0	405	0	405	0	405	ns
		1.6 V ≤ EV <sub>DD0</sub> < 1.8 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5 kΩ	—		0	405	0	405	ns

- Notes**
1. The value must also be equal to or less than f<sub>MCK</sub>/4.
  2. Set the f<sub>MCK</sub> value to keep the hold time of SCLr = "L" and SCLr = "H".

**Caution** Select the normal input buffer and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 128-pin products)) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

(Remarks are listed on the next page.)

**Simplified I<sup>2</sup>C mode connection diagram (during communication at same potential)****Simplified I<sup>2</sup>C mode serial transfer timing (during communication at same potential)**

- Remarks**
1.  $R_b[\Omega]$ : Communication line (SDAr) pull-up resistance,  $C_b[F]$ : Communication line (SDAr, SCLr) load capacitance
  2. r: IIC number (r = 00, 01, 10, 11, 20, 21, 30, 31), g: PIM number (g = 0, 1, 4, 5, 8, 14),  
h: POM number (g = 0, 1, 4, 5, 7 to 9, 14)
  3.  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0, 1),  
n: Channel number (n = 0 to 3), mn = 00 to 03, 10 to 13)

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (1/2)****(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ E<sub>VDD0</sub> = E<sub>VDD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = E<sub>VSS0</sub> = E<sub>VSS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Transfer rate		Reception	4.0 V ≤ E <sub>VDD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V		f <sub>MCK</sub> /6 Note 1		f <sub>MCK</sub> /6 Note 1		bps
					5.3		1.3		Mbps
			Theoretical value of the maximum transfer rate f <sub>MCK</sub> = f <sub>CLK</sub> Note 4						
			2.7 V ≤ E <sub>VDD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V		f <sub>MCK</sub> /6 Note 1		f <sub>MCK</sub> /6 Note 1		bps
					5.3		1.3		Mbps
			Theoretical value of the maximum transfer rate f <sub>MCK</sub> = f <sub>CLK</sub> Note 4						
			1.8 V ≤ E <sub>VDD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V		f <sub>MCK</sub> /6 Notes 1 to 3		f <sub>MCK</sub> /6 Notes 1, 2		bps
					5.3		1.3		Mbps
			Theoretical value of the maximum transfer rate f <sub>MCK</sub> = f <sub>CLK</sub> Note 4						

**Notes 1.** Transfer rate in the SNOOZE mode is 4800 bps only.**2.** Use it with E<sub>VDD0</sub> ≥ V<sub>b</sub>.**3.** The following conditions are required for low voltage interface when E<sub>VDD0</sub> < V<sub>DD</sub>.2.4 V ≤ E<sub>VDD0</sub> < 2.7 V : MAX. 2.6 Mbps1.8 V ≤ E<sub>VDD0</sub> < 2.4 V : MAX. 1.3 Mbps**4.** The maximum operating frequencies of the CPU/peripheral hardware clock (f<sub>CLK</sub>) are:HS (high-speed main) mode: 32 MHz (2.7 V ≤ V<sub>DD</sub> ≤ 5.5 V)16 MHz (2.4 V ≤ V<sub>DD</sub> ≤ 5.5 V)LS (low-speed main) mode: 8 MHz (1.8 V ≤ V<sub>DD</sub> ≤ 5.5 V)LV (low-voltage main) mode: 4 MHz (1.6 V ≤ V<sub>DD</sub> ≤ 5.5 V)

**Caution** Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/E<sub>VDD</sub> tolerance (When 64- to 128-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

**Remarks 1.** V<sub>b</sub>[V]: Communication line voltage**2.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 8, 14)**3.** f<sub>MCK</sub>: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

**4.** UART2 cannot communicate at different potential when bit 1 (PIOR1) of peripheral I/O redirection register (PIOR) is 1.

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (2/2)****(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Transfer rate		Transmission	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V		<b>Note 1</b>		<b>Note 1</b>		bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 1.4 kΩ, V <sub>b</sub> = 2.7 V		2.8 <small>Note 2</small>		2.8 <small>Note 2</small>		Mbps
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V		<b>Note 3</b>		<b>Note 3</b>		bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ, V <sub>b</sub> = 2.3 V		1.2 <small>Note 4</small>		1.2 <small>Note 4</small>		Mbps
			1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V		<b>Notes 5, 6</b>		<b>Notes 5, 6</b>		bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 5.5 kΩ, V <sub>b</sub> = 1.6 V		0.43 <small>Note 7</small>		0.43 <small>Note 7</small>		Mbps

**Notes 1.** The smaller maximum transfer rate derived by using f<sub>MCK</sub>/6 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 4.0 V ≤ EV<sub>DD0</sub> ≤ 5.5 V and 2.7 V ≤ V<sub>b</sub> ≤ 4.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

2. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to Note 1 above to calculate the maximum transfer rate under conditions of the customer.

3. The smaller maximum transfer rate derived by using  $f_{MCK}/6$  or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when  $2.7\text{ V} \leq E_{VDD0} < 4.0\text{ V}$  and  $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

4. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to Note 3 above to calculate the maximum transfer rate under conditions of the customer.
5. Use it with  $E_{VDD0} \geq V_b$ .
6. The smaller maximum transfer rate derived by using  $f_{MCK}/6$  or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when  $1.8\text{ V} \leq E_{VDD0} < 3.3\text{ V}$  and  $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\} \times 3} \text{ [bps]}$$

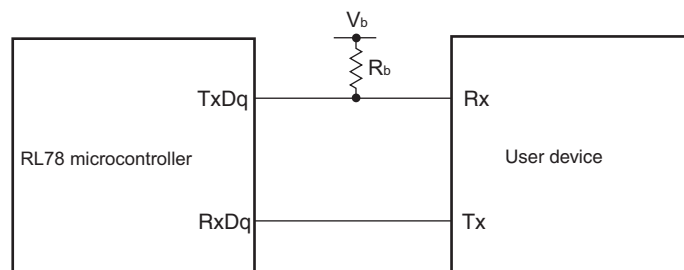
$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

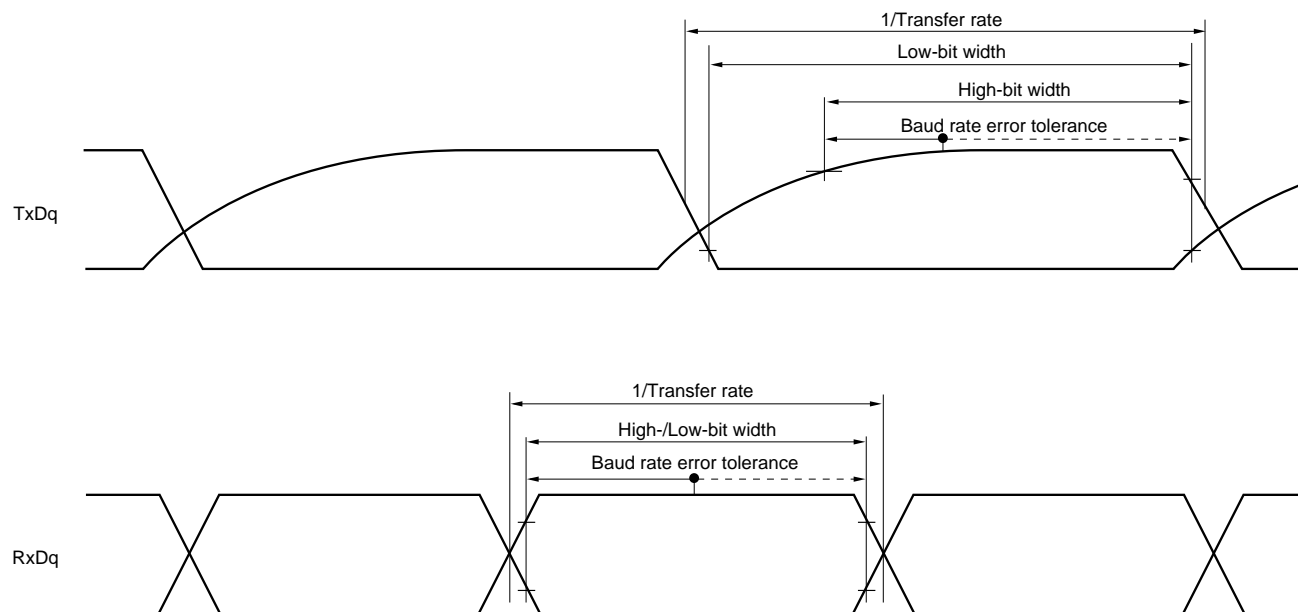
\* This value is the theoretical value of the relative difference between the transmission and reception sides.

7. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to Note 6 above to calculate the maximum transfer rate under conditions of the customer.

**Caution** Select the TTL input buffer for the Rx<sub>Dq</sub> pin and the N-ch open drain output ( $V_{DD}$  tolerance (When 20- to 52-pin products)/ $E_{VDD}$  tolerance (When 64- to 128-pin products)) mode for the Tx<sub>Dq</sub> pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

UART mode connection diagram (during communication at different potential)



**UART mode bit width (during communication at different potential) (reference)**

- Remarks 1.**  $R_b[\Omega]$ : Communication line (TxDq) pull-up resistance,  
 $C_b[F]$ : Communication line (TxDq) load capacitance,  $V_b[V]$ : Communication line voltage
- 2.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 8, 14)
- 3.**  $f_{MCK}$ : Serial array unit operation clock frequency  
 (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).  
 m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))
- 4.** UART2 cannot communicate at different potential when bit 1 (PIOR1) of peripheral I/O redirection register (PIOR) is 1.

**(7) Communication at different potential (2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output, corresponding CSI00 only) (1/2)**

(T<sub>A</sub> = -40 to +85°C, 2.7 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp cycle time	t <sub>KCY1</sub>	t <sub>KCY1</sub> ≥ 2/f <sub>CLK</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 1.4 kΩ	200		1150		1150		ns
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 2.7 kΩ	300		1150		1150		ns
SCKp high-level width	t <sub>KH1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 1.4 kΩ		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 2.7 kΩ		t <sub>KCY1</sub> /2 – 120		t <sub>KCY1</sub> /2 – 120		t <sub>KCY1</sub> /2 – 120		ns
SCKp low-level width	t <sub>KL1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 1.4 kΩ		t <sub>KCY1</sub> /2 – 7		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 2.7 kΩ		t <sub>KCY1</sub> /2 – 10		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		ns
Slp setup time (to SCKp↑) <sup>Note 1</sup>	t <sub>SIK1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 1.4 kΩ		58		479		479		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 2.7 kΩ		121		479		479		ns
Slp hold time (from SCKp↑) <sup>Note 1</sup>	t <sub>KSI1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 1.4 kΩ		10		10		10		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 2.7 kΩ		10		10		10		ns
Delay time from SCKp↓ to SOp output <sup>Note 1</sup>	t <sub>KSO1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 1.4 kΩ			60		60		60	ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 2.7 kΩ			130		130		130	ns

(Notes, Caution, and Remarks are listed on the next page.)

**(7) Communication at different potential (2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output, corresponding CSI00 only) (2/2)**

(T<sub>A</sub> = -40 to +85°C, 2.7 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Slp setup time (to SCKp↓) <sup>Note 2</sup>	t <sub>SIK1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 1.4 kΩ	23		110	110			ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 2.7 kΩ	33		110	110			ns
Slp hold time (from SCKp↓) <sup>Note 2</sup>	t <sub>KSI1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 1.4 kΩ	10		10	10			ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 2.7 kΩ	10		10	10			ns
Delay time from SCKp↑ to SOp output <sup>Note 2</sup>	t <sub>KSO1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 1.4 kΩ		10		10		10	ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 20 pF, R <sub>b</sub> = 2.7 kΩ		10		10		10	ns

**Notes** 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.

2. When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 128-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

**Remarks** 1. R<sub>b</sub>[Ω]: Communication line (SCKp, SOp) pull-up resistance, C<sub>b</sub>[F]: Communication line (SCKp, SOp) load capacitance, V<sub>b</sub>[V]: Communication line voltage  
 2. p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0),  
 g: PIM and POM number (g = 1)  
 3. f<sub>MCK</sub>: Serial array unit operation clock frequency  
 (Operation clock to be set by the CKSm n bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00))  
 4. This value is valid only when CSI00's peripheral I/O redirect function is not used.



**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (1/3)**  
**(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp cycle time	t <sub>KCY1</sub>	t <sub>KCY1</sub> ≥ 4/f <sub>CLK</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	300		1150		1150		ns
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	500		1150		1150		ns
			1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	1150	1150			1150		ns
SCKp high-level width	t <sub>KH1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ		t <sub>KCY1</sub> /2 – 75		t <sub>KCY1</sub> /2 – 75		t <sub>KCY1</sub> /2 – 75		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ		t <sub>KCY1</sub> /2 – 170		t <sub>KCY1</sub> /2 – 170		t <sub>KCY1</sub> /2 – 170		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ		t <sub>KCY1</sub> /2 – 458		t <sub>KCY1</sub> /2 – 458		t <sub>KCY1</sub> /2 – 458		ns
SCKp low-level width	t <sub>KL1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ		t <sub>KCY1</sub> /2 – 12		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ		t <sub>KCY1</sub> /2 – 18		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		ns

**Note** Use it with EV<sub>DD0</sub> ≥ V<sub>b</sub>.

**Caution** Select the TTL input buffer for the SIp pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 128-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

(Remarks are listed two pages after the next page.)

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (2/3)****(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Slp setup time (to SCKp↑) <sup>Note 1</sup>	t <sub>SIK1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	81		479		479		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	177		479		479		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	479		479		479		ns
Slp hold time (from SCKp↑) <sup>Note 1</sup>	t <sub>KSI1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	19		19		19		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	19		19		19		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	19		19		19		ns
Delay time from SCKp↓ to SOp output <sup>Note 1</sup>	t <sub>KSO1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ		100		100		100	ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ		195		195		195	ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ		483		483		483	ns

- Notes**
1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.
  2. Use it with EV<sub>DD0</sub> ≥ V<sub>b</sub>.

**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 128-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the page after the next page.)

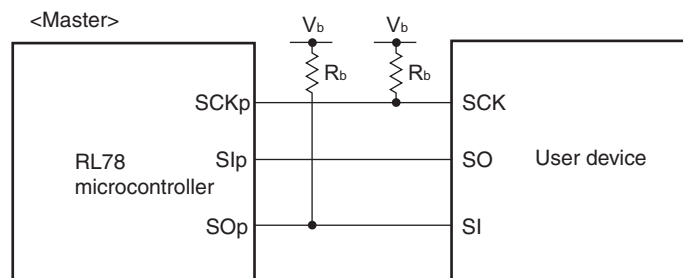
**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (3/3)****(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Slp setup time (to SCKp↓) <sup>Note 1</sup>	t <sub>SIK1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	44		110		110		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	44		110		110		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	110		110		110		ns
Slp hold time (from SCKp↓) <sup>Note 1</sup>	t <sub>KSI1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	19		19		19		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	19		19		19		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	19		19		19		ns
Delay time from SCKp↑ to SOp output <sup>Note 1</sup>	t <sub>KSO1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ		25		25		25	ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ		25		25		25	ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ		25		25		25	ns

- Notes**
1. When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
  2. Use it with EV<sub>DD0</sub> ≥ V<sub>b</sub>.

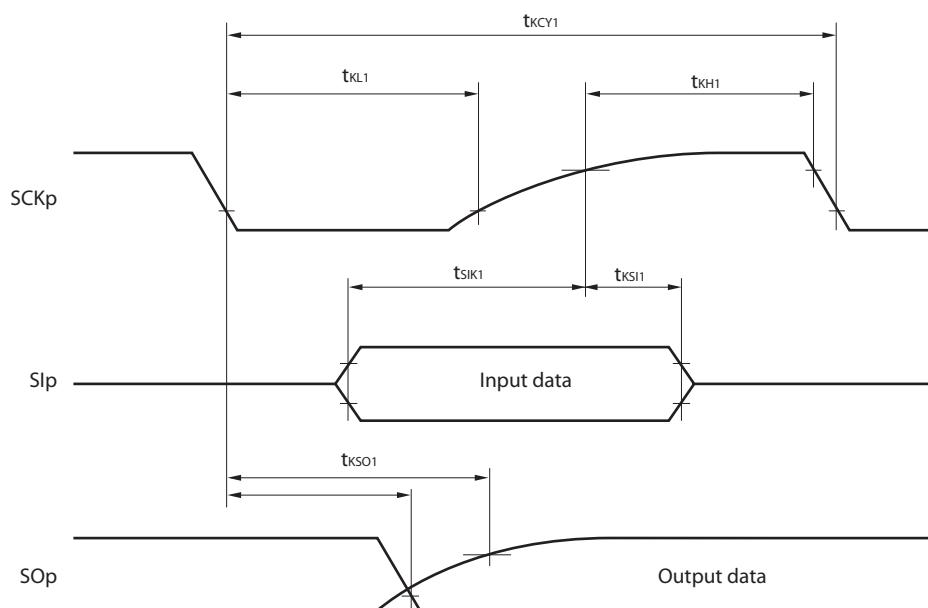
**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 128-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

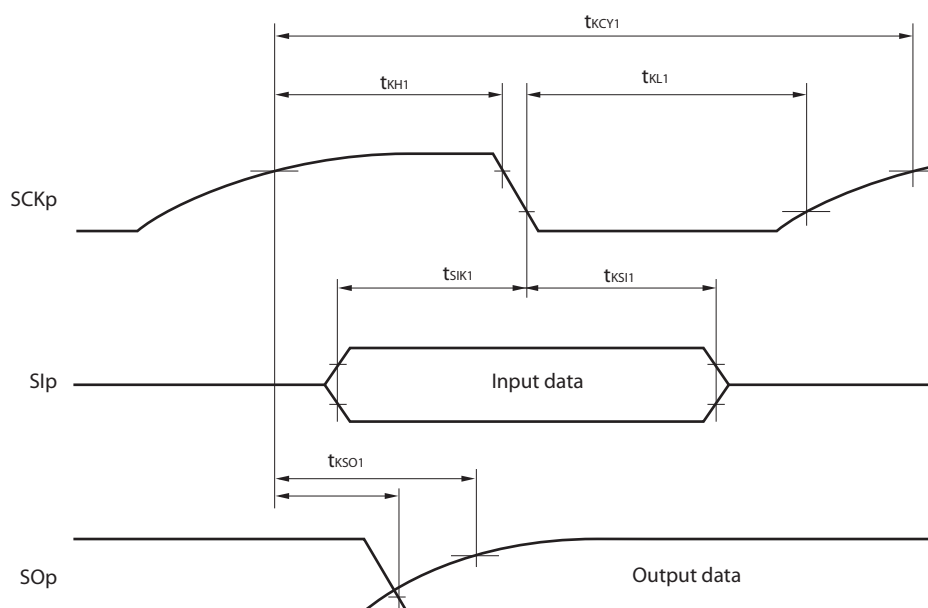
**CSI mode connection diagram (during communication at different potential)**

- Remarks**
1.  $R_b[\Omega]$ : Communication line (SCKp, SOp) pull-up resistance,  $C_b[\text{F}]$ : Communication line (SCKp, SOp) load capacitance,  $V_b[\text{V}]$ : Communication line voltage
  2. p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number, n: Channel number (mn = 00, 01, 02, 10, 12, 13), g: PIM and POM number (g = 0, 1, 4, 5, 8, 14)
  3.  $f_{\text{MCK}}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).  
m: Unit number, n: Channel number (mn = 00))
  4. CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

**CSI mode serial transfer timing (master mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**CSI mode serial transfer timing (master mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



- Remarks**
1. p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number (m = 00, 01, 02, 10, 12, 13), n: Channel number (n = 0, 2), g: PIM and POM number (g = 0, 1, 4, 5, 8, 14)
  2. CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

**(9) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (slave mode, SCKp... external clock input)**  
**(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (1/2)**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp cycle time <sup>Note 1</sup>	t <sub>KCY2</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V	24 MHz < f <sub>MCK</sub>	14/ f <sub>MCK</sub>		—		—		ns
			20 MHz < f <sub>MCK</sub> ≤ 24 MHz	12/ f <sub>MCK</sub>		—		—		ns
			8 MHz < f <sub>MCK</sub> ≤ 20 MHz	10/ f <sub>MCK</sub>		—		—		ns
			4 MHz < f <sub>MCK</sub> ≤ 8 MHz	8/f <sub>MCK</sub>		16/ f <sub>MCK</sub>		—		ns
			f <sub>MCK</sub> ≤ 4 MHz	6/f <sub>MCK</sub>		10/ f <sub>MCK</sub>		10/ f <sub>MCK</sub>		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V	24 MHz < f <sub>MCK</sub>	20/ f <sub>MCK</sub>		—		—		ns
			20 MHz < f <sub>MCK</sub> ≤ 24 MHz	16/ f <sub>MCK</sub>		—		—		ns
			16 MHz < f <sub>MCK</sub> ≤ 20 MHz	14/ f <sub>MCK</sub>		—		—		ns
			8 MHz < f <sub>MCK</sub> ≤ 16 MHz	12/ f <sub>MCK</sub>		—		—		ns
			4 MHz < f <sub>MCK</sub> ≤ 8 MHz	8/f <sub>MCK</sub>		16/ f <sub>MCK</sub>		—		ns
			f <sub>MCK</sub> ≤ 4 MHz	6/f <sub>MCK</sub>		10/ f <sub>MCK</sub>		10/ f <sub>MCK</sub>		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup>	24 MHz < f <sub>MCK</sub>	48/ f <sub>MCK</sub>		—		—		ns
			20 MHz < f <sub>MCK</sub> ≤ 24 MHz	36/ f <sub>MCK</sub>		—		—		ns
			16 MHz < f <sub>MCK</sub> ≤ 20 MHz	32/ f <sub>MCK</sub>		—		—		ns
			8 MHz < f <sub>MCK</sub> ≤ 16 MHz	26/ f <sub>MCK</sub>		—		—		ns
			4 MHz < f <sub>MCK</sub> ≤ 8 MHz	16/ f <sub>MCK</sub>		16/ f <sub>MCK</sub>		—		ns
			f <sub>MCK</sub> ≤ 4 MHz	10/ f <sub>MCK</sub>		10/ f <sub>MCK</sub>		10/ f <sub>MCK</sub>		ns

(Notes and Caution are listed on the next page, and Remarks are listed on the page after the next page.)

**(9) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (slave mode, SCKp... external clock input)****(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (2/2)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp high-/low-level width	t <sub>KH2</sub> , t <sub>KL2</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V	t <sub>KCY2</sub> /2 – 12		t <sub>KCY2</sub> /2 – 50		t <sub>KCY2</sub> /2 – 50		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V	t <sub>KCY2</sub> /2 – 18		t <sub>KCY2</sub> /2 – 50		t <sub>KCY2</sub> /2 – 50		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup>	t <sub>KCY2</sub> /2 – 50		t <sub>KCY2</sub> /2 – 50		t <sub>KCY2</sub> /2 – 50		ns
Slp setup time (to SCKp↑) <sup>Note 3</sup>	t <sub>SIK2</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V	1/f <sub>MCK</sub> + 20		1/f <sub>MCK</sub> + 30		1/f <sub>MCK</sub> + 30		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V	1/f <sub>MCK</sub> + 20		1/f <sub>MCK</sub> + 30		1/f <sub>MCK</sub> + 30		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup>	1/f <sub>MCK</sub> + 30		1/f <sub>MCK</sub> + 30		1/f <sub>MCK</sub> + 30		ns
Slp hold time (from SCKp↑) <sup>Note 4</sup>	t <sub>KS12</sub>		1/f <sub>MCK</sub> + 31		1/f <sub>MCK</sub> + 31		1/f <sub>MCK</sub> + 31		ns
Delay time from SCKp↓ to SOp output <sup>Note 5</sup>	t <sub>KSO2</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ		2/f <sub>MCK</sub> + 120		2/f <sub>MCK</sub> + 573		2/f <sub>MCK</sub> + 573	ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ		2/f <sub>MCK</sub> + 214		2/f <sub>MCK</sub> + 573		2/f <sub>MCK</sub> + 573	ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ		2/f <sub>MCK</sub> + 573		2/f <sub>MCK</sub> + 573		2/f <sub>MCK</sub> + 573	ns

**Notes** 1. Transfer rate in the SNOOZE mode : MAX. 1 Mbps2. Use it with EV<sub>DD0</sub> ≥ V<sub>b</sub>.

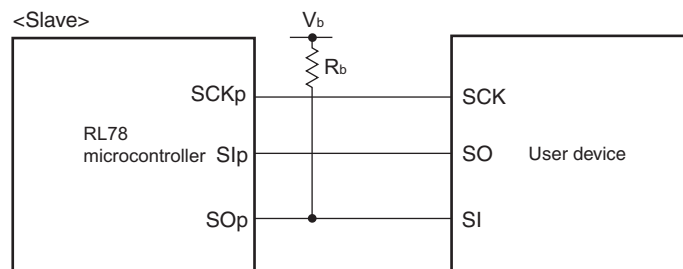
3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

4. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

5. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 128-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

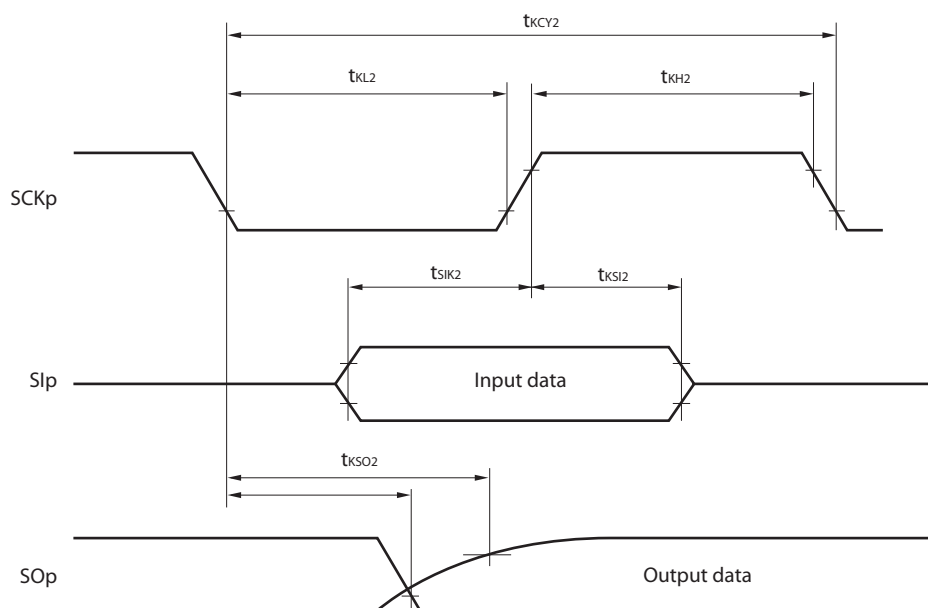
(Remarks are listed on the next page.)

**CSI mode connection diagram (during communication at different potential)**

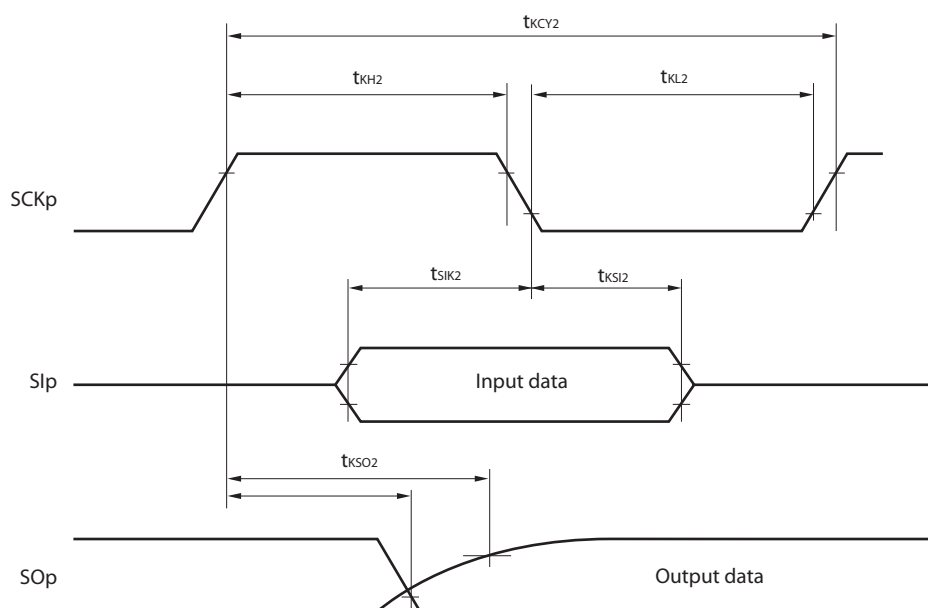
- Remarks**
1.  $R_b[\Omega]$ : Communication line (SO<sub>p</sub>) pull-up resistance,  $C_b[F]$ : Communication line (SO<sub>p</sub>) load capacitance,  $V_b[V]$ : Communication line voltage
  2. p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 00, 01, 02, 10, 12, 13), g: PIM and POM number (g = 0, 1, 4, 5, 8, 14)
  3.  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).  
m: Unit number, n: Channel number (mn = 00, 01, 02, 10, 12, 13))
  4. CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.



**CSI mode serial transfer timing (slave mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**CSI mode serial transfer timing (slave mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



- Remarks**
1. p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number, n: Channel number (mn = 00, 01, 02, 10, 12, 13), g: PIM and POM number (g = 0, 1, 4, 5, 8, 14)
  2. CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

**(10) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode) (1/2)****(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCLr clock frequency	f <sub>SCL</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ		1000 Note 1		300 Note 1		300 Note 1	kHz
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ		1000 Note 1		300 Note 1		300 Note 1	kHz
		4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.8 kΩ		400 Note 1		300 Note 1		300 Note 1	kHz
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.7 kΩ		400 Note 1		300 Note 1		300 ote 1	kHz
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 kΩ		300 Note 1		300 Note 1		300 Note 1	kHz
Hold time when SCLr = "L"	t <sub>LOW</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	475		1550		1550		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	475		1550		1550		ns
		4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.8 kΩ	1150		1550		1550		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.7 kΩ	1150		1550		1550		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 kΩ	1550		1550		1550		ns
Hold time when SCLr = "H"	t <sub>HIGH</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	245	610	610				ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	200	610	610				ns
		4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.8 kΩ	675	610	610				ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.7 kΩ	600	610	610				ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 kΩ	610	610	610				ns

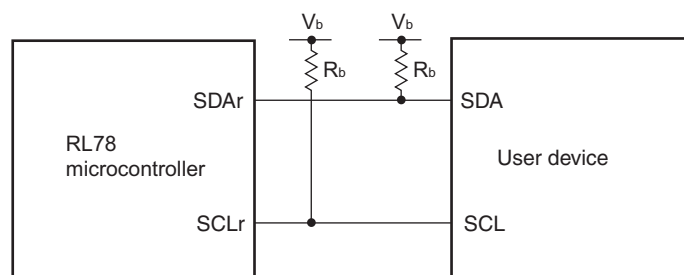
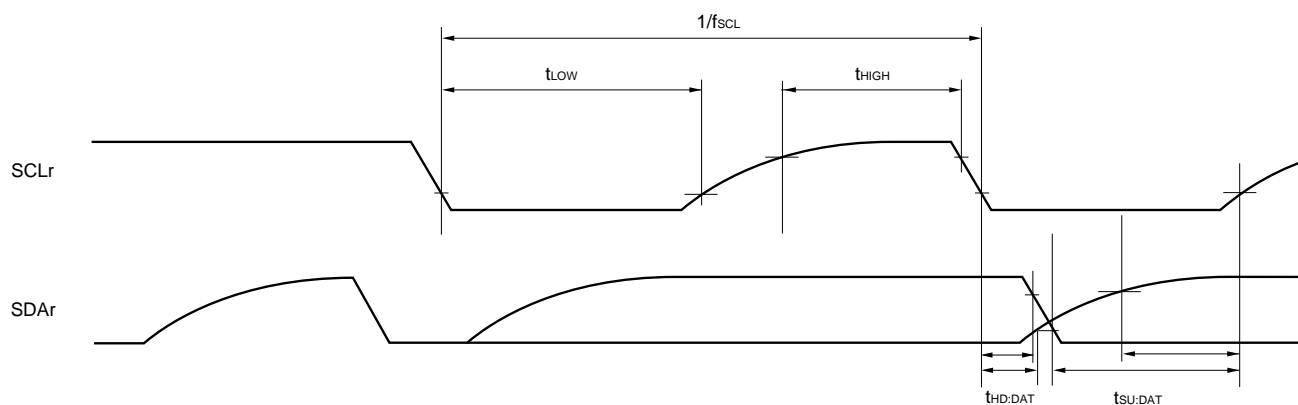
**(10) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode) (2/2)****(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Data setup time (reception)	t <sub>SU:DAT</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	1/f <sub>MCK</sub> + 135 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		kHz
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	1/f <sub>MCK</sub> + 135 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		kHz
		4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.8 kΩ	1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		kHz
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.7 kΩ	1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		kHz
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 kΩ	1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		kHz
Data hold time (transmission)	t <sub>HD:DAT</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	0	305	0	305			ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	0	305	0	305	0	305	ns
		4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.8 kΩ	0	355	0	355	0	355	ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.7 kΩ	0	355	0	355	0	355	ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 kΩ	0	405	0	405	0	405	ns

**Notes 1.** The value must also be equal to or less than f<sub>MCK</sub>/4.**2.** Use it with EV<sub>DD0</sub> ≥ V<sub>b</sub>.**3.** Set the f<sub>MCK</sub> value to keep the hold time of SCLr = "L" and SCLr = "H".

**Caution** Select the TTL input buffer and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 128-pin products)) mode for the SDAr pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 128-pin products)) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

**Simplified I<sup>2</sup>C mode connection diagram (during communication at different potential)****Simplified I<sup>2</sup>C mode serial transfer timing (during communication at different potential)**

- Remarks**
1.  $R_b[\Omega]$ : Communication line (SDAr, SCLr) pull-up resistance,  $C_b[F]$ : Communication line (SDAr, SCLr) load capacitance,  $V_b[V]$ : Communication line voltage
  2. r: IIC number ( $r = 00, 01, 10, 20, 30, 31$ ), g: PIM, POM number ( $g = 0, 1, 4, 5, 8, 14$ )
  3.  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number ( $mn = 00, 01, 02, 10, 12, 13$ ))

## 29.5.2 Serial interface IICA

(1) I<sup>2</sup>C standard mode(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCLA0 clock frequency	f <sub>SCL</sub>	Standard mode: f <sub>CLK</sub> ≥ 1 MHz	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	100	0	100	0	100	kHz
			1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	100	0	100	0	100	kHz
			1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	100	0	100	0	100	kHz
			1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	—		0	100	0	100	kHz
Setup time of restart condition	t <sub>SU:STA</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.7		4.7		4.7		μs	
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.7		4.7		4.7		μs	
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.7		4.7		4.7		μs	
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	—		4.7		4.7		μs	
Hold time <sup>Note 1</sup>	t <sub>HD:STA</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.0		4.0		4.0		μs	
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.0		4.0		4.0		μs	
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.0		4.0		4.0		μs	
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	—		4.0		4.0		μs	
Hold time when SCLA0 = “L”	t <sub>LOW</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.7	4.7			4.7		μs	
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.7		4.7		4.7		μs	
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.7		4.7		4.7		μs	
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	—		4.7		4.7		μs	
Hold time when SCLA0 = “H”	t <sub>HIGH</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.0		4.0		4.0		μs	
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.0		4.0		4.0		μs	
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.0		4.0		4.0		μs	
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	—		4.0		4.0		μs	
Data setup time (reception)	t <sub>SU:DAT</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	250		250		250		ns	
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	250		250		250		ns	
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	250		250		250		ns	
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	—		250		250		ns	
Data hold time (transmission) <sup>Note 2</sup>	t <sub>HD:DAT</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	3.45	0	3.45	0	3.45	μs	
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	3.45	0	3.45	0	3.45	μs	
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	3.45	0	3.45	0	3.45	μs	
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	—		0	3.45	0	3.45	μs	
Setup time of stop condition	t <sub>SU:STO</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.0	4.0			4.0		μs	
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.0		4.0		4.0		μs	
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.0		4.0		4.0		μs	
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	—		4.0		4.0		μs	
Bus-free time	t <sub>BUF</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.7		4.7		4.7		μs	
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.7		4.7		4.7		μs	
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	4.7		4.7		4.7		μs	
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	—		4.7		4.7		μs	

- Notes**
1. The first clock pulse is generated after this period when the start/restart condition is detected.
  2. The maximum value (MAX.) of t<sub>HD:DAT</sub> is during normal transfer and a wait state is inserted in the  $\overline{\text{ACK}}$  (acknowledge) timing.

**Caution** The values in the above table are applied even when bit 2 (PIOR2) in the peripheral I/O redirection register (PIOR) is 1. At this time, the pin characteristics (I<sub>OH1</sub>, I<sub>OL1</sub>, V<sub>OH1</sub>, V<sub>OL1</sub>) must satisfy the values in the redirect destination.

**Remark** The maximum value of C<sub>b</sub> (communication line capacitance) and the value of R<sub>b</sub> (communication line pull-up resistor) at that time in each mode are as follows.

Standard mode: C<sub>b</sub> = 400 pF, R<sub>b</sub> = 2.7 kΩ

(2) I<sup>2</sup>C fast mode(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCLA0 clock frequency	f <sub>SCL</sub>	Fast mode: f <sub>CLK</sub> ≥ 3.5 MHz							
		2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	400	0	400	0	400	kHz
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	400	0	400	0	400	kHz
Setup time of restart condition	t <sub>SU:STA</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0.6		0.6		0.6		μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0.6		0.6		0.6		μs
Hold time <sup>Note 1</sup>	t <sub>HD:STA</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0.6		0.6		0.6		μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0.6		0.6		0.6		μs
Hold time when SCLA0 = "L"	t <sub>LOW</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	1.3		1.3		1.3		μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	1.3		1.3		1.3		μs
Hold time when SCLA0 = "H"	t <sub>HIGH</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0.6		0.6		0.6		μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0.6		0.6		0.6		μs
Data setup time (reception)	t <sub>SU:DAT</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	100		100		100		μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	100		100		100		μs
Data hold time (transmission) <sup>Note 2</sup>	t <sub>HD:DAT</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	0.9	0	0.9	0	0.9	μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	0.9	0	0.9	0	0.9	μs
Setup time of stop condition	t <sub>SU:STO</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0.6		0.6		0.6		μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0.6		0.6		0.6		μs
Bus-free time	t <sub>BUF</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	1.3		1.3		1.3		μs
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	1.3		1.3		1.3		μs

- Notes**
1. The first clock pulse is generated after this period when the start/restart condition is detected.
  2. The maximum value (MAX.) of t<sub>HD:DAT</sub> is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.

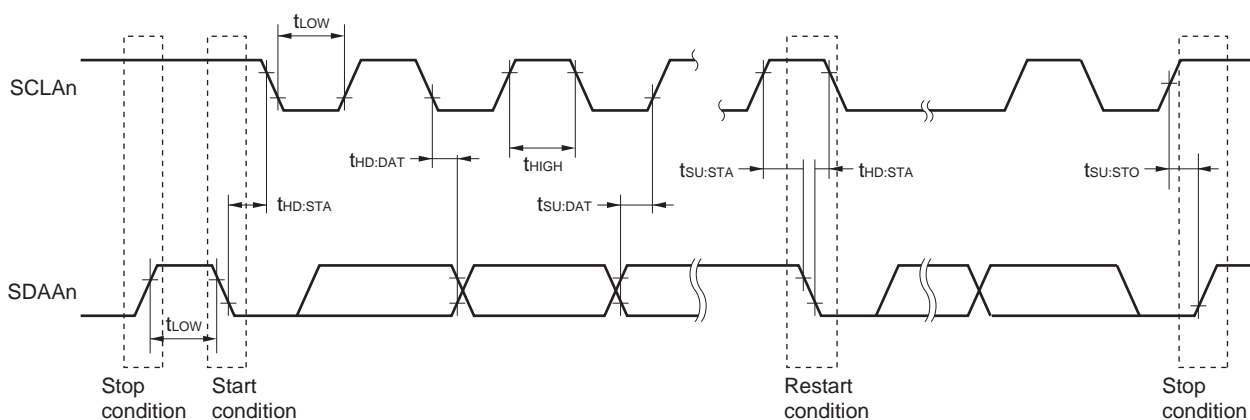
**Caution** The values in the above table are applied even when bit 2 (PIOR2) in the peripheral I/O redirection register (PIOR) is 1. At this time, the pin characteristics (I<sub>OH1</sub>, I<sub>OL1</sub>, V<sub>OH1</sub>, V<sub>OL1</sub>) must satisfy the values in the redirect destination.

**Remark** The maximum value of C<sub>b</sub> (communication line capacitance) and the value of R<sub>b</sub> (communication line pull-up resistor) at that time in each mode are as follows.

Fast mode: C<sub>b</sub> = 320 pF, R<sub>b</sub> = 1.1 kΩ

**(3) I<sup>2</sup>C fast mode plus****(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCL <sub>A0</sub> clock frequency	f <sub>SCL</sub>	Fast mode plus: f <sub>CLK</sub> ≥ 10 MHz 2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	1000	—	—	—	—	kHz
Setup time of restart condition	t <sub>SU:STA</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0.26		—	—	—	—	μs
Hold time <sup>Note 1</sup>	t <sub>HD:STA</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0.26		—	—	—	—	μs
Hold time when SCL <sub>A0</sub> = "L"	t <sub>LOW</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0.5		—	—	—	—	μs
Hold time when SCL <sub>A0</sub> = "H"	t <sub>HIGH</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0.26		—	—	—	—	μs
Data setup time (reception)	t <sub>SU:DAT</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	50		—	—	—	—	μs
Data hold time (transmission) <sup>Note 2</sup>	t <sub>HD:DAT</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	0.45	—	—	—	—	μs
Setup time of stop condition	t <sub>SU:STO</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0.26		—	—	—	—	μs
Bus-free time	t <sub>BUF</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0.5		—	—	—	—	μs

**Notes** 1. The first clock pulse is generated after this period when the start/restart condition is detected.2. The maximum value (MAX.) of t<sub>HD:DAT</sub> is during normal transfer and a wait state is inserted in the  $\overline{\text{ACK}}$  (acknowledge) timing.**Caution** The values in the above table are applied even when bit 2 (PIOR2) in the peripheral I/O redirection register (PIOR) is 1. At this time, the pin characteristics (I<sub>OH1</sub>, I<sub>OL1</sub>, V<sub>OH1</sub>, V<sub>OL1</sub>) must satisfy the values in the redirect destination.**Remark** The maximum value of C<sub>b</sub> (communication line capacitance) and the value of R<sub>b</sub> (communication line pull-up resistor) at that time in each mode are as follows.Fast mode plus: C<sub>b</sub> = 120 pF, R<sub>b</sub> = 1.1 kΩ**I<sup>2</sup>C serial transfer timing****Remark** n = 0, 1



## 29.6 Analog Characteristics

### 29.6.1 A/D converter characteristics

Classification of A/D converter characteristics

Input channel	Reference Voltage		
	Reference voltage (+) = AV <sub>REFP</sub> Reference voltage (-) = AV <sub>REFM</sub>	Reference voltage (+) = V <sub>DD</sub> Reference voltage (-) = V <sub>SS</sub>	Reference voltage (+) = V <sub>BGR</sub> Reference voltage (-) = AV <sub>REFM</sub>
ANI0 to ANI14	Refer to 29.6.1 (1).	Refer to 29.6.1 (3).	Refer to 29.6.1 (3).
ANI16 to ANI26	Refer to 29.6.1 (2).		
Internal reference voltage Temperature sensor output voltage	Refer to 29.6.1 (1).		—

(1) When reference voltage (+) = AV<sub>REFP</sub>/ANI0 (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) = AV<sub>REFM</sub>/ANI1 (ADREFM = 1), target pin : ANI2 to ANI14, internal reference voltage, and temperature sensor output voltage

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ AV<sub>REFP</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V, Reference voltage (+) = AV<sub>REFP</sub>, Reference voltage (-) = AV<sub>REFM</sub> = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8		10	bit
Overall error <sup>Note 1</sup>	AINL	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Note 3</sup>	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		1.2	±3.5	LSB
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V <sup>Note 4</sup>		1.2	±7.0	LSB
Conversion time	t <sub>CONV</sub>	10-bit resolution Target pin: ANI2 to ANI14	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.125		39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.1875		39	μs
			1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	17		39	μs
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	57		95	μs
	t <sub>CONV</sub>	10-bit resolution Target pin: Internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode)	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.375		39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.5625		39	μs
			2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17		39	μs
Zero-scale error <sup>Notes 1, 2</sup>	E <sub>ZS</sub>	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Note 3</sup>	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V			±0.25	%FSR
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V <sup>Note 4</sup>			±0.50	%FSR
Full-scale error <sup>Notes 1, 2</sup>	E <sub>FS</sub>	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Note 3</sup>	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V			±0.25	%FSR
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V <sup>Note 4</sup>			±0.50	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Note 3</sup>	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V			±2.5	LSB
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V <sup>Note 4</sup>			±5.0	LSB
Differential linearity error <sup>Note 1</sup>	DLE	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Note 3</sup>	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V			±1.5	LSB
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V <sup>Note 4</sup>			±2.0	LSB
Analog input voltage	V <sub>AIN</sub>	ANI2 to ANI14		0		AV <sub>REFP</sub>	V
		Internal reference voltage output (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)		V <sub>BGR</sub> <sup>Note 5</sup>			V
		Temperature sensor output voltage (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)		V <sub>TMPS25</sub> <sup>Note 5</sup>			V

- Notes**
1. Excludes quantization error ( $\pm 1/2$  LSB).
  2. This value is indicated as a ratio (%FSR) to the full-scale value.
  3. When  $AV_{REFP} < V_{DD}$ , the MAX. values are as follows.  
Overall error: Add  $\pm 1.0$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .  
Zero-scale error/Full-scale error: Add  $\pm 0.05\%$ FSR to the MAX. value when  $AV_{REFP} = V_{DD}$ .  
Integral linearity error/ Differential linearity error: Add  $\pm 0.5$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .
  4. Values when the conversion time is set to  $57\ \mu\text{s}$  (min.) and  $95\ \mu\text{s}$  (max.).
  5. Refer to **29.6.2 Temperature sensor/internal reference voltage characteristics**.

(2) When reference voltage (+) =  $AV_{REFP}/ANI0$  (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) =  $AV_{REFM}/ANI1$  (ADREFM = 1), target pin : ANI16 to ANI26

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, 1.6 V ≤ AV<sub>REFP</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V, Reference voltage (+) = AV<sub>REFP</sub>, Reference voltage (-) = AV<sub>REFM</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES		8		10	bit
Overall error <sup>Note 1</sup>	AINL	10-bit resolution EV <sub>DD0</sub> = AV <sub>REFP</sub> = V <sub>DD</sub> Notes 3, 4	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V	1.2	±5.0	LSB
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V <sup>Note 5</sup>	1.2	±8.5	LSB
Conversion time	t <sub>CONV</sub>	10-bit resolution Target ANI pin : ANI16 to ANI26	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.125	39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.1875	39	μs
			1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	17	39	μs
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	57	95	μs
Zero-scale error <sup>Notes 1, 2</sup>	E <sub>ZS</sub>	10-bit resolution EV <sub>DD0</sub> = AV <sub>REFP</sub> = V <sub>DD</sub> Notes 3, 4	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±0.35	%FSR
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V <sup>Note 5</sup>		±0.60	%FSR
Full-scale error <sup>Notes 1, 2</sup>	E <sub>FS</sub>	10-bit resolution EV <sub>DD0</sub> = AV <sub>REFP</sub> = V <sub>DD</sub> Notes 3, 4	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±0.35	%FSR
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V <sup>Note 5</sup>		±0.60	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	10-bit resolution EV <sub>DD0</sub> = AV <sub>REFP</sub> = V <sub>DD</sub> Notes 3, 4	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±3.5	LSB
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V <sup>Note 5</sup>		±6.0	LSB
Differential linearity error <sup>Note 1</sup>	DLE	10-bit resolution EV <sub>DD0</sub> = AV <sub>REFP</sub> = V <sub>DD</sub> Notes 3, 4	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±2.0	LSB
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V <sup>Note 5</sup>		±2.5	LSB
Analog input voltage	V <sub>AIN</sub>	ANI16 to ANI26	0		AV <sub>REFP</sub> and EV <sub>DD0</sub>	V

**Notes** 1. Excludes quantization error (±1/2 LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. When AV<sub>REFP</sub> < V<sub>DD</sub>, the MAX. values are as follows.

Overall error: Add ±1.0 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Zero-scale error/Full-scale error: Add ±0.05%FSR to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Integral linearity error/ Differential linearity error: Add ±0.5 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

4. When AV<sub>REFP</sub> < EV<sub>DD0</sub> ≤ V<sub>DD</sub>, the MAX. values are as follows.

Overall error: Add ±4.0 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Zero-scale error/Full-scale error: Add ±0.20%FSR to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Integral linearity error/ Differential linearity error: Add ±2.0 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

5. When the conversion time is set to 57 μs (min.) and 95 μs (max.).

(3) When reference voltage (+) = V<sub>DD</sub> (ADREFP1 = 0, ADREFP0 = 0), reference voltage (-) = V<sub>SS</sub> (ADREFM = 0), target pin : ANI0 to ANI14, ANI16 to ANI26, internal reference voltage, and temperature sensor output voltage

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V, Reference voltage (+) = V<sub>DD</sub>, Reference voltage (-) = V<sub>SS</sub>)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8		10	bit
Overall error <sup>Note 1</sup>	AINL	10-bit resolution	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V		1.2	±7.0	LSB
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V Note 3		1.2	±10.5	LSB
Conversion time	t <sub>CONV</sub>	10-bit resolution Target pin: ANI0 to ANI14, ANI16 to ANI26	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.125		39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.1875		39	μs
			1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	17		39	μs
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	57		95	μs
Conversion time	t <sub>CONV</sub>	10-bit resolution Target pin: internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode)	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.375		39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.5625		39	μs
			2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17		39	μs
Zero-scale error <sup>Notes 1, 2</sup>	E <sub>ZS</sub>	10-bit resolution	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V			±0.60	%FSR
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V Note 3			±0.85	%FSR
Full-scale error <sup>Notes 1, 2</sup>	E <sub>FS</sub>	10-bit resolution	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V			±0.60	%FSR
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V Note 3			±0.85	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	10-bit resolution	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V			±4.0	LSB
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V Note 3			±6.5	LSB
Differential linearity error <sup>Note 1</sup>	DLE	10-bit resolution	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V			±2.0	LSB
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V Note 3			±2.5	LSB
Analog input voltage	V <sub>AIN</sub>	ANI0 to ANI14		0		V <sub>DD</sub>	V
		ANI16 to ANI26		0		EV <sub>DD0</sub>	V
		Internal reference voltage output (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)		V <sub>BGR</sub> <sup>Note 4</sup>			V
		Temperature sensor output voltage (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)		V <sub>TMPS25</sub> <sup>Note 4</sup>			V

**Notes** 1. Excludes quantization error (±1/2 LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. When the conversion time is set to 57 μs (min.) and 95 μs (max.).

4. Refer to 29.6.2 Temperature sensor/internal reference voltage characteristics.

(4) When reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), reference voltage (-) = AV<sub>REFM</sub>/ANI1 (ADREFM = 1), target pin : ANI0, ANI2 to ANI14, ANI16 to ANI26

(T<sub>A</sub> = -40 to +85°C, 2.4 V ≤ V<sub>DD</sub> ≤ 5.5 V, 1.6 V ≤ EV<sub>DD</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub>, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V, Reference voltage (+) = V<sub>BGR</sub><sup>Note 3</sup>, Reference voltage (-) = AV<sub>REFM</sub> = 0 V<sup>Note 4</sup>, HS (high-speed main) mode)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8			bit
Conversion time	t <sub>CONV</sub>	8-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17		39	μs
Zero-scale error <sup>Notes 1, 2</sup>	E <sub>zs</sub>	8-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±0.60	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	8-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±2.0	LSB
Differential linearity error <sup>Note 1</sup>	DLE	8-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±1.0	LSB
Analog input voltage	V <sub>AIN</sub>			0		V <sub>BGR</sub> <sup>Note 3</sup>	V

**Notes** 1. Excludes quantization error (±1/2 LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. Refer to 29.6.2 Temperature sensor/internal reference voltage characteristics.

4. When reference voltage (-) = V<sub>SS</sub>, the MAX. values are as follows.

Zero-scale error: Add ±0.35%FSR to the MAX. value when reference voltage (-) = AV<sub>REFM</sub>.

Integral linearity error: Add ±0.5 LSB to the MAX. value when reference voltage (-) = AV<sub>REFM</sub>.

Differential linearity error: Add ±0.2 LSB to the MAX. value when reference voltage (-) = AV<sub>REFM</sub>.

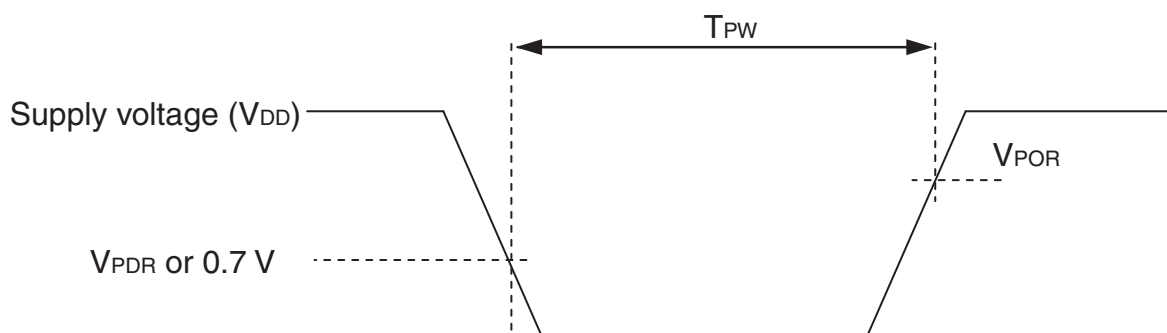
**29.6.2 Temperature sensor/internal reference voltage characteristics****( $T_A = -40$  to  $+85^{\circ}\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ , HS (high-speed main) mode)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Temperature sensor output voltage	$V_{TMPS25}$	Setting ADS register = 80H, $T_A = +25^{\circ}\text{C}$		1.05		V
Internal reference voltage	$V_{BGR}$	Setting ADS register = 81H	1.38	1.45	1.5	V
Temperature coefficient	$F_{VTMPS}$	Temperature sensor that depends on the temperature		-3.6		mV/ $^{\circ}\text{C}$
Operation stabilization wait time	$t_{AMP}$		5			$\mu\text{s}$

**29.6.3 POR circuit characteristics****( $T_A = -40$  to  $+85^{\circ}\text{C}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Detection voltage	$V_{POR}$	Power supply rise time	1.47	1.51	1.54	V
	$V_{PDR}$	Power supply fall time	1.46	1.50	1.53	V
Minimum pulse width <sup>Note</sup>	$T_{PW}$		300			$\mu\text{s}$

**Note** Minimum time required for a POR reset when  $V_{DD}$  exceeds below  $V_{PDR}$ . This is also the minimum time required for a POR reset from when  $V_{DD}$  exceeds below  $0.7\text{ V}$  to when  $V_{DD}$  exceeds  $V_{POR}$  while STOP mode is entered or the main system clock is stopped through setting bit 0 (HIOSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



## 29.6.4 LVD circuit characteristics

## LVD Detection Voltage of Reset Mode and Interrupt Mode

(T<sub>A</sub> = -40 to +85°C, V<sub>PDR</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit		
Detection voltage	Supply voltage level	V <sub>LVD0</sub>	Power supply rise time	3.98	4.06	4.14	V		
			Power supply fall time	3.90	3.98	4.06	V		
		V <sub>LVD1</sub>	Power supply rise time	3.68	3.75	3.82	V		
			Power supply fall time	3.60	3.67	3.74	V		
		V <sub>LVD2</sub>	Power supply rise time	3.07	3.13	3.19	V		
			Power supply fall time	3.00	3.06	3.12	V		
		V <sub>LVD3</sub>	Power supply rise time	2.96	3.02	3.08	V		
			Power supply fall time	2.90	2.96	3.02	V		
		V <sub>LVD4</sub>	Power supply rise time	2.86	2.92	2.97	V		
			Power supply fall time	2.80	2.86	2.91	V		
		V <sub>LVD5</sub>	Power supply rise time	2.76	2.81	2.87	V		
			Power supply fall time	2.70	2.75	2.81	V		
		V <sub>LVD6</sub>	Power supply rise time	2.66	2.71	2.76	V		
			Power supply fall time	2.60	2.65	2.70	V		
		V <sub>LVD7</sub>	Power supply rise time	2.56	2.61	2.66	V		
			Power supply fall time	2.50	2.55	2.60	V		
		V <sub>LVD8</sub>	Power supply rise time	2.45	2.50	2.55	V		
			Power supply fall time	2.40	2.45	2.50	V		
		V <sub>LVD9</sub>	Power supply rise time	2.05	2.09	2.13	V		
			Power supply fall time	2.00	2.04	2.08	V		
		V <sub>LVD10</sub>	Power supply rise time	1.94	1.98	2.02	V		
			Power supply fall time	1.90	1.94	1.98	V		
		V <sub>LVD11</sub>	Power supply rise time	1.84	1.88	1.91	V		
			Power supply fall time	1.80	1.84	1.87	V		
		V <sub>LVD12</sub>	Power supply rise time	1.74	1.77	1.81	V		
			Power supply fall time	1.70	1.73	1.77	V		
		V <sub>LVD13</sub>	Power supply rise time	1.64	1.67	1.70	V		
			Power supply fall time	1.60	1.63	1.66	V		
		Minimum pulse width		t <sub>LW</sub>		300			μs
		Detection delay time						300	μs

**LVD Detection Voltage of Interrupt & Reset Mode**(T<sub>A</sub> = -40 to +85°C, V<sub>PDR</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Interrupt and reset mode	V <sub>LVD13</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC0</sub> = 0, 0, 0, falling reset voltage		1.60	1.63	1.66	V
	V <sub>LVD12</sub>	LVIS1, LVIS0 = 1, 0	Rising release reset voltage	1.74	1.77	1.81	V
			Falling interrupt voltage	1.70	1.73	1.77	V
	V <sub>LVD11</sub>	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	1.84	1.88	1.91	V
			Falling interrupt voltage	1.80	1.84	1.87	V
	V <sub>LVD4</sub>	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	2.86	2.92	2.97	V
			Falling interrupt voltage	2.80	2.86	2.91	V
	V <sub>LVD11</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC0</sub> = 0, 0, 1, falling reset voltage		1.80	1.84	1.87	V
	V <sub>LVD10</sub>	LVIS1, LVIS0 = 1, 0	Rising release reset voltage	1.94	1.98	2.02	V
			Falling interrupt voltage	1.90	1.94	1.98	V
	V <sub>LVD9</sub>	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	2.05	2.09	2.13	V
			Falling interrupt voltage	2.00	2.04	2.08	V
	V <sub>LVD2</sub>	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	3.07	3.13	3.19	V
			Falling interrupt voltage	3.00	3.06	3.12	V
	V <sub>LVD8</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC0</sub> = 0, 1, 0, falling reset voltage		2.40	2.45	2.50	V
	V <sub>LVD7</sub>	LVIS1, LVIS0 = 1, 0	Rising release reset voltage	2.56	2.61	2.66	V
			Falling interrupt voltage	2.50	2.55	2.60	V
	V <sub>LVD6</sub>	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	2.66	2.71	2.76	V
			Falling interrupt voltage	2.60	2.65	2.70	V
	V <sub>LVD1</sub>	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	3.68	3.75	3.82	V
			Falling interrupt voltage	3.60	3.67	3.74	V
	V <sub>LVD5</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC0</sub> = 0, 1, 1, falling reset voltage		2.70	2.75	2.81	V
	V <sub>LVD4</sub>	LVIS1, LVIS0 = 1, 0	Rising release reset voltage	2.86	2.92	2.97	V
			Falling interrupt voltage	2.80	2.86	2.91	V
	V <sub>LVD3</sub>	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	2.96	3.02	3.08	V
			Falling interrupt voltage	2.90	2.96	3.02	V
	V <sub>LVD0</sub>	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	3.98	4.06	4.14	V
			Falling interrupt voltage	3.90	3.98	4.06	V

**29.6.5 Power supply voltage rising slope characteristics**(T<sub>A</sub> = -40 to +85°C, V<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	S <sub>VDD</sub>				54	V/ms

**Caution** Make sure to keep the internal reset state by the LVD circuit or an external reset until V<sub>DD</sub> reaches the operating voltage range shown in 29.4 AC Characteristics.

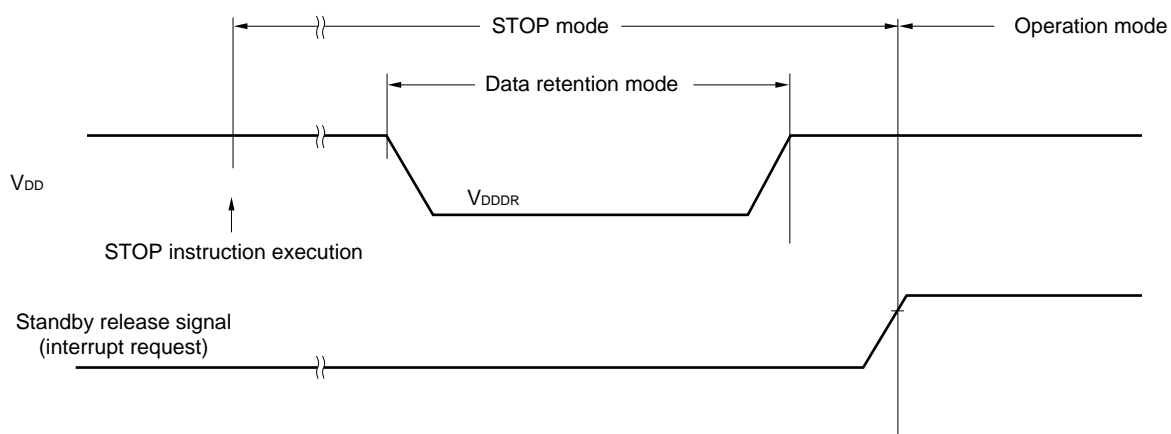


## 29.7 Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $V_{SS} = 0$  V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention supply voltage	$V_{DDDR}$		1.46 <sup>Note</sup>		5.5	V

**Note** The value depends on the POR detection voltage. When the voltage drops, the data is retained before a POR reset is effected, but data is not retained when a POR reset is effected.



## 29.8 Flash Memory Programming Characteristics

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0$  V)

TA = -40 to 105 °C, 1.8 V ≤ VDD ≤ 5.5 V, VSS = 0 V)							
Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
CPU/peripheral hardware clock frequency	fCLK	1.8 V ≤ VDD ≤ 5.5 V		1		32	MHz
Number of code flash rewrites Note 1, 2, 3	Cenwr	Retained for 20 years	TA = 85°C <sup>Note3</sup>	1,000			Times
Number of data flash rewrites Note 1, 2, 3		Retained for 1 years	TA = 25°C <sup>Note3</sup>		1,000,000		
		Retained for 5 years	TA = 85°C <sup>Note3</sup>	100,000			
		Retained for 20 years	TA = 85°C <sup>Note3</sup>	10,000			

**Notes** 1. 1 erase + 1 write after the erase is regarded as 1 rewrite.

The retaining years are until next rewrite after the rewrite.

2. When using flash memory programmer and Renesas Electronics self programming library

3. These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.

## 29.9 Dedicated Flash Memory Programmer Communication (UART)

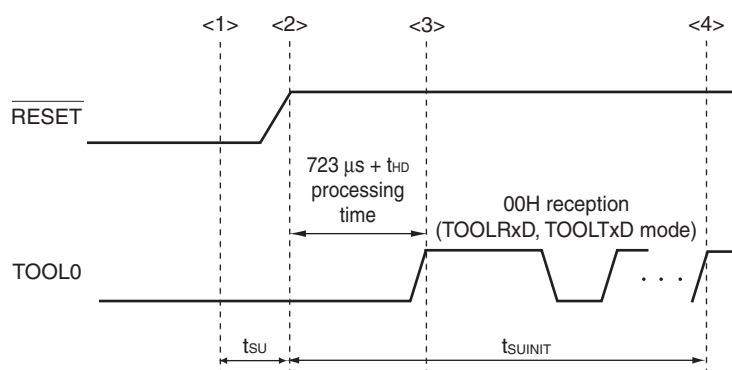
( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq EV_{DD0} = EV_{DD1} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = EV_{SS0} = EV_{SS1} = 0$  V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		During flash memory programming	115,200		1,000,000	bps

### 29.10 Timing Specs for Switching Flash Memory Programming Modes

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq \text{EV}_{\text{DD0}} = \text{EV}_{\text{DD1}} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$ ,  $\text{V}_{\text{SS}} = \text{EV}_{\text{SS0}} = \text{EV}_{\text{SS1}} = 0\text{ V}$ )

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
How long from when an external reset ends until the initial communication settings are specified	$t_{\text{SUIINIT}}$	POR and LVD reset must end before the external reset ends.			100	ms
How long from when the TOOL0 pin is placed at the low level until an external reset ends	$t_{\text{SU}}$	POR and LVD reset must end before the external reset ends.	10			$\mu\text{s}$
How long the TOOL0 pin must be kept at the low level after an external reset ends (excluding the processing time of the firmware to control the flash memory)	$t_{\text{HD}}$	POR and LVD reset must end before the external reset ends.	1			ms



<1> The low level is input to the TOOL0 pin.

<2> The external reset ends (POR and LVD reset must end before the external reset ends.).

<3> The TOOL0 pin is set to the high level.

<4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

**Remark**  $t_{\text{SUIINIT}}$ : The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the resets end.

$t_{\text{SU}}$ : How long from when the TOOL0 pin is placed at the low level until an external reset ends

$t_{\text{HD}}$ : How long to keep the TOOL0 pin at the low level from when the external and internal resets end (excluding the processing time of the firmware to control the flash memory)

To our valued customers:	<p>RL78/G13 Technical Update Exhibit Chapter 30 ELECTRICAL SPECIFICATIONS (G: T<sub>A</sub> = -40 to +105°C)</p>	M C Y G - A B - 1 2 - 0 3 8 5 - 1
		March 15, 2013
		<p>Hiroshi Uchimura Manager 1<sup>st</sup> Solution Business Unit 3<sup>rd</sup> MCU Business Division Brand Strategy Department Renesas Electronics Corporation</p>

(Rep. Seiya Indo)

Thank you for your continued support for Renesas Electronics products.

Please be advised that the misstatements found in the following User's Manual have been fixed.

The second and following pages in this document include "Chapter 30 ELECTRICAL SPECIFICATIONS (G: T<sub>A</sub> = -40 to +105°C)" which has been updated by the Correction for incorrect description notice RL78/G13 Descriptions in the User's Manual: Hardware Rev.2.10 changed (TN-RL\*-A005A/E).

1. Applicable products:

**RL78/G13**

R5F100xxG

2. Reference documents:

Correction for incorrect description notice RL78/G13 Descriptions in the User's Manual:  
Hardware Rev.2.10 changed (TN-RL\*-A005A/E)  
RL78/G13 User's Manual: Hardware Rev.2.10 (R01UH0146EJ0210)

## CHAPTER 30 ELECTRICAL SPECIFICATIONS (G: T<sub>A</sub> = -40 to +105°C)

This chapter describes the electrical specifications for the products "G: Industrial applications (T<sub>A</sub> = -40 to +105°C)".

- Cautions**
1. The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.
  2. With products not provided with an EV<sub>DD0</sub>, EV<sub>DD1</sub>, EV<sub>SS0</sub>, or EV<sub>SS1</sub> pin, replace EV<sub>DD0</sub> and EV<sub>DD1</sub> with V<sub>DD</sub>, or replace EV<sub>SS0</sub> and EV<sub>SS1</sub> with V<sub>SS</sub>.
  3. The pins mounted depend on the product. Refer to 2.1 Port Function to 2.2.1 With functions for each product.

There are following differences between the products "G: Industrial applications (T<sub>A</sub> = -40 to + 105°C)" and the products "A: Consumer applications, and D: Industrial applications".

Parameter	Application	
	A: Consumer applications, D: Industrial applications	G: Industrial applications
Operating ambient temperature	-40 to +85°C	-40 to +105°C
Operating mode Operating voltage range	HS (high-speed main) mode: 2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 32 MHz 2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 16 MHz LS (low-speed main) mode: 1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 8 MHz LV (low-voltage main) mode: 1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 4 MHz	HS (high-speed main) mode only: 2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 32 MHz 2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 16 MHz
High-speed on-chip oscillator clock accuracy	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V ±1.0%@ T <sub>A</sub> = -20°C to +85°C ±1.5%@ T <sub>A</sub> = -40°C to -20°C 1.6 V ≤ V <sub>DD</sub> < 1.8 V ±5.0%@ T <sub>A</sub> = -20°C to +85°C ±5.5%@ T <sub>A</sub> = -40°C to -20°C	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V ±2.0%@ T <sub>A</sub> = +85°C to +105°C ±1.0%@ T <sub>A</sub> = -20°C to +85°C ±1.5%@ T <sub>A</sub> = -40°C to -20°C
Serial array unit	UART CSI: f <sub>CLK</sub> /2 (supporting 16 Mbps), f <sub>CLK</sub> /4 Simplified I <sup>2</sup> C communication	UART CSI: f <sub>CLK</sub> /4 Simplified I <sup>2</sup> C communication
IICA	Normal mode Fast mode Fast mode plus	Normal mode Fast mode
Voltage detector	Rise detection voltage: 1.67 V to 4.06 V (14 levels) Fall detection voltage: 1.63 V to 3.98 V (14 levels)	Rise detection voltage: 2.61 V to 4.06 V (8 levels) Fall detection voltage: 2.55 V to 3.98 V (8 levels)

**Remark** The electrical characteristics of the products G: Industrial applications (T<sub>A</sub> = -40 to +105°C) are different from those of the products “A: Consumer applications, and D: Industrial applications”. For details, refer to 30.1 to 30.10.

### 30.1 Absolute Maximum Ratings

#### Absolute Maximum Ratings (T<sub>A</sub> = 25°C) (1/2)

Parameter	Symbols	Conditions	Ratings	Unit
Supply voltage	V <sub>DD</sub>		-0.5 to +6.5	V
	EV <sub>DD0</sub> , EV <sub>DD1</sub>	EV <sub>DD0</sub> = EV <sub>DD1</sub>	-0.5 to +6.5	V
	EV <sub>SS0</sub> , EV <sub>SS1</sub>	EV <sub>SS0</sub> = EV <sub>SS1</sub>	-0.5 to +0.3	V
REGC pin input voltage	V <sub>IREGC</sub>	REGC	-0.3 to +2.8 and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 1</sup>	V
Input voltage	V <sub>I1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147	-0.3 to EV <sub>DD0</sub> + 0.3 and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
	V <sub>I2</sub>	P60 to P63 (N-ch open-drain)	-0.3 to +6.5	V
	V <sub>I3</sub>	P20 to P27, P121 to P124, P137, P150 to P156, EXCLK, EXCLKS, RESET	-0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
Output voltage	V <sub>O1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	-0.3 to EV <sub>DD0</sub> + 0.3 and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
	V <sub>O2</sub>	P20 to P27, P150 to P156	-0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
Analog input voltage	V <sub>AI1</sub>	ANI16 to ANI26	-0.3 to EV <sub>DD0</sub> + 0.3 and -0.3 to AV <sub>REF</sub> (+) + 0.3 <sup>Notes 2, 3</sup>	V
	V <sub>AI2</sub>	ANI0 to ANI14	-0.3 to V <sub>DD</sub> + 0.3 and -0.3 to AV <sub>REF</sub> (+) + 0.3 <sup>Notes 2, 3</sup>	V

- Notes**
1. Connect the REGC pin to V<sub>SS</sub> via a capacitor (0.47 to 1 μF). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.
  2. Must be 6.5 V or lower.
  3. Do not exceed AV<sub>REF</sub>(+) + 0.3 V in case of A/D conversion target pin.

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

- Remarks**
1. Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.
  2. AV<sub>REF</sub>(+) : + side reference voltage of the A/D converter.
  3. V<sub>SS</sub> : Reference voltage

**Absolute Maximum Ratings (T<sub>A</sub> = 25°C) (2/2)**

Absolute Maximum Ratings (TA = 25 °C) (2/2)					
Parameter	Symbols	Conditions		Ratings	Unit
Output current, high	IOH1	Per pin	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	−40	mA
		Total of all pins −170 mA	P00 to P04, P07, P32 to P37, P40 to P47, P102 to P106, P120, P125 to P127, P130, P140 to P145	−70	mA
			P05, P06, P10 to P17, P30, P31, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100, P101, P110 to P117, P146, P147	−100	mA
	IOH2	Per pin	P20 to P27, P150 to P156	−0.5	mA
		Total of all pins		−2	mA
	Output current, low	IOL1	Per pin	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	40
Total of all pins 170 mA			P00 to P04, P07, P32 to P37, P40 to P47, P102 to P106, P120, P125 to P127, P130, P140 to P145	70	mA
			P05, P06, P10 to P17, P30, P31, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100, P101, P110 to P117, P146, P147	100	mA
IOL2		Per pin	P20 to P27, P150 to P156	1	mA
		Total of all pins		5	mA
Operating ambient temperature		TA	In normal operation mode		−40 to +105 <sup>note</sup>
	In flash memory programming mode				
Storage temperature	Tstg			−65 to +150	°C

**Note** Total operating time in 85°C to 105°C : 10,000 hours

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

## 30.2 Oscillator Characteristics

### 30.2.1 X1, XT1 oscillator characteristics

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Parameter	Resonator	Conditions	MIN.	TYP.	MAX.	Unit
X1 clock oscillation frequency (f <sub>x</sub> ) <sup>Note</sup>	Ceramic resonator/ crystal resonator	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	1.0		20.0	MHz
		2.4 V ≤ V <sub>DD</sub> < 2.7 V	1.0		16.0	MHz
XT1 clock oscillation frequency (f <sub>x</sub> ) <sup>Note</sup>	Crystal resonator		32	32.768	35	kHz

**Note** Indicates only permissible oscillator frequency ranges. Refer to AC Characteristics for instruction execution time. Request evaluation by the manufacturer of the oscillator circuit mounted on a board to check the oscillator characteristics.

**Caution** Since the CPU is started by the high-speed on-chip oscillator clock after a reset release, check the X1 clock oscillation stabilization time using the oscillation stabilization time counter status register (OSTC) by the user. Determine the oscillation stabilization time of the OSTC register and the oscillation stabilization time select register (OSTS) after sufficiently evaluating the oscillation stabilization time with the resonator to be used.

**Remark** When using the X1 oscillator and XT1 oscillator, refer to 5.4 System Clock Oscillator.

### 30.2.2 On-chip oscillator characteristics

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Oscillators	Parameters	Conditions		MIN.	TYP.	MAX.	Unit
High-speed on-chip oscillator clock frequency <sup>Notes 1, 2</sup>	f <sub>IH</sub>			1		32	MHz
High-speed on-chip oscillator clock frequency accuracy		-20 to +85 °C	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	-1.0		+1.0	%
		-40 to -20 °C	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	-1.5		+1.5	%
		+85 to +105 °C	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	-2.0		+2.0	%
Low-speed on-chip oscillator clock frequency	f <sub>IL</sub>				15		kHz
Low-speed on-chip oscillator clock frequency accuracy				-15		+15	%

**Notes 1.** High-speed on-chip oscillator frequency is selected by bits 0 to 3 of option byte (000C2H/010C2H) and bits 0 to 2 of HOCODIV register.

**2.** This indicates the oscillator characteristics only. Refer to AC Characteristics for instruction execution time.

### 30.3 DC Characteristics

#### 30.3.1 Pin characteristics

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (1/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output current, high <sup>Note 1</sup>	I <sub>OH1</sub>	Per pin for P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		-3.0 <sup>Note 2</sup>	mA
		Total of P00 to P04, P07, P32 to P37, P40 to P47, P102 to P106, P120, P125 to P127, P130, P140 to P145 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		-30.0	mA
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V		-10.0	mA
			2.4 V ≤ EV <sub>DD0</sub> < 2.7 V		-5.0	mA
		Total of P05, P06, P10 to P17, P30, P31, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100, P101, P110 to P117, P146, P147 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		-30.0	mA
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V		-19.0	mA
			2.4 V ≤ EV <sub>DD0</sub> < 2.7 V		-10.0	mA
		Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )	2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		-60.0	mA
	I <sub>OH2</sub>	Per pin for P20 to P27, P150 to P156	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V		-0.1 <sup>Note 2</sup>	mA
		Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V		-1.5	mA

**Notes** 1. Value of current at which the device operation is guaranteed even if the current flows from the EV<sub>DD0</sub>, EV<sub>DD1</sub>, V<sub>DD</sub> pins to an output pin.

2. Do not exceed the total current value.

3. Specification under conditions where the duty factor ≤ 70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (I<sub>OH</sub> × 0.7)/(n × 0.01)

<Example> Where n = 80% and I<sub>OH</sub> = -10.0 mA

$$\text{Total output current of pins} = (-10.0 \times 0.7) / (80 \times 0.01) \cong -8.7 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

**Caution** P00, P02 to P04, P10 to P15, P17, P43 to P45, P50, P52 to P55, P71, P74, P80 to P82, P96, and P142 to P144 do not output high level in N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.



(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (2/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output current, low <sup>Note 1</sup>	I <sub>OL1</sub>	Per pin for P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147			8.5 <sup>Note 2</sup>	mA
		Per pin for P60 to P63			15.0 <sup>Note 2</sup>	mA
		Total of P00 to P04, P07, P32 to P37, P40 to P47, P102 to P106, P120, P125 to P127, P130, P140 to P145 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		40.0	mA
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V		15.0	mA
			2.4 V ≤ EV <sub>DD0</sub> < 2.7 V		9.0	mA
		Total of P05, P06, P10 to P17, P30, P31, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100, P101, P110 to P117, P146, P147 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		40.0	mA
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V		35.0	mA
			2.4 V ≤ EV <sub>DD0</sub> < 2.7 V		20.0	mA
		Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )			80.0	mA
	I <sub>OL2</sub>	Per pin for P20 to P27, P150 to P156			0.4 <sup>Note 2</sup>	mA
		Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V		5.0	mA

**Notes** 1. Value of current at which the device operation is guaranteed even if the current flows from an output pin to the EV<sub>SS0</sub>, EV<sub>SS1</sub> and V<sub>SS</sub> pin.

2. Do not exceed the total current value.

3. Specification under conditions where the duty factor ≤ 70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (I<sub>OL</sub> × 0.7)/(n × 0.01)

<Example> Where n = 80% and I<sub>OL</sub> = 10.0 mA

$$\text{Total output current of pins} = (10.0 \times 0.7)/(80 \times 0.01) \cong 8.7 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (3/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input voltage, high	V <sub>IH1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147	0.8EV <sub>DD0</sub>		EV <sub>DD0</sub>	V
	V <sub>IH2</sub>	P01, P03, P04, P10, P11, P13 to P17, P43, P44, P53 to P55, P80, P81, P142, P143	TTL input buffer 4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	2.2	EV <sub>DD0</sub>	V
			TTL input buffer 3.3 V ≤ EV <sub>DD0</sub> < 4.0 V	2.0	EV <sub>DD0</sub>	V
			TTL input buffer 2.4 V ≤ EV <sub>DD0</sub> < 3.3 V	1.5	EV <sub>DD0</sub>	V
	V <sub>IH3</sub>	P20 to P27, P150 to P156	0.7V <sub>DD</sub>		V <sub>DD</sub>	V
	V <sub>IH4</sub>	P60 to P63	0.7EV <sub>DD0</sub>		6.0	V
	V <sub>IH5</sub>	P121 to P124, P137, EXCLK, EXCLKS, $\overline{\text{RESET}}$	0.8V <sub>DD</sub>		V <sub>DD</sub>	V
Input voltage, low	V <sub>IL1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147	0		0.2EV <sub>DD0</sub>	V
	V <sub>IL2</sub>	P01, P03, P04, P10, P11, P13 to P17, P43, P44, P53 to P55, P80, P81, P142, P143	TTL input buffer 4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	0	0.8	V
			TTL input buffer 3.3 V ≤ EV <sub>DD0</sub> < 4.0 V	0	0.5	V
			TTL input buffer 2.4 V ≤ EV <sub>DD0</sub> < 3.3 V	0	0.32	V
	V <sub>IL3</sub>	P20 to P27, P150 to P156	0		0.3V <sub>DD</sub>	V
	V <sub>IL4</sub>	P60 to P63	0		0.3EV <sub>DD0</sub>	V
	V <sub>IL5</sub>	P121 to P124, P137, EXCLK, EXCLKS, $\overline{\text{RESET}}$	0		0.2V <sub>DD</sub>	V

**Caution** The maximum value of V<sub>IH</sub> of pins P00, P02 to P04, P10 to P15, P17, P43 to P45, P50, P52 to P55, P71, P74, P80 to P82, P96, and P142 to P144 is EV<sub>DD0</sub>, even in the N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (4/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output voltage, high	V <sub>OH1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, I <sub>OH1</sub> = -3.0 mA	EV <sub>DD0</sub> - 0.7		V
			2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, I <sub>OH1</sub> = -2.0 mA	EV <sub>DD0</sub> - 0.6		V
			2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, I <sub>OH1</sub> = -1.5 mA	EV <sub>DD0</sub> - 0.5		V
	V <sub>OH2</sub>	P20 to P27, P150 to P156	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, I <sub>OH2</sub> = -100 μA	V <sub>DD</sub> - 0.5		V
Output voltage, low	V <sub>OL1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, I <sub>OL1</sub> = 8.5 mA		0.7	V
			4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, I <sub>OL1</sub> = 3.0 mA		0.6	V
			2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, I <sub>OL1</sub> = 1.5 mA		0.4	V
			2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, I <sub>OL1</sub> = 0.6 mA		0.4	V
	V <sub>OL2</sub>	P20 to P27, P150 to P156	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, I <sub>OL2</sub> = 400 μA		0.4	V
	V <sub>OL3</sub>	P60 to P63	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, I <sub>OL3</sub> = 15.0 mA		2.0	V
			4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, I <sub>OL3</sub> = 5.0 mA		0.4	V
			2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, I <sub>OL3</sub> = 3.0 mA		0.4	V
			2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, I <sub>OL3</sub> = 2.0 mA		0.4	V

**Caution** P00, P02 to P04, P10 to P15, P17, P43 to P45, P50, P52 to P55, P71, P74, P80 to P82, P96, and P142 to P144 do not output high level in N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (5/5)

Items	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Input leakage current, high	I <sub>LIH1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147	V <sub>I</sub> = EV <sub>DD0</sub>			1	μA
	I <sub>LIH2</sub>	P20 to P27, P137, P150 to P156, RESET	V <sub>I</sub> = V <sub>DD</sub>			1	μA
	I <sub>LIH3</sub>	P121 to P124 (X1, X2, XT1, XT2, EXCLK, EXCLKS)	V <sub>I</sub> = V <sub>DD</sub>	In input port or external clock input		1	μA
				In resonator connection		10	μA
Input leakage current, low	I <sub>LIL1</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147	V <sub>I</sub> = EV <sub>SS0</sub>			-1	μA
	I <sub>LIL2</sub>	P20 to P27, P137, P150 to P156, RESET	V <sub>I</sub> = V <sub>SS</sub>			-1	μA
	I <sub>LIL3</sub>	P121 to P124 (X1, X2, XT1, XT2, EXCLK, EXCLKS)	V <sub>I</sub> = V <sub>SS</sub>	In input port or external clock input		-1	μA
				In resonator connection		-10	μA
On-chip pll-up resistance	R <sub>U</sub>	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147	V <sub>I</sub> = EV <sub>SS0</sub> , In input port	10	20	100	kΩ

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

## 30.3.2 Supply current characteristics

## (1) Flash ROM: 16 to 64 KB of 20- to 64-pin products

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = 0 V) (1/2)

Parameter	Symbol	Conditions					MIN.	TYP.	MAX.	Unit
Supply current <sup>Note 1</sup>	I <sub>DD1</sub>	Operating mode	HS (high-speed main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 32 MHz <sup>Note 3</sup>	Basic operation	V <sub>DD</sub> = 5.0 V		2.1		mA
						V <sub>DD</sub> = 3.0 V		2.1		mA
					Normal operation	V <sub>DD</sub> = 5.0 V		4.6	7.5	mA
						V <sub>DD</sub> = 3.0 V		4.6	7.5	mA
				f <sub>IH</sub> = 24 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 5.0 V		3.7	5.8	mA
						V <sub>DD</sub> = 3.0 V		3.7	5.8	mA
				f <sub>IH</sub> = 16 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 5.0 V		2.7	4.2	mA
						V <sub>DD</sub> = 3.0 V		2.7	4.2	mA
			HS (high-speed main) mode <sup>Note 5</sup>	f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		3.0	4.9	mA
						Resonator connection		3.2	5.0	mA
					Normal operation	Square wave input		3.0	4.9	mA
						Resonator connection		3.2	5.0	mA
				f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		1.9	2.9	mA
						Resonator connection		1.9	2.9	mA
					Normal operation	Square wave input		1.9	2.9	mA
						Resonator connection		1.9	2.9	mA
		Subsystem clock operation		f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = -40°C	Normal operation	Square wave input		4.1	4.9	μA
						Resonator connection		4.2	5.0	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +25°C	Normal operation	Square wave input		4.1	4.9	μA
						Resonator connection		4.2	5.0	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +50°C	Normal operation	Square wave input		4.2	5.5	μA
						Resonator connection		4.3	5.6	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +70°C	Normal operation	Square wave input		4.3	6.3	μA
						Resonator connection		4.4	6.4	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +85°C	Normal operation	Square wave input		4.6	7.7	μA
						Resonator connection		4.7	7.8	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +105°C	Normal operation	Square wave input		6.9	19.7	μA
						Resonator connection		7.0	19.8	μA

(Notes and Remarks are listed on the next page.)

- Notes**
1. Total current flowing into V<sub>DD</sub> and EV<sub>DD0</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub> or V<sub>SS</sub>, EV<sub>SS0</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. When high-speed on-chip oscillator and subsystem clock are stopped.
  3. When high-speed system clock and subsystem clock are stopped.
  4. When high-speed on-chip oscillator and high-speed system clock are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation). However, not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
  5. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.  
HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$

- Remarks**
1. f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2. f<sub>IH</sub>: High-speed on-chip oscillator clock frequency
  3. f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
  4. Except subsystem clock operation, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

## (1) Flash ROM: 16 to 64 KB of 20- to 64-pin products

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ E<sub>VDD0</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = E<sub>VSS0</sub> = 0 V) (2/2)

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit	
Supply current Note 1	I <sub>DD2</sub> Note 2	HALT mode	HS (high-speed main) mode Note 7	f <sub>IH</sub> = 32 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.54	2.90	mA	
					V <sub>DD</sub> = 3.0 V		0.54	2.90	mA	
				f <sub>IH</sub> = 24 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.44	2.30	mA	
					V <sub>DD</sub> = 3.0 V		0.44	2.30	mA	
				f <sub>IH</sub> = 16 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.40	1.70	mA	
					V <sub>DD</sub> = 3.0 V		0.40	1.70	mA	
				HS (high-speed main) mode Note 7	f <sub>MX</sub> = 20 MHz Note 3, V <sub>DD</sub> = 5.0 V	Square wave input		0.28	1.90	mA
						Resonator connection		0.45	2.00	mA
					f <sub>MX</sub> = 20 MHz Note 3, V <sub>DD</sub> = 3.0 V	Square wave input		0.28	1.90	mA
						Resonator connection		0.45	2.00	mA
			f <sub>MX</sub> = 10 MHz Note 3, V <sub>DD</sub> = 5.0 V		Square wave input		0.19	1.02	mA	
					Resonator connection		0.26	1.10	mA	
			f <sub>MX</sub> = 10 MHz Note 3, V <sub>DD</sub> = 3.0 V		Square wave input		0.19	1.02	mA	
					Resonator connection		0.26	1.10	mA	
			Subsystem clock operation		f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = −40°C	Square wave input		0.25	0.57	μA
						Resonator connection		0.44	0.76	μA
				f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = +25°C	Square wave input		0.30	0.57	μA	
					Resonator connection		0.49	0.76	μA	
				f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = +50°C	Square wave input		0.37	1.17	μA	
					Resonator connection		0.56	1.36	μA	
				f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = +70°C	Square wave input		0.53	1.97	μA	
					Resonator connection		0.72	2.16	μA	
				f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = +85°C	Square wave input		0.82	3.37	μA	
					Resonator connection		1.01	3.56	μA	
			f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = +105°C	Square wave input		3.01	15.37	μA		
				Resonator connection		3.20	15.56	μA		
	I <sub>DD3</sub> Note 6	STOP mode Note 8	T <sub>A</sub> = −40°C					0.18	0.50	μA
			T <sub>A</sub> = +25°C					0.23	0.50	μA
			T <sub>A</sub> = +50°C					0.30	1.10	μA
			T <sub>A</sub> = +70°C					0.46	1.90	μA
			T <sub>A</sub> = +85°C					0.75	3.30	μA
			T <sub>A</sub> = +105°C					2.94	15.30	μA

(Notes and Remarks are listed on the next page.)

- Notes**
1. Total current flowing into V<sub>DD</sub> and EV<sub>DD0</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub> or V<sub>SS</sub>, EV<sub>SS0</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. During HALT instruction execution by flash memory.
  3. When high-speed on-chip oscillator and subsystem clock are stopped.
  4. When high-speed system clock and subsystem clock are stopped.
  5. When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
  6. Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
  7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.  
 HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$
  8. Regarding the value for current operate the subsystem clock in STOP mode, refer to that in HALT mode.

- Remarks**
1. f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2. f<sub>IH</sub>: High-speed on-chip oscillator clock frequency
  3. f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
  4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is T<sub>A</sub> = 25°C



**(2) Flash ROM: 96 to 256 KB of 30- to 100-pin products****(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (1/2)**

Parameter	Symbol	Conditions					MIN.	TYP.	MAX.	Unit
Supply current <sup>Note 1</sup>	I <sub>DD1</sub>	Operating mode	HS (high-speed main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 32 MHz <sup>Note 3</sup>	Basic operation	V <sub>DD</sub> = 5.0 V		2.3		mA
						V <sub>DD</sub> = 3.0 V		2.3		mA
				Normal operation		V <sub>DD</sub> = 5.0 V		5.2	9.2	mA
						V <sub>DD</sub> = 3.0 V		5.2	9.2	mA
				f <sub>IH</sub> = 24 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 5.0 V		4.1	7.0	mA
						V <sub>DD</sub> = 3.0 V		4.1	7.0	mA
				f <sub>IH</sub> = 16 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 5.0 V		3.0	5.0	mA
						V <sub>DD</sub> = 3.0 V		3.0	5.0	mA
			HS (high-speed main) mode <sup>Note 5</sup>	f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		3.4	5.9	mA
						Resonator connection		3.6	6.0	mA
				f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		3.4	5.9	mA
						Resonator connection		3.6	6.0	mA
				f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		2.1	3.5	mA
						Resonator connection		2.1	3.5	mA
				f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		2.1	3.5	mA
						Resonator connection		2.1	3.5	mA
		Subsystem clock operation		f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = -40°C	Normal operation	Square wave input		4.8	5.9	μA
						Resonator connection		4.9	6.0	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +25°C	Normal operation	Square wave input		4.9	5.9	μA
						Resonator connection		5.0	6.0	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +50°C	Normal operation	Square wave input		5.0	7.6	μA
						Resonator connection		5.1	7.7	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +70°C	Normal operation	Square wave input		5.2	9.3	μA
						Resonator connection		5.3	9.4	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +85°C	Normal operation	Square wave input		5.7	13.3	μA
						Resonator connection		5.8	13.4	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +105°C	Normal operation	Square wave input		10.0	46.0	μA
						Resonator connection		10.0	46.0	μA

(Notes and Remarks are listed on the next page.)

- Notes**
1. Total current flowing into V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, or V<sub>SS</sub>, EV<sub>SS0</sub>, and EV<sub>SS1</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. When high-speed on-chip oscillator and subsystem clock are stopped.
  3. When high-speed system clock and subsystem clock are stopped.
  4. When high-speed on-chip oscillator and high-speed system clock are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation). However, not including the current flowing into the 12-bit interval timer and watchdog timer.
  5. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.  
HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$

- Remarks**
1. f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2. f<sub>IH</sub>: High-speed on-chip oscillator clock frequency
  3. f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
  4. Except subsystem clock operation, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

**(2) Flash ROM: 96 to 256 KB of 30- to 100-pin products****(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (2/2)**

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit	
Supply current Note 1	I <sub>DD2</sub> Note 2	HALT mode	HS (high-speed main) mode Note 7	f <sub>IH</sub> = 32 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.62	3.40	mA	
					V <sub>DD</sub> = 3.0 V		0.62	3.40	mA	
				f <sub>IH</sub> = 24 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.50	2.70	mA	
					V <sub>DD</sub> = 3.0 V		0.50	2.70	mA	
				f <sub>IH</sub> = 16 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.44	1.90	mA	
					V <sub>DD</sub> = 3.0 V		0.44	1.90	mA	
				HS (high-speed main) mode Note 7	f <sub>MX</sub> = 20 MHz Note 3, V <sub>DD</sub> = 5.0 V	Square wave input		0.31	2.10	mA
						Resonator connection		0.48	2.20	mA
					f <sub>MX</sub> = 20 MHz Note 3, V <sub>DD</sub> = 3.0 V	Square wave input		0.31	2.10	mA
						Resonator connection		0.48	2.20	mA
			f <sub>MX</sub> = 10 MHz Note 3, V <sub>DD</sub> = 5.0 V		Square wave input		0.21	1.10	mA	
					Resonator connection		0.28	1.20	mA	
			f <sub>MX</sub> = 10 MHz Note 3, V <sub>DD</sub> = 3.0 V		Square wave input		0.21	1.10	mA	
					Resonator connection		0.28	1.20	mA	
			Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = −40°C	Square wave input		0.28	0.61	μA	
					Resonator connection		0.47	0.80	μA	
				f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = +25°C	Square wave input		0.34	0.61	μA	
					Resonator connection		0.53	0.80	μA	
				f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = +50°C	Square wave input		0.41	2.30	μA	
					Resonator connection		0.60	2.49	μA	
				f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = +70°C	Square wave input		0.64	4.03	μA	
					Resonator connection		0.83	4.22	μA	
				f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = +85°C	Square wave input		1.09	8.04	μA	
					Resonator connection		1.28	8.23	μA	
			f <sub>SUB</sub> = 32.768 kHz Note 5 T <sub>A</sub> = +105°C	Square wave input		5.50	41.00	μA		
				Resonator connection		5.50	41.00	μA		
	I <sub>DD3</sub> Note 6	STOP mode Note 8	T <sub>A</sub> = −40°C					0.19	0.52	μA
			T <sub>A</sub> = +25°C					0.25	0.52	μA
			T <sub>A</sub> = +50°C					0.32	2.21	μA
			T <sub>A</sub> = +70°C					0.55	3.94	μA
			T <sub>A</sub> = +85°C					1.00	7.95	μA
			T <sub>A</sub> = +105°C					5.00	40.00	μA

(Notes and Remarks are listed on the next page.)

- Notes**
1. Total current flowing into V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, or V<sub>SS</sub>, EV<sub>SS0</sub>, and EV<sub>SS1</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. During HALT instruction execution by flash memory.
  3. When high-speed on-chip oscillator and subsystem clock are stopped.
  4. When high-speed system clock and subsystem clock are stopped.
  5. When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
  6. Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
  7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.  
 HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$
  8. Regarding the value for current operate the subsystem clock in STOP mode, refer to that in HALT mode.

- Remarks**
1. f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2. f<sub>IH</sub>: High-speed on-chip oscillator clock frequency
  3. f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
  4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

**(3) Peripheral Functions (Common to all products)****(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions MIN.		TYP.	MAX.	Unit
Low-speed on-chip oscillator operating current	I <sub>FIL</sub> <sup>Note 1</sup>			0.20		μA
RTC operating current	I <sub>RTC</sub> <sup>Notes 1, 2, 3</sup>			0.02		μA
12-bit interval timer operating current	I <sub>IT</sub> <sup>Notes 1, 2, 4</sup>			0.22		μA
Watchdog timer operating current	I <sub>WDT</sub> <sup>Notes 1, 2, 5</sup>	f <sub>IL</sub> = 15 kHz		0.22		μA
A/D converter operating current	I <sub>ADC</sub> <sup>Notes 1, 6</sup>	When conversion at maximum speed	Normal mode, AV <sub>REFP</sub> = V <sub>DD</sub> = 5.0 V	1.3	1.7	mA
			Low voltage mode, AV <sub>REFP</sub> = V <sub>DD</sub> = 3.0 V	0.5	0.7	mA
A/D converter reference voltage current	I <sub>ADREF</sub> <sup>Note 1</sup>			75.0		μA
Temperature sensor operating current	I <sub>TMPS</sub> <sup>Note 1</sup>			75.0		μA
LVD operating current	I <sub>LVI</sub> <sup>Notes 1, 7</sup>			0.08		μA
Self programming operating current	I <sub>FSP</sub> <sup>Notes 1, 9</sup>			2.50	12.20	mA
BGO operating current	I <sub>BGO</sub> <sup>Notes 1, 8</sup>			2.50	12.20	mA
SNOOZE operating current	I <sub>SNOZ</sub> <sup>Note 1</sup>	ADC operation	The mode is performed <sup>Note 10</sup>	0.50	1.10	mA
			The A/D conversion operations are performed, Loe voltage mode, AV <sub>REFP</sub> = V <sub>DD</sub> = 3.0 V	1.20	2.04	mA
		CSI/UART operation		0.70	1.54	mA

**Notes** 1. Current flowing to the V<sub>DD</sub>.

- When high speed on-chip oscillator and high-speed system clock are stopped.
- Current flowing only to the real-time clock (RTC) (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either I<sub>DD1</sub> or I<sub>DD2</sub>, and I<sub>RTC</sub>, when the real-time clock operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, I<sub>FIL</sub> should be added. I<sub>DD2</sub> subsystem clock operation includes the operational current of the real-time clock.
- Current flowing only to the 12-bit interval timer (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either I<sub>DD1</sub> or I<sub>DD2</sub>, and I<sub>IT</sub>, when the 12-bit interval timer operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, I<sub>FIL</sub> should be added.
- Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The supply current of the RL78 is the sum of I<sub>DD1</sub>, I<sub>DD2</sub> or I<sub>DD3</sub> and I<sub>WDT</sub> when the watchdog timer operates.
- Current flowing only to the A/D converter. The supply current of the RL78 microcontrollers is the sum of I<sub>DD1</sub> or I<sub>DD2</sub> and I<sub>ADC</sub> when the A/D converter is in operation.

7. Current flowing only to the LVD circuit. The supply current of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$  and  $I_{LVD}$  when the LVD circuit is in operation.
8. Current flowing only during data flash rewrite.
9. Current flowing only during self programming.
10. For shift time to the SNOOZE mode, see **18.3.3 SNOOZE mode**.

- Remarks**
1.  $f_{IL}$ : Low-speed on-chip oscillator clock frequency
  2.  $f_{SUB}$ : Subsystem clock frequency (XT1 clock oscillation frequency)
  3.  $f_{CLK}$ : CPU/peripheral hardware clock frequency
  4. Temperature condition of the TYP. value is  $T_A = 25^{\circ}\text{C}$

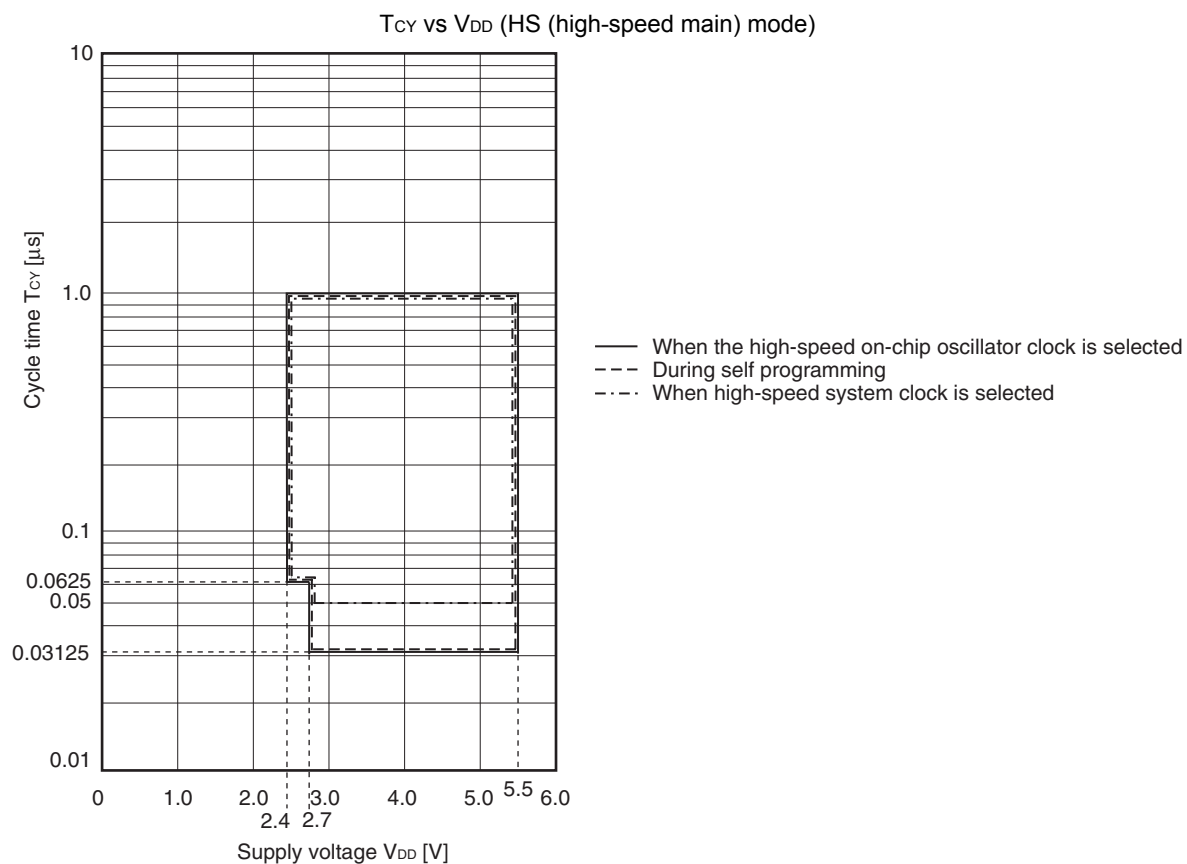
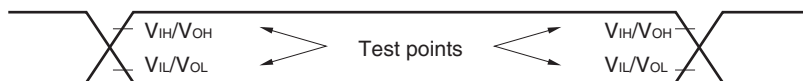
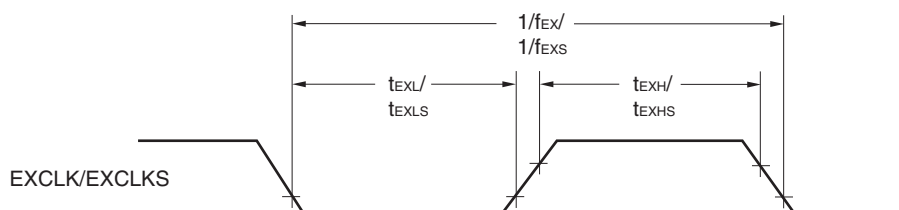
## 30.4 AC Characteristics

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ E<sub>VDD0</sub> = E<sub>VDD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = E<sub>VSS0</sub> = E<sub>VSS1</sub> = 0 V)

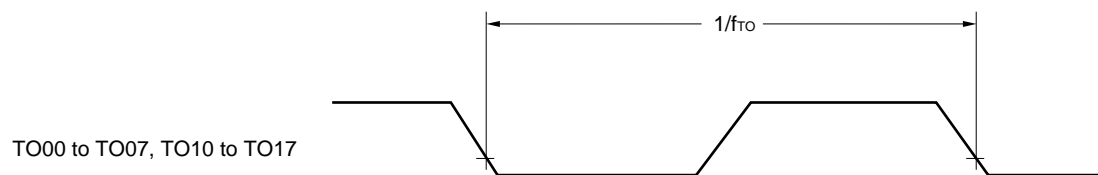
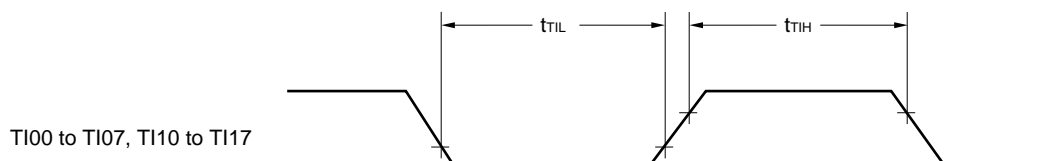
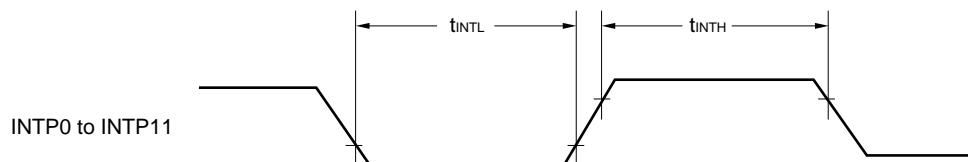
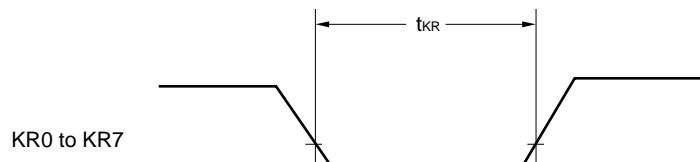
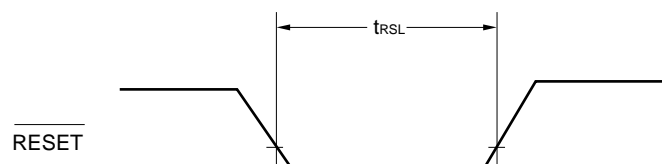
Items	Symbol	Conditions			MIN.	TYP.	MAX.	Unit
Instruction cycle (minimum instruction execution time)	T <sub>CY</sub>	Main system clock (f <sub>MAIN</sub> ) operation	HS (high-speed main) mode	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.03125		1	μs
				2.4 V ≤ V <sub>DD</sub> < 2.7 V	0.0625		1	μs
		Subsystem clock (f <sub>SUB</sub> ) operation		2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	28.5	30.5 31.3		μs
		In the self programming mode	HS (high-speed main) mode	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.03125		1	μs
				2.4 V ≤ V <sub>DD</sub> < 2.7 V	0.0625		1	μs
External system clock frequency	f <sub>EX</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V			1.0		20.0	MHz
		2.4 V ≤ V <sub>DD</sub> < 2.7 V			1.0		16.0	MHz
	f <sub>EXS</sub>				32	35		kHz
External system clock input high-level width, low-level width	t <sub>EXH</sub> , t <sub>EXL</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V			24			ns
		2.4 V ≤ V <sub>DD</sub> < 2.7 V			30			ns
	t <sub>EXHS</sub> , t <sub>EXLS</sub>				13.7			μs
TI00 to TI07, TI10 to TI17 input high-level width, low-level width	t <sub>TIH</sub> , t <sub>TIL</sub>				1/f <sub>MCK</sub> +10			ns <sup>Note</sup>
TO00 to TO07, TO10 to TO17 output frequency	f <sub>TO</sub>	HS (high-speed main) mode	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V				16	MHz
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V				8	MHz
			2.4 V ≤ EV <sub>DD0</sub> < 2.7 V				4	MHz
PCLBUZ0, PCLBUZ1 output frequency	f <sub>PCL</sub>	HS (high-speed main) mode	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V				16	MHz
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V				8	MHz
			2.4 V ≤ EV <sub>DD0</sub> < 2.7 V				4	MHz
Interrupt input high-level width, low-level width	t <sub>INTH</sub> , t <sub>INTL</sub>	INTP0	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V		1			μs
		INTP1 to INTP11	2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		1			μs
Key interrupt input low-level width	t <sub>KR</sub>	KR0 to KR7	2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		250			ns
RESET low-level width	t <sub>RSL</sub>				10			μs

**Note** The following conditions are required for low voltage interface when E<sub>VDD0</sub> < V<sub>DD</sub>2.4 V ≤ E<sub>VDD0</sub> < 2.7 V : MIN. 125 ns**Remark** f<sub>MCK</sub>: Timer array unit operation clock frequency(Operation clock to be set by the CKS<sub>mn</sub>0, CKS<sub>mn</sub>1 bits of timer mode register mn (TMR<sub>mn</sub>).

m: Unit number (m = 0, 1), n: Channel number (n = 0 to 7))

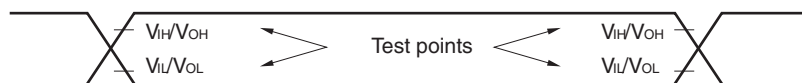
**Minimum Instruction Execution Time during Main System Clock Operation****AC Timing Test Points****External System Clock Timing**



**TI/TO Timing****Interrupt Request Input Timing****Key Interrupt Input Timing****RESET Input Timing**

## 30.5 Peripheral Functions Characteristics

### AC Timing Test Points



#### 30.5.1 Serial array unit

##### (1) During communication at same potential (UART mode)

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq E_{VDD0} = E_{VDD1} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = E_{VSS0} = E_{VSS1} = 0\text{ V}$ )

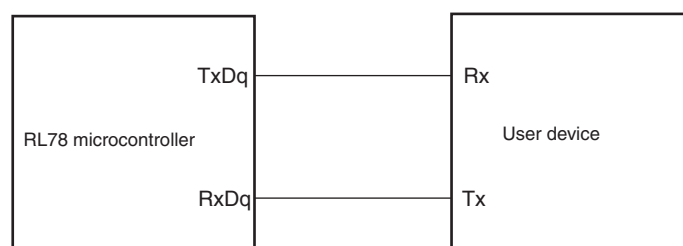
Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Transfer rate <sup>Note 1</sup>				$f_{MCK}/12$ <sup>Note 2</sup>	bps
		Theoretical value of the maximum transfer rate $f_{CLK} = 32\text{ MHz}$ , $f_{MCK} = f_{CLK}$		2.6	Mbps

**Notes 1.** Transfer rate in the SNOOZE mode is 4800 bps only.

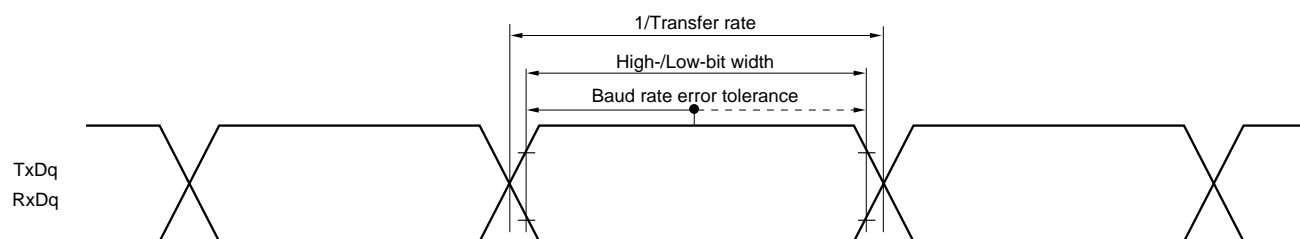
- 2.** The following conditions are required for low voltage interface when  $E_{VDD0} < V_{DD}$ .  
 $2.4\text{ V} \leq E_{VDD0} < 2.7\text{ V}$  : MAX. 1.3 Mbps

**Caution** Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

#### UART mode connection diagram (during communication at same potential)



#### UART mode bit width (during communication at same potential) (reference)



**Remarks 1.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 8, 14)

**2.**  $f_{MCK}$ : Serial array unit operation clock frequency

(Operation clock to be set by the CKSMn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

**(2) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output)****(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		Unit
				MIN.	MAX.	
SCKp cycle time	t <sub>KCY1</sub>	t <sub>KCY1</sub> ≥ 4/f <sub>CLK</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	250		ns
			2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	500		ns
SCKp high-/low-level width	t <sub>KH1</sub> , t <sub>KL1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY1</sub> /2 – 24		ns
		2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY1</sub> /2 – 36		ns
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY1</sub> /2 – 76		ns
Slp setup time (to SCKp↑) <sup>Note 1</sup>	t <sub>SIK1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		66		ns
		2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		66		ns
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		113		ns
Slp hold time (from SCKp↑) <sup>Note 2</sup>	t <sub>KSI1</sub>			38		ns
Delay time from SCKp↓ to SOp output <sup>Note 3</sup>	t <sub>KSO1</sub>	C = 30 pF <sup>Note 4</sup>			50	ns

- Notes**
1. When DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 0, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 1. The Slp setup time becomes “to SCKp↓” when DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 1, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 0.
  2. When DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 0, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 1. The Slp hold time becomes “from SCKp↓” when DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 1, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 0.
  3. When DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 0, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 1. The delay time to SOp output becomes “from SCKp↑” when DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 1, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 0.
  4. C is the load capacitance of the SCKp and SOp output lines.

**Caution** Select the normal input buffer for the Slp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

- Remarks**
1. p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), g: PIM and POM numbers (g = 0, 1, 4, 5, 8, 14)
  2. f<sub>MCK</sub>: Serial array unit operation clock frequency  
(Operation clock to be set by the CKS<sub>mn</sub> bit of serial mode register mn (SMR<sub>mn</sub>). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

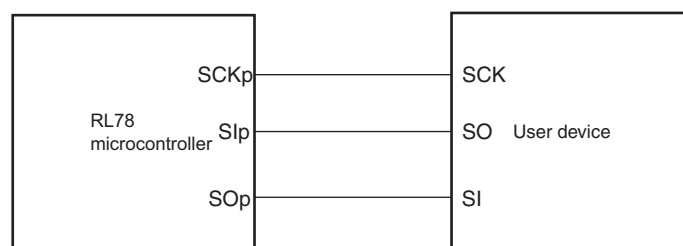
**(3) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input)****(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		Unit
				MIN.	MAX.	
SCKp cycle time <sup>Note 5</sup>	t <sub>KCY2</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	20 MHz < f <sub>MCK</sub>	16/f <sub>MCK</sub>		ns
			f <sub>MCK</sub> ≤ 20 MHz	12/f <sub>MCK</sub>		ns
		2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	16 MHz < f <sub>MCK</sub>	16/f <sub>MCK</sub>		ns
			f <sub>MCK</sub> ≤ 16 MHz	12/f <sub>MCK</sub>		ns
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		16/f <sub>MCK</sub>		ns
				12/f <sub>MCK</sub> and 1000		ns
SCKp high-/low-level width	t <sub>KH2</sub> , t <sub>KL2</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY2</sub> /2 - 14		ns
		2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY2</sub> /2 - 16		ns
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY2</sub> /2 - 36		ns
Slp setup time (to SCKp↑) <sup>Note 1</sup>	t <sub>SIK2</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		1/f <sub>MCK</sub> +40		ns
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		1/f <sub>MCK</sub> +60		ns
Slp hold time (from SCKp↑) <sup>Note 2</sup>	t <sub>KS12</sub>	2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		1/f <sub>MCK</sub> +62		ns
Delay time from SCKp↓ to SOp output <sup>Note 3</sup>	t <sub>KSO2</sub>	C = 30 pF <sup>Note 4</sup>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		2/f <sub>MCK</sub> +66	ns
			2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		2/f <sub>MCK</sub> +113	ns

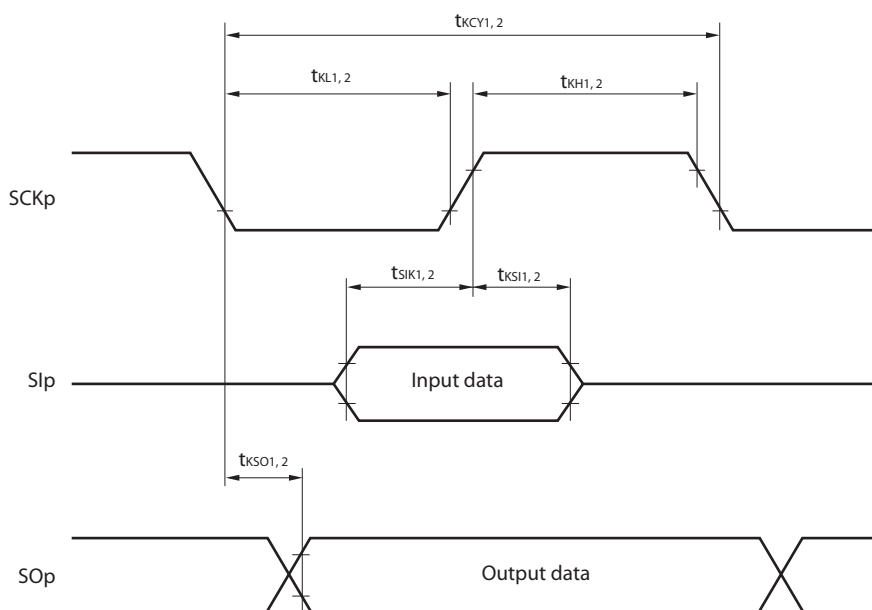
- Notes**
1. When DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 0, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 1. The Slp setup time becomes “to SCKp↓” when DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 1, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 0.
  2. When DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 0, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 1. The Slp hold time becomes “from SCKp↓” when DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 1, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 0.
  3. When DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 0, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 1. The delay time to SOp output becomes “from SCKp↑” when DAP<sub>mn</sub> = 0 and CKP<sub>mn</sub> = 1, or DAP<sub>mn</sub> = 1 and CKP<sub>mn</sub> = 0.
  4. C is the load capacitance of the SOp output lines.
  5. Transfer rate in the SNOOZE mode : MAX. 1 Mbps

**Caution** Select the normal input buffer for the Slp pin and SCKp pin and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

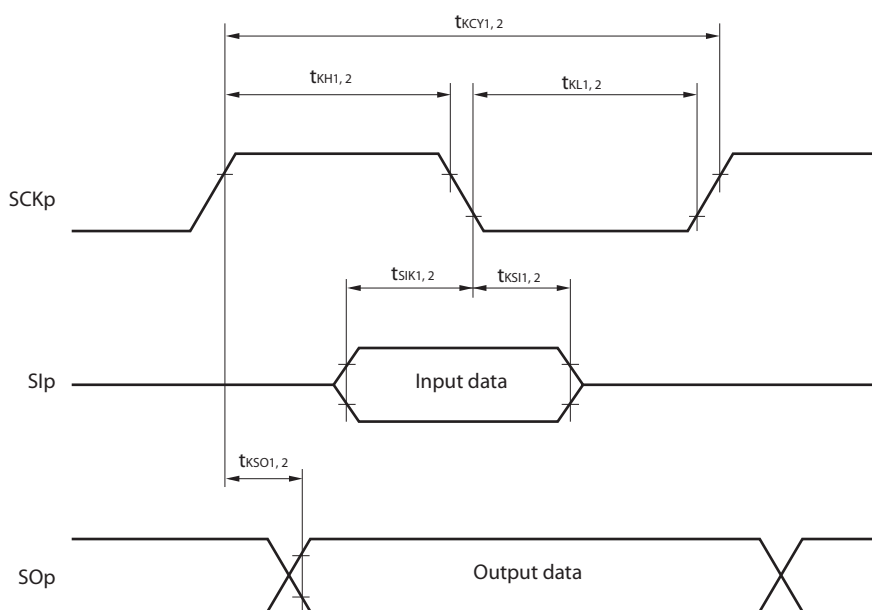
- Remarks**
1. p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1),  
n: Channel number (n = 0 to 3), g: PIM number (g = 0, 1, 4, 5, 8, 14)
  2. f<sub>MCK</sub>: Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

**CSI mode connection diagram (during communication at same potential)**

**CSI mode serial transfer timing (during communication at same potential)**  
**(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**CSI mode serial transfer timing (during communication at same potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



- Remarks**
1. p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31)
  2. m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13)

**(4) During communication at same potential (simplified I<sup>2</sup>C mode)****(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

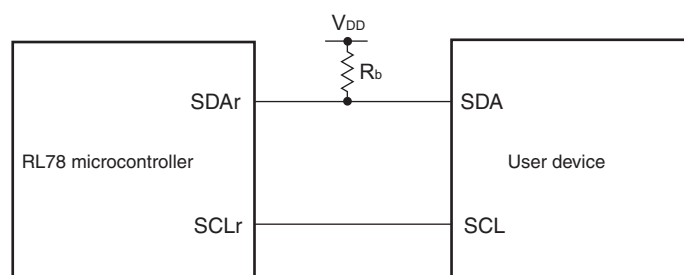
Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
SCLr clock frequency	f <sub>SCL</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ		400 <sup>Note1</sup>	kHz
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 3 kΩ		100 <sup>Note1</sup>	kHz
Hold time when SCLr = "L"	t <sub>LOW</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	1200		ns
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 3 kΩ	4600		ns
Hold time when SCLr = "H"	t <sub>HIGH</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	1200		ns
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 3 kΩ	4600		ns
Data setup time (reception)	t <sub>SU:DAT</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	1/f <sub>MCK</sub> + 220 <sup>Note2</sup>		ns
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 3 kΩ	1/f <sub>MCK</sub> + 580 <sup>Note2</sup>		ns
Data hold time (transmission)	t <sub>HD:DAT</sub>	2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	0	770	ns
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 3 kΩ	0	1420	ns

**Notes** 1. The value must also be equal to or less than f<sub>MCK</sub>/4.2. Set the f<sub>MCK</sub> value to keep the hold time of SCLr = "L" and SCLr = "H".

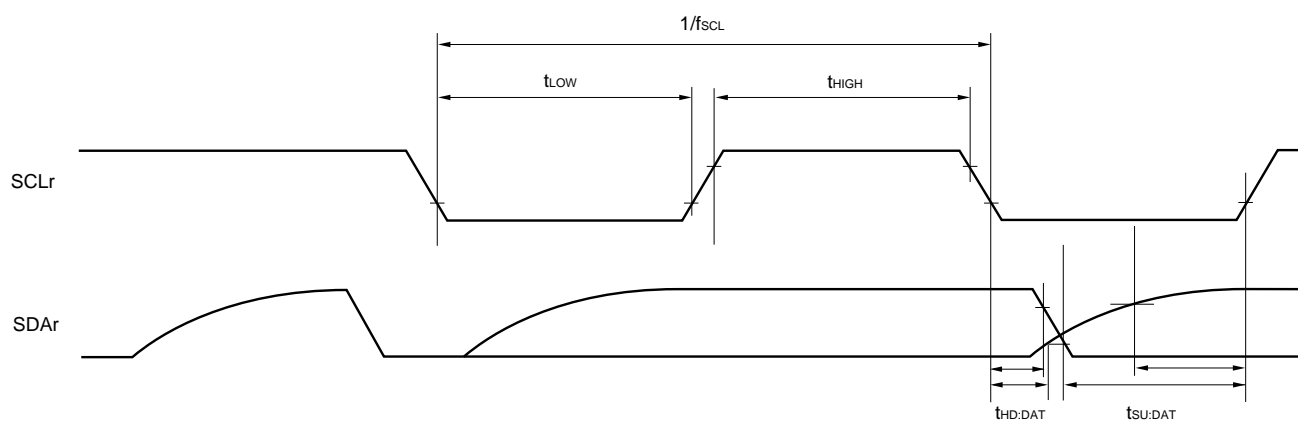
**Caution** Select the normal input buffer and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 100-pin products)) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

(Remarks are listed on the next page.)

### Simplified I<sup>2</sup>C mode connection diagram (during communication at same potential)



### Simplified I<sup>2</sup>C mode serial transfer timing (during communication at same potential)



- Remarks**
1.  $R_b[\Omega]$ : Communication line (SDAr) pull-up resistance,  $C_b[F]$ : Communication line (SDAr, SCLr) load capacitance
  2. r: IIC number (r = 00, 01, 10, 11, 20, 21, 30, 31), g: PIM number (g = 0, 1, 4, 5, 8, 14), h: POM number (g = 0, 1, 4, 5, 7 to 9, 14)
  3.  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), mn = 00 to 03, 10 to 13)

**(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (1/2)****(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Transfer rate		Reception	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V	f <sub>MCK</sub> /12 <sup>Note 1</sup>	bps
			Theoretical value of the maximum transfer rate f <sub>CLK</sub> = 32 MHz, f <sub>MCK</sub> = f <sub>CLK</sub>	2.6	Mbps
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V	f <sub>MCK</sub> /12 <sup>Note 1</sup>	bps
			Theoretical value of the maximum transfer rate f <sub>CLK</sub> = 32 MHz, f <sub>MCK</sub> = f <sub>CLK</sub>	2.6	Mbps
			2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V	f <sub>MCK</sub> /12 <sup>Notes 1,2</sup>	bps
			Theoretical value of the maximum transfer rate f <sub>CLK</sub> = 32 MHz, f <sub>MCK</sub> = f <sub>CLK</sub>	2.6	Mbps

**Notes 1.** Transfer rate in the SNOOZE mode is 4800 bps only.**2.** The following conditions are required for low voltage interface when EV<sub>DD0</sub> < V<sub>DD</sub>.2.4 V ≤ EV<sub>DD0</sub> < 2.7 V : MAX. 1.3 Mbps

**Caution** Select the TTL input buffer for the Rx<sub>Dq</sub> pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 100-pin products)) mode for the Tx<sub>Dq</sub> pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

**Remarks 1.** V<sub>b</sub>[V]: Communication line voltage**2.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 8, 14)**3.** f<sub>MCK</sub>: Serial array unit operation clock frequency(Operation clock to be set by the CKSm<sub>n</sub> bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))**4.** UART2 cannot communicate at different potential when bit 1 (PIOR1) of peripheral I/O redirection register (PIOR) is 1.



**(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (2/2)****(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Transfer rate		Transmission	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V	<b>Note 1</b>	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 1.4 kΩ, V <sub>b</sub> = 2.7 V	2.6 <sup>Note 2</sup>	Mbps
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V	<b>Note 3</b>	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ, V <sub>b</sub> = 2.3 V	1.2 <sup>Note 4</sup>	Mbps
			2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V	<b>Note 5</b>	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 5.5 kΩ, V <sub>b</sub> = 1.6 V	0.43 <sup>Note 6</sup>	Mbps

**Notes** 1. The smaller maximum transfer rate derived by using f<sub>MCK</sub>/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 4.0 V ≤ EV<sub>DD0</sub> ≤ 5.5 V and 2.7 V ≤ V<sub>b</sub> ≤ 4.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

- This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to Note 1 above to calculate the maximum transfer rate under conditions of the customer.
- The smaller maximum transfer rate derived by using f<sub>MCK</sub>/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 2.7 V ≤ EV<sub>DD0</sub> < 4.0 V and 2.4 V ≤ V<sub>b</sub> ≤ 2.7 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

- This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to Note 3 above to calculate the maximum transfer rate under conditions of the customer.

5. The smaller maximum transfer rate derived by using  $f_{MCK}/12$  or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when  $2.4\text{ V} \leq EV_{DD0} < 3.3\text{ V}$  and  $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\} \times 3} \text{ [bps]}$$

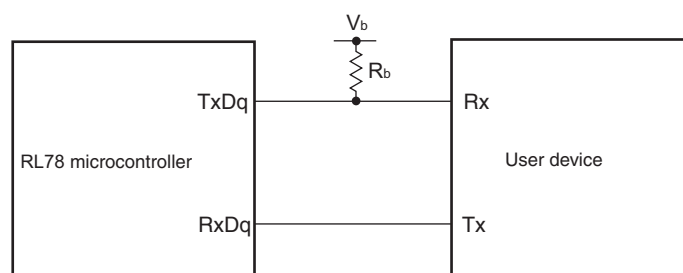
$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

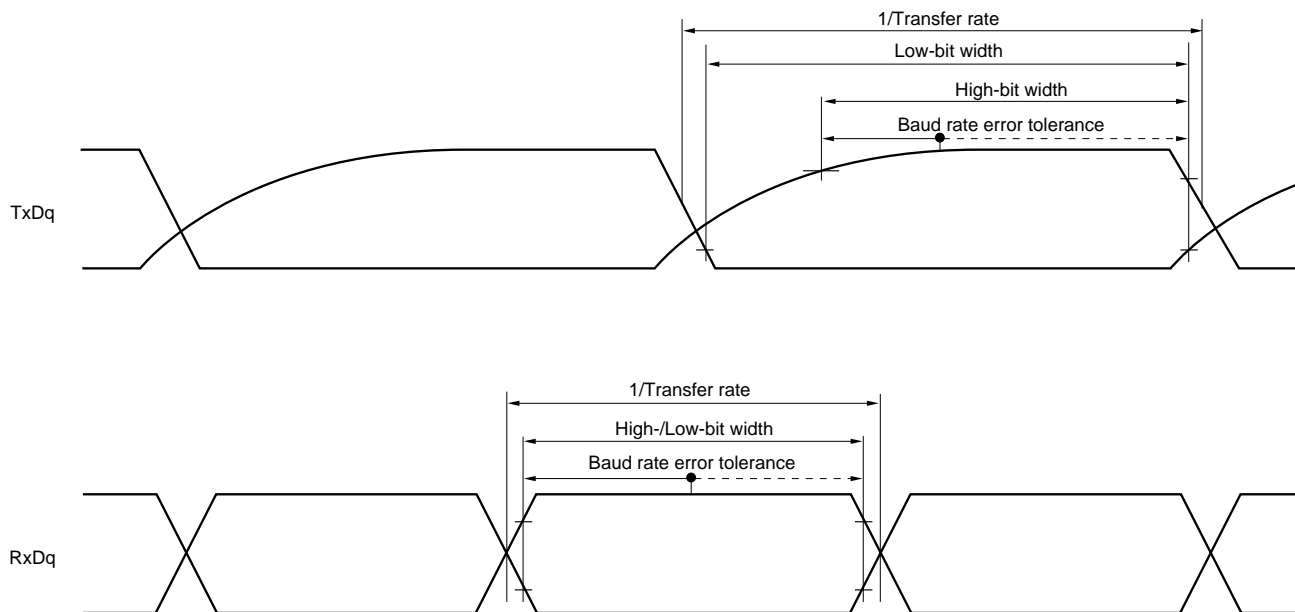
\* This value is the theoretical value of the relative difference between the transmission and reception sides.

6. This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to Note 5 above to calculate the maximum transfer rate under conditions of the customer.

**Caution** Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 100-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

UART mode connection diagram (during communication at different potential)



**UART mode bit width (during communication at different potential) (reference)**

- Remarks 1.**  $R_b[\Omega]$ : Communication line (TxDq) pull-up resistance,  
 $C_b[F]$ : Communication line (TxDq) load capacitance,  $V_b[V]$ : Communication line voltage
2.  $q$ : UART number ( $q = 0$  to  $3$ ),  $g$ : PIM and POM number ( $g = 0, 1, 8, 14$ )
  3.  $f_{MCK}$ : Serial array unit operation clock frequency  
 (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).  
 m: Unit number, n: Channel number ( $mn = 00$  to  $03, 10$  to  $13$ ))
  4. UART2 cannot communicate at different potential when bit 1 (PIOR1) of peripheral I/O redirection register (PIOR) is 1.

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (1/3)****(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		Unit
				MIN.	MAX.	
SCKp cycle time	t <sub>KCY1</sub>	t <sub>KCY1</sub> ≥ 4/f <sub>CLK</sub> 4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ		600		ns
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	1000		ns
			2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	2300		ns
SCKp high-level width	t <sub>KH1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ		t <sub>KCY1</sub> /2 – 150		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ		t <sub>KCY1</sub> /2 – 340		ns
		2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ		t <sub>KCY1</sub> /2 – 916		ns
SCKp low-level width	t <sub>KL1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ		t <sub>KCY1</sub> /2 – 24		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ		t <sub>KCY1</sub> /2 – 36		ns
		2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ		t <sub>KCY1</sub> /2 – 100		ns

**Caution** Select the TTL input buffer for the SIp pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

(Remarks are listed two pages after the next page.)

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (2/3)****(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Slp setup time (to SCKp↑) <sup>Note</sup>	t <sub>SIK1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	162		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	354		ns
		2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	958		ns
Slp hold time (from SCKp↑) <sup>Note</sup>	t <sub>SIH1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	38		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	38		ns
		2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	38		ns
Delay time from SCKp↓ to SOp output <sup>Note</sup>	t <sub>KSO1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ		200	ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ		390	ns
		2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ		966	ns

**Note** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.

**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the page after the next page.)

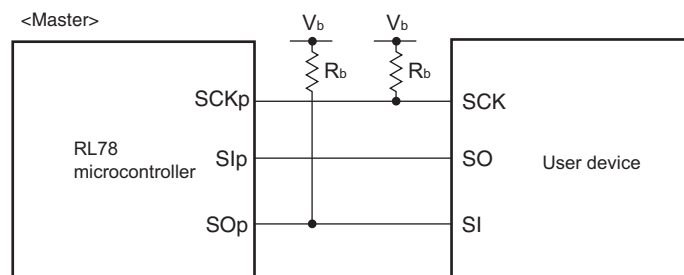
**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (3/3)****(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Slp setup time (to SCKp↓) <sup>Note</sup>	t <sub>SIK1</sub>	4.0 V ≤ EV <sub>DD</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	88		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	88		ns
		2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	220		ns
Slp hold time (from SCKp↓) <sup>Note</sup>	t <sub>KSI1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	38		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	38		ns
		2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	38		ns
Delay time from SCKp↑ to SOp output <sup>Note</sup>	t <sub>KSO1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ		50	ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ		50	ns
		2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ		50	ns

**Note** When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

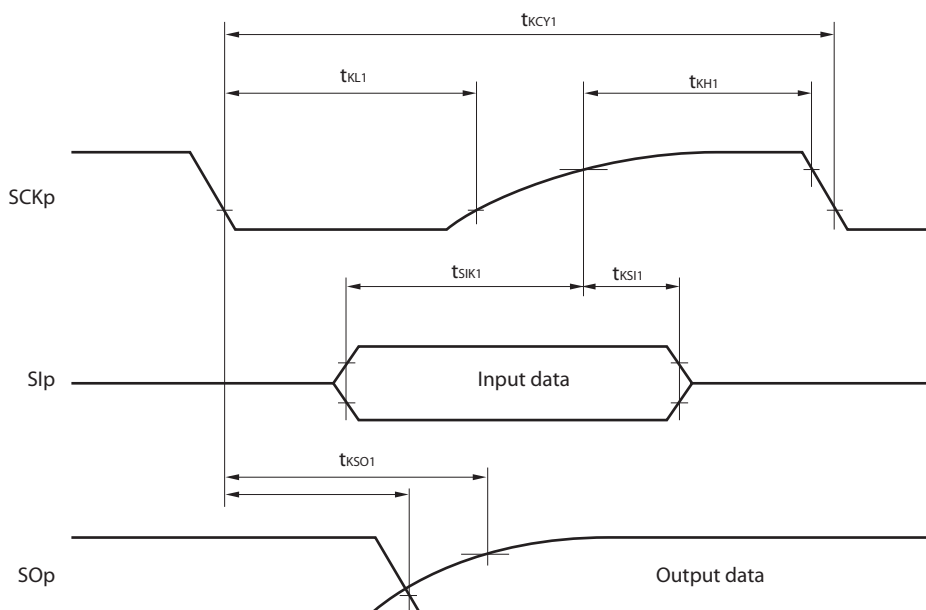
**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

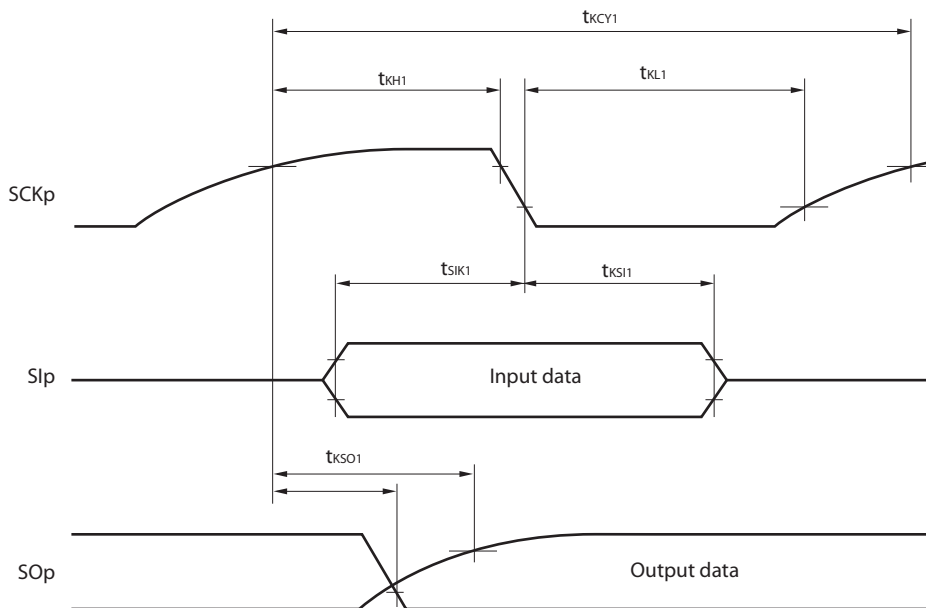
**CSI mode connection diagram (during communication at different potential)**

- Remarks**
1.  $R_b[\Omega]$ : Communication line (SCKp, SOp) pull-up resistance,  $C_b[F]$ : Communication line (SCKp, SOp) load capacitance,  $V_b[V]$ : Communication line voltage
  2. p: CSI number ( $p = 00, 01, 10, 20, 30, 31$ ), m: Unit number, n: Channel number ( $mn = 00, 01, 02, 10, 12, 13$ ), g: PIM and POM number ( $g = 0, 1, 4, 5, 8, 14$ )
  3.  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).  
m: Unit number, n: Channel number ( $mn = 00$ ))
  4. CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

**CSI mode serial transfer timing (master mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**CSI mode serial transfer timing (master mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



- Remarks**
1. p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number (m = 00, 01, 02, 10, 12, 13), n: Channel number (n = 0, 2), g: PIM and POM number (g = 0, 1, 4, 5, 8, 14)
  2. CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.



**(7) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (slave mode, SCKp... external clock input)**  
**(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

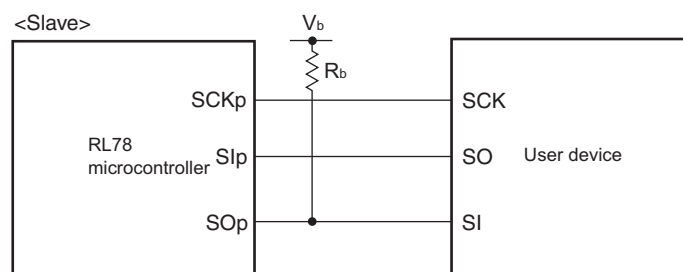
Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
SCKp cycle time <sup>Note 1</sup>	t <sub>KCY2</sub>	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V	24 MHz < f <sub>MCK</sub>	28/f <sub>MCK</sub>	ns
			20 MHz < f <sub>MCK</sub> ≤ 24 MHz	24/f <sub>MCK</sub>	ns
			8 MHz < f <sub>MCK</sub> ≤ 20 MHz	20/f <sub>MCK</sub>	ns
			4 MHz < f <sub>MCK</sub> ≤ 8 MHz	16/f <sub>MCK</sub>	ns
			f <sub>MCK</sub> ≤ 4 MHz	12/f <sub>MCK</sub>	ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V	24 MHz < f <sub>MCK</sub>	40/f <sub>MCK</sub>	ns
			20 MHz < f <sub>MCK</sub> ≤ 24 MHz	32/f <sub>MCK</sub>	ns
			16 MHz < f <sub>MCK</sub> ≤ 20 MHz	28/f <sub>MCK</sub>	ns
			8 MHz < f <sub>MCK</sub> ≤ 16 MHz	24/f <sub>MCK</sub>	ns
			4 MHz < f <sub>MCK</sub> ≤ 8 MHz	16/f <sub>MCK</sub>	ns
			f <sub>MCK</sub> ≤ 4 MHz	12/f <sub>MCK</sub>	ns
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V	24 MHz < f <sub>MCK</sub>	96/f <sub>MCK</sub>	ns
			20 MHz < f <sub>MCK</sub> ≤ 24 MHz	72/f <sub>MCK</sub>	ns
			16 MHz < f <sub>MCK</sub> ≤ 20 MHz	64/f <sub>MCK</sub>	ns
			8 MHz < f <sub>MCK</sub> ≤ 16 MHz	52/f <sub>MCK</sub>	ns
			4 MHz < f <sub>MCK</sub> ≤ 8 MHz	32/f <sub>MCK</sub>	ns
			f <sub>MCK</sub> ≤ 4 MHz	20/f <sub>MCK</sub>	ns
SCKp high-/low-level width	t <sub>KH2</sub> , t <sub>KL2</sub>	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V	t <sub>KCY2</sub> /2 - 24		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V	t <sub>KCY2</sub> /2 - 36		ns
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup>	t <sub>KCY2</sub> /2 - 100		ns
Slp setup time (to SCKp↑) <sup>Note 2</sup>	t <sub>SIK2</sub>	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V	1/f <sub>MCK</sub> + 40		ns
		2.7 V ≤ EVDD0 ≤ 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V	1/f <sub>MCK</sub> + 40		ns
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V	1/f <sub>MCK</sub> + 60		ns
Slp hold time (from SCKp↑) <sup>Note 3</sup>	t <sub>KSI2</sub>		1/f <sub>MCK</sub> + 62		ns
Delay time from SCKp↓ to SOp output <sup>Note 4</sup>	t <sub>KSO2</sub>	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ		2/f <sub>MCK</sub> + 240	ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ		2/f <sub>MCK</sub> + 428	ns
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ		2/f <sub>MCK</sub> + 1146	ns

(Notes, Caution and Remarks are listed on the next page.)

- Notes**
1. Transfer rate in the SNOOZE mode : MAX. 1 Mbps
  2. When  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 0$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 1$ . The  $\text{Slp}$  setup time becomes “to  $\text{SCKp}\downarrow$ ” when  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 1$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 0$ .
  3. When  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 0$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 1$ . The  $\text{Slp}$  hold time becomes “from  $\text{SCKp}\downarrow$ ” when  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 1$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 0$ .
  4. When  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 0$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 1$ . The delay time to  $\text{SOp}$  output becomes “from  $\text{SCKp}\uparrow$ ” when  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 1$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 0$ .

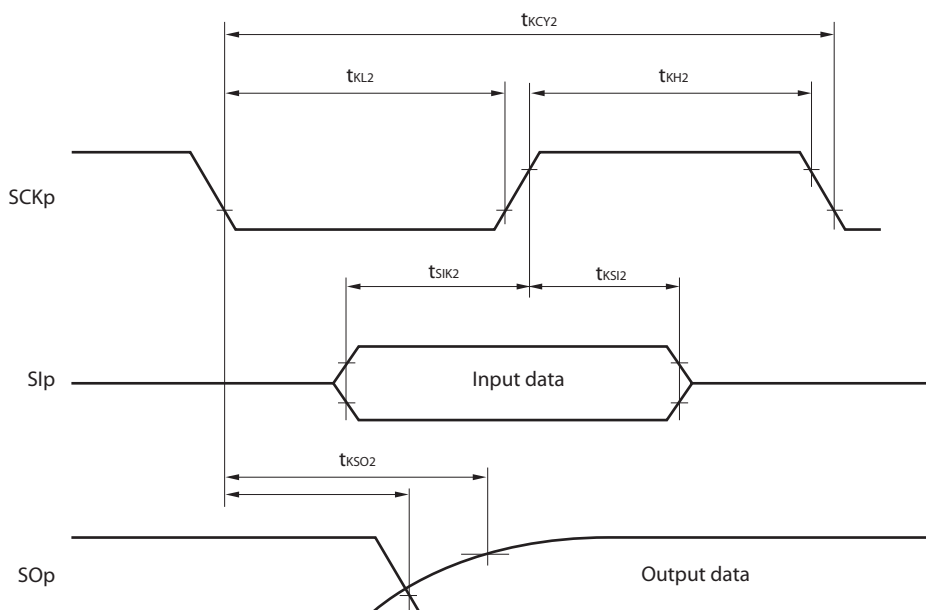
**Caution** Select the TTL input buffer for the  $\text{Slp}$  pin and  $\text{SCKp}$  pin and the N-ch open drain output ( $V_{DD}$  tolerance (When 20- to 52-pin products)/ $\text{EV}_{DD}$  tolerance (When 64- to 128-pin products)) mode for the  $\text{SOp}$  pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

CSI mode connection diagram (during communication at different potential)

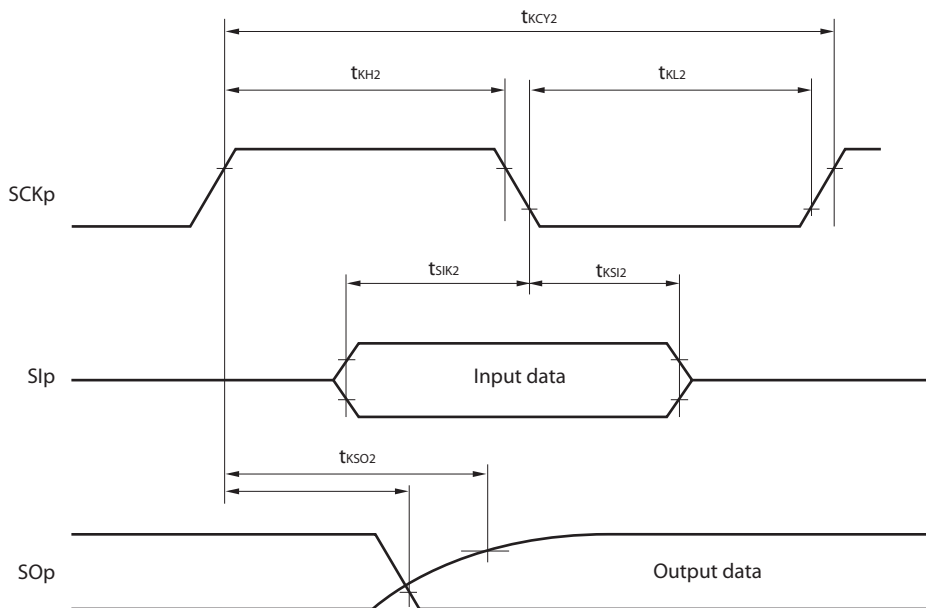


- Remarks**
1.  $R_b[\Omega]$ : Communication line ( $\text{SOp}$ ) pull-up resistance,  $C_b[\text{F}]$ : Communication line ( $\text{SOp}$ ) load capacitance,  $V_b[\text{V}]$ : Communication line voltage
  2. p: CSI number ( $p = 00, 01, 10, 20, 30, 31$ ), m: Unit number ( $m = 0, 1$ ), n: Channel number ( $n = 00, 01, 02, 10, 12, 13$ ), g: PIM and POM number ( $g = 0, 1, 4, 5, 8, 14$ )
  3.  $f_{\text{MCK}}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the  $\text{CKSmn}$  bit of serial mode register mn (SMRmn).  
m: Unit number, n: Channel number ( $mn = 00, 01, 02, 10, 12, 13$ ))
  4. CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

**CSI mode serial transfer timing (slave mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**CSI mode serial transfer timing (slave mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



- Remarks**
1. p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number,  
n: Channel number (mn = 00, 01, 02, 10, 12, 13), g: PIM and POM number (g = 0, 1, 4, 5, 8, 14)
  2. CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I2C mode) (1/2)****(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
SCLr clock frequency	f <sub>SCL</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ		400 <sup>Note 1</sup>	kHz
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ		400 <sup>Note 1</sup>	kHz
		4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.8 kΩ		100 <sup>Note 1</sup>	kHz
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.7 kΩ		100 <sup>Note 1</sup>	kHz
		2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 kΩ		100 <sup>Note 1</sup>	kHz
Hold time when SCLr = "L"	t <sub>LOW</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	1200		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	1200		ns
		4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.8 kΩ	4600		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.7 kΩ	4600		ns
		2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 kΩ	4650		ns
Hold time when SCLr = "H"	t <sub>HIGH</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	620		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	500		ns
		4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.8 kΩ	2700		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.7 kΩ	2400		ns
		2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 kΩ	1830		ns

(Notes, Caution and Remarks are listed on the next page.)

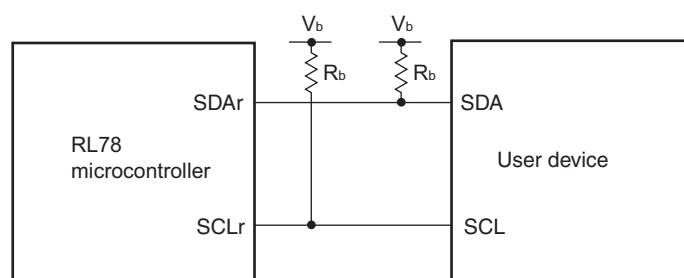
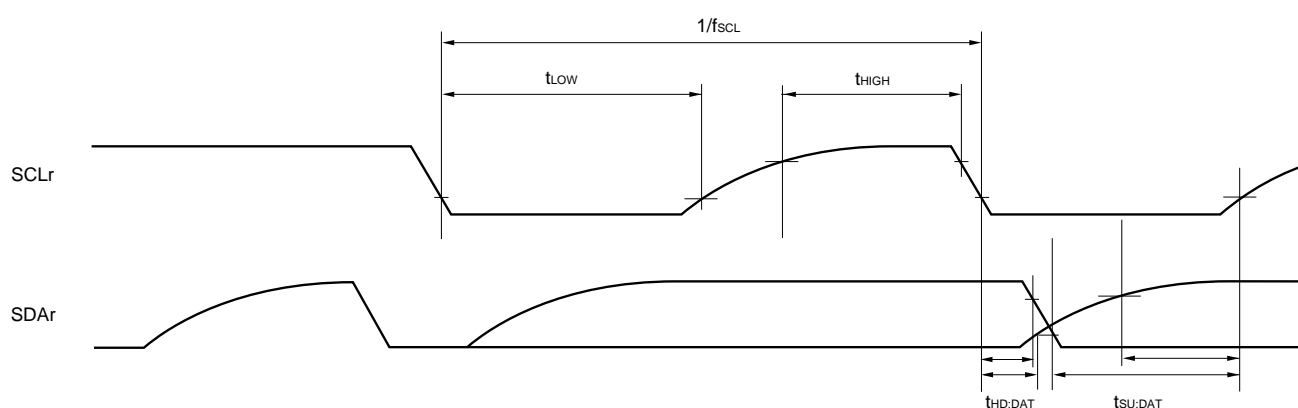
**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I2C mode) (2/2)****(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Data setup time (reception)	t <sub>SU:DAT</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	1/f <sub>MCK</sub> + 340 Note 2		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	1/f <sub>MCK</sub> + 340 Note 2		ns
		4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.8 kΩ	1/f <sub>MCK</sub> + 760 Note 2		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.7 kΩ	1/f <sub>MCK</sub> + 760 Note 2		ns
		2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 kΩ	1/f <sub>MCK</sub> + 570 Note 2		ns
Data hold time (transmission)	t <sub>HD:DAT</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	0	770	ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ	0	770	ns
		4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.8 kΩ	0	1420	ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.7 kΩ	0	1420	ns
		2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 kΩ	0	1215	ns

**Notes 1.** The value must also be equal to or less than f<sub>MCK</sub>/4.**2.** Set the f<sub>MCK</sub> value to keep the hold time of SCLr = "L" and SCLr = "H".

**Caution** Select the TTL input buffer and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 100-pin products)) mode for the SDAr pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 100-pin products)) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

**Simplified I<sup>2</sup>C mode connection diagram (during communication at different potential)****Simplified I<sup>2</sup>C mode serial transfer timing (during communication at different potential)**

**Caution** Select the TTL input buffer and the N-ch open drain output ( $V_{DD}$  tolerance (When 20- to 52-pin products)/ $EV_{DD}$  tolerance (When 64- to 100-pin products)) mode for the SDAr pin and the N-ch open drain output ( $V_{DD}$  tolerance (When 20- to 52-pin products)/ $EV_{DD}$  tolerance (When 64- to 100-pin products)) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

- Remarks**
1.  $R_b[\Omega]$ : Communication line (SDAr, SCLr) pull-up resistance,  $C_b[F]$ : Communication line (SDAr, SCLr) load capacitance,  $V_b[V]$ : Communication line voltage
  2. r: IIC number (r = 00, 01, 10, 20, 30, 31), g: PIM, POM number (g = 0, 1, 4, 5, 8, 14)
  3.  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01, 02, 10, 12, 13))

## 30.5.2 Serial interface IICA

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) Mode				Unit
			Standard Mode		Fast Mode		
			MIN.	MAX.	MIN.	MAX.	
SCLA0 clock frequency	f <sub>SCL</sub>	Fast mode: f <sub>CLK</sub> ≥ 3.5 MHz	-	-	0	400	kHz
		Standard mode: f <sub>CLK</sub> ≥ 1 MHz	0	100	-	-	kHz
Setup time of restart condition	t <sub>SU:STA</sub>		4.7		0.6		μs
Hold time <sup>Note 1</sup>	t <sub>HD:STA</sub>		4.0		0.6		μs
Hold time when SCLA0 = “L”	t <sub>LOW</sub>		4.7		1.3		μs
Hold time when SCLA0 = “H”	t <sub>HIGH</sub>		4.0		0.6		μs
Data setup time (reception)	t <sub>SU:DAT</sub>		250		100		ns
Data hold time (transmission) <sup>Note 2</sup>	t <sub>HD:DAT</sub>		0	3.45	0	0.9	μs
Setup time of stop condition	t <sub>SU:STO</sub>		4.0		0.6		μs
Bus-free time	t <sub>BUF</sub>		4.7		1.3		μs

- Notes**
1. The first clock pulse is generated after this period when the start/restart condition is detected.
  2. The maximum value (MAX.) of t<sub>HD:DAT</sub> is during normal transfer and a wait state is inserted in the  $\overline{\text{ACK}}$  (acknowledge) timing.

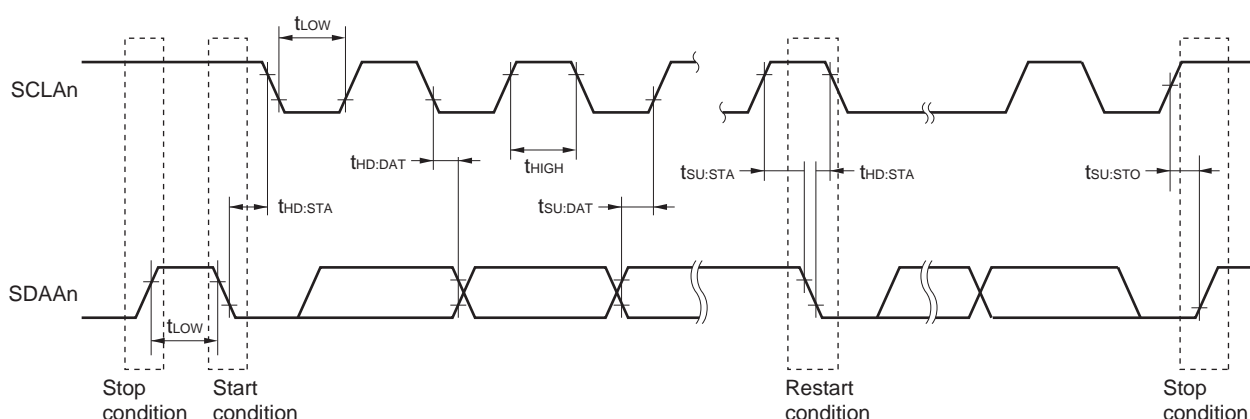
**Caution** The values in the above table are applied even when bit 2 (PIOR2) in the peripheral I/O redirection register (PIOR) is 1. At this time, the pin characteristics (I<sub>OH1</sub>, I<sub>OL1</sub>, V<sub>OH1</sub>, V<sub>OL1</sub>) must satisfy the values in the redirect destination.

**Remark** The maximum value of C<sub>b</sub> (communication line capacitance) and the value of R<sub>b</sub> (communication line pull-up resistor) at that time in each mode are as follows.

Standard mode: C<sub>b</sub> = 400 pF, R<sub>b</sub> = 2.7 kΩ

Fast mode: C<sub>b</sub> = 320 pF, R<sub>b</sub> = 1.1 kΩ

IICA serial transfer timing



**Remark** n = 0, 1

## 30.6 Analog Characteristics

### 30.6.1 A/D converter characteristics

Classification of A/D converter characteristics

Input channel	Reference Voltage		
	Reference voltage (+) = AV <sub>REFP</sub> Reference voltage (-) = AV <sub>REFM</sub>	Reference voltage (+) = V <sub>DD</sub> Reference voltage (-) = V <sub>SS</sub>	Reference voltage (+) = V <sub>BGR</sub> Reference voltage (-) = AV <sub>REFM</sub>
ANI0 to ANI14	Refer to 30.6.1 (1).	Refer to 30.6.1 (3).	Refer to 30.6.1 (3).
ANI16 to ANI26	Refer to 30.6.1 (2).		
Internal reference voltage Temperature sensor output voltage	Refer to 30.6.1 (1).		—

(1) When reference voltage (+) = AV<sub>REFP</sub>/ANI0 (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) = AV<sub>REFM</sub>/ANI1 (ADREFM = 1), target pin : ANI2 to ANI14, internal reference voltage, and temperature sensor output voltage

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ AV<sub>REFP</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V, Reference voltage (+) = AV<sub>REFP</sub>, Reference voltage (-) = AV<sub>REFM</sub> = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8		10	bit
Overall error <sup>Note 1</sup>	AINL	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Note 3</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		1.2	±3.5	LSB
Conversion time	t <sub>CONV</sub>	10-bit resolution Target pin: ANI2 to ANI14	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.125		39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.1875		39	μs
			2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17	39		μs
		10-bit resolution Target pin: Internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode)	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.375		39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.5625		39	μs
			2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17	39		μs
Zero-scale error <sup>Notes 1, 2</sup>	E <sub>ZS</sub>	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Note 3</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V			±0.25	%FSR
Full-scale error <sup>Notes 1, 2</sup>	E <sub>FS</sub>	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Note 3</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V			±0.25	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Note 3</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V			±2.5	LSB
Differential linearity error <sup>Note 1</sup>	DLE	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Note 3</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V			±1.5	LSB
Analog input voltage	V <sub>AIN</sub>	ANI2 to ANI14		0		AV <sub>REFP</sub>	V
		Internal reference voltage output (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)		V <sub>BGR</sub> <sup>Note 4</sup>			V
		Temperature sensor output voltage (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)		V <sub>TMPS25</sub> <sup>Note 4</sup>			V

(Notes are listed on the next page.)



- Notes**
1. Excludes quantization error ( $\pm 1/2$  LSB).
  2. This value is indicated as a ratio (%FSR) to the full-scale value.
  3. When  $AV_{REFP} < V_{DD}$ , the MAX. values are as follows.  
Overall error: Add  $\pm 1.0$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .  
Zero-scale error/Full-scale error: Add  $\pm 0.05\%$ FSR to the MAX. value when  $AV_{REFP} = V_{DD}$ .  
Integral linearity error/ Differential linearity error: Add  $\pm 0.5$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .
  4. Refer to **30.6.2 Temperature sensor/internal reference voltage characteristics**.

(2) When reference voltage (+) = AV<sub>REFP</sub>/ANI0 (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) = AV<sub>REFM</sub>/ANI1 (ADREFM = 1), target pin : ANI16 to ANI26

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, 2.4 V ≤ AV<sub>REFP</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V, Reference voltage (+) = AV<sub>REFP</sub>, Reference voltage (-) = AV<sub>REFM</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES		8		10	bit
Overall error <sup>Note 1</sup>	AINL	10-bit resolution EV <sub>DD0</sub> ≤ AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Notes 3, 4</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		1.2	±5.0 LSB
Conversion time	t <sub>CONV</sub>	10-bit resolution Target pin : ANI16 to ANI26	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.125		39 μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.1875		39 μs
			2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17		39 μs
Zero-scale error <sup>Notes 1, 2</sup>	E <sub>ZS</sub>	10-bit resolution EV <sub>DD0</sub> ≤ AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Notes 3, 4</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V			±0.35 %FSR
Full-scale error <sup>Notes 1, 2</sup>	E <sub>FS</sub>	10-bit resolution EV <sub>DD0</sub> ≤ AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Notes 3, 4</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V			±0.35 %FSR
Integral linearity error <sup>Note 1</sup>	ILE	10-bit resolution EV <sub>DD0</sub> ≤ AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Notes 3, 4</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V			±3.5 LSB
Differential linearity error <sup>Note 1</sup>	DLE	10-bit resolution EV <sub>DD0</sub> ≤ AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Notes 3, 4</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V			±2.0 LSB
Analog input voltage	V <sub>AIN</sub>	ANI16 to ANI26	0		AV <sub>REFP</sub> and EV <sub>DD0</sub>	V

**Notes** 1. Excludes quantization error (±1/2 LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. When AV<sub>REFP</sub> < V<sub>DD</sub>, the MAX. values are as follows.

Overall error: Add ±1.0 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Zero-scale error/Full-scale error: Add ±0.05%FSR to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Integral linearity error/ Differential linearity error: Add ±0.5 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

4. When AV<sub>REFP</sub> < EV<sub>DD0</sub> ≤ V<sub>DD</sub>, the MAX. values are as follows.

Overall error: Add ±4.0 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Zero-scale error/Full-scale error: Add ±0.20%FSR to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Integral linearity error/ Differential linearity error: Add ±2.0 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

(3) When reference voltage (+) = V<sub>DD</sub> (ADREFP1 = 0, ADREFP0 = 0), reference voltage (-) = V<sub>SS</sub> (ADREFM = 0), target pin : ANI0 to ANI14, ANI16 to ANI26, internal reference voltage, and temperature sensor output voltage

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V, Reference voltage (+) = V<sub>DD</sub>, Reference voltage (-) = V<sub>SS</sub>)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8		10	bit
Overall error <sup>Note 1</sup>	AINL	10-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V		1.2	±7.0	LSB
Conversion time	t <sub>CONV</sub>	10-bit resolution Target pin: ANI0 to ANI14, ANI16 to ANI26	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.125		39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.1875		39	μs
			2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17		39	μs
		10-bit resolution Target pin: internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode)	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.375		39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.5625		39	μs
			2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17		39	μs
Zero-scale error <sup>Notes 1, 2</sup>	E <sub>ZS</sub>	10-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±0.60	%FSR
Full-scale error <sup>Notes 1, 2</sup>	E <sub>FS</sub>	10-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±0.60	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	10-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±4.0	LSB
Differential linearity error <sup>Note 1</sup>	DLE	10-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±2.0	LSB
Analog input voltage	V <sub>AIN</sub>	ANI0 to ANI14		0		V <sub>DD</sub>	V
		ANI16 to ANI26		0		EV <sub>DD0</sub>	V
		Internal reference voltage output (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)		V <sub>BGR</sub> <sup>Note 3</sup>			V
		Temperature sensor output voltage (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)		V <sub>TMPS25</sub> <sup>Note 3</sup>			V

**Notes** 1. Excludes quantization error (±1/2 LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. Refer to **30.6.2 Temperature sensor/internal reference voltage characteristics**.

(4) When reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), reference voltage (-) = AV<sub>REFM</sub>/ANI1 (ADREFM = 1), target pin : ANI0, ANI2 to ANI14, ANI16 to ANI26

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V, Reference voltage (+) = V<sub>BGR</sub><sup>Note 3</sup>, Reference voltage (-) = AV<sub>REFM</sub><sup>Note 4</sup> = 0 V, HS (high-speed main) mode)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8			bit
Conversion time	t <sub>CONV</sub>	8-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17		39	μs
Zero-scale error <sup>Notes 1, 2</sup>	E <sub>zs</sub>	8-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±0.60	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	8-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±2.0	LSB
Differential linearity error <sup>Note 1</sup>	DLE	8-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±1.0	LSB
Analog input voltage	V <sub>AIN</sub>			0		V <sub>BGR</sub> <sup>Note 3</sup>	V

**Notes** 1. Excludes quantization error (±1/2 LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. Refer to **30.6.2 Temperature sensor/internal reference voltage characteristics**.

4. When reference voltage (-) = V<sub>SS</sub>, the MAX. values are as follows.

Zero-scale error: Add ±0.35%FSR to the MAX. value when reference voltage (-) = AV<sub>REFM</sub>.

Integral linearity error: Add ±0.5 LSB to the MAX. value when reference voltage (-) = AV<sub>REFM</sub>.

Differential linearity error: Add ±0.2 LSB to the MAX. value when reference voltage (-) = AV<sub>REFM</sub>.

### 30.6.2 Temperature sensor/internal reference voltage characteristics

( $T_A = -40$  to  $+105^{\circ}\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ , HS (high-speed main) mode)

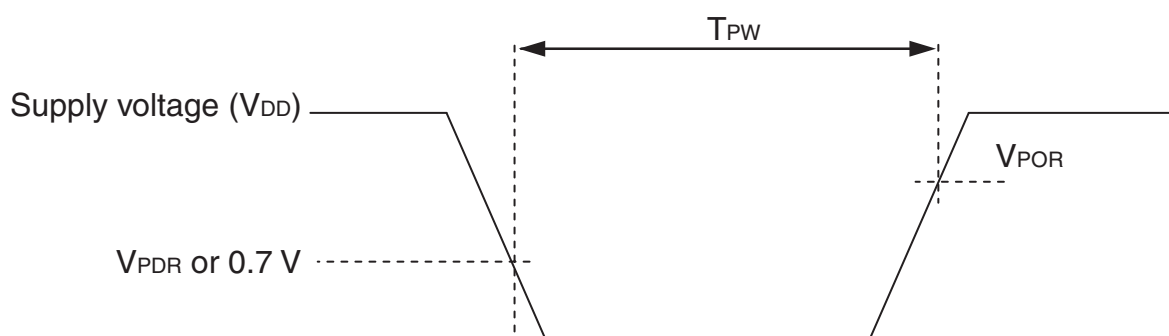
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Temperature sensor output voltage	$V_{TMPS25}$	Setting ADS register = 80H, $T_A = +25^{\circ}\text{C}$		1.05		V
Internal reference voltage	$V_{BGR}$	Setting ADS register = 81H	1.38	1.45	1.5	V
Temperature coefficient	$F_{VTMPS}$	Temperature sensor that depends on the temperature		-3.6		mV/ $^{\circ}\text{C}$
Operation stabilization wait time	$t_{AMP}$		5			$\mu\text{s}$

### 30.6.3 POR circuit characteristics

( $T_A = -40$  to  $+105^{\circ}\text{C}$ ,  $V_{SS} = 0\text{ V}$ )

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Detection voltage	$V_{POR}$	Power supply rise time	1.45	1.51	1.57	V
	$V_{PDR}$	Power supply fall time	1.44	1.50	1.56	V
Minimum pulse width	$T_{PW}$		300			$\mu\text{s}$

**Note** Minimum time required for a POR reset when  $V_{DD}$  exceeds below  $V_{PDR}$ . This is also the minimum time required for a POR reset from when  $V_{DD}$  exceeds below 0.7 V to when  $V_{DD}$  exceeds  $V_{POR}$  while STOP mode is entered or the main system clock is stopped through setting bit 0 (HIOSSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



## 30.6.4 LVD circuit characteristics

## LVD Detection Voltage of Reset Mode and Interrupt Mode

(T<sub>A</sub> = -40 to +105°C, V<sub>PDR</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Detection voltage	Supply voltage level	VLVD0	Power supply rise time	3.90	4.06	4.22	V
			Power supply fall time	3.83	3.98	4.13	V
		VLVD1	Power supply rise time	3.60	3.75	3.90	V
			Power supply fall time	3.53	3.67	3.81	V
		VLVD2	Power supply rise time	3.01	3.13	3.25	V
			Power supply fall time	2.94	3.06	3.18	V
		VLVD3	Power supply rise time	2.90	3.02	3.14	V
			Power supply fall time	2.85	2.96	3.07	V
		VLVD4	Power supply rise time	2.81	2.92	3.03	V
			Power supply fall time	2.75	2.86	2.97	V
		VLVD5	Power supply rise time	2.70	2.81	2.92	V
			Power supply fall time	2.64	2.75	2.86	V
		VLVD6	Power supply rise time	2.61	2.71	2.81	V
			Power supply fall time	2.55	2.65	2.75	V
		VLVD7	Power supply rise time	2.51	2.61	2.71	V
			Power supply fall time	2.45	2.55	2.65	V
Minimum pulse width		tLW		300			μs
Detection delay time						300	μs

## LVD Detection Voltage of Interrupt &amp; Reset Mode

(T<sub>A</sub> = -40 to +105°C, V<sub>PDR</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Interrupt and reset mode	V <sub>LVD5</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC0</sub> = 0, 1, 1, falling reset voltage		2.64	2.75	2.86	V
	V <sub>LVD4</sub>	LVIS1, LVIS0 = 1, 0	Rising release reset voltage	2.81	2.92	3.03	V
			Falling interrupt voltage	2.75	2.86	2.97	V
	V <sub>LVD3</sub>	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	2.90	3.02	3.14	V
			Falling interrupt voltage	2.85	2.96	3.07	V
	V <sub>LVD0</sub>	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	3.90	4.06	4.22	V
			Falling interrupt voltage	3.83	3.98	4.13	V

### 30.6.5 Power supply voltage rising slope characteristics

(T<sub>A</sub> = -40 to +105°C, V<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	S <sub>VDD</sub>				54	V/ms

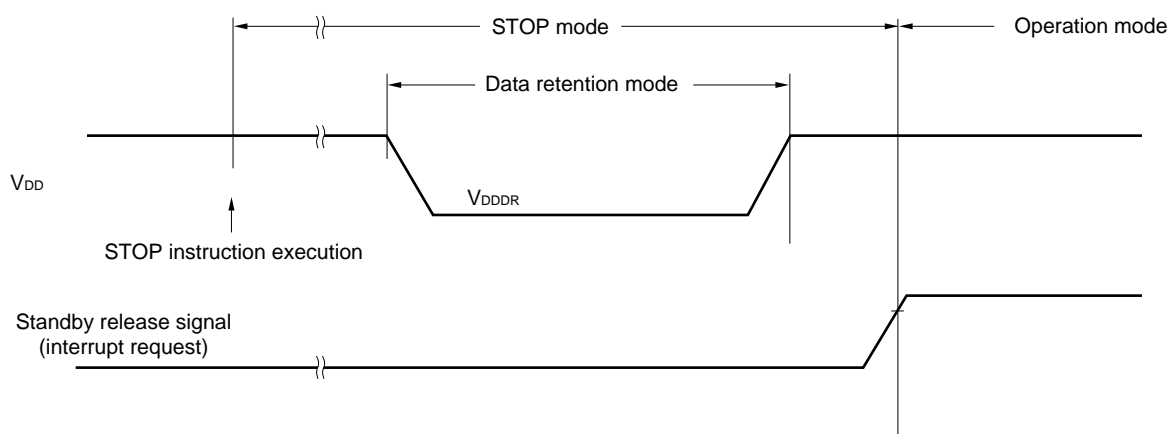
**Caution** Make sure to keep the internal reset state by the LVD circuit or an external reset until V<sub>DD</sub> reaches the operating voltage range shown in 30.4 AC Characteristics.

### 30.7 Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics

(T<sub>A</sub> = -40 to +105°C, V<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention supply voltage	V <sub>DDDR</sub>		1.44 <sup>Note</sup>		5.5	V

**Note** The value depends on the POR detection voltage. When the voltage drops, the data is retained before a POR reset is effected, but data is not retained when a POR reset is effected.



### 30.8 Flash Memory Programming Characteristics

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
CPU/peripheral hardware clock frequency	f <sub>CLK</sub>	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V		1		32	MHz
Number of code flash rewrites Note1,2,3	C <sub>erwr</sub>	Retained for 20 years	T <sub>A</sub> = 85°C Note3	1,000			Times
Number of data flash rewrites Note1,2,3		Retained for 1 years	T <sub>A</sub> = 25°C Note3		1,000,000		
		Retained for 5 years	T <sub>A</sub> = 85°C Note3	100,000			
		Retained for 20 years	T <sub>A</sub> = 85°C Note3	10,000			

- Notes**
- 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.
  2. When using flash memory programmer and Renesas Electronics self programming library.
  3. These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.

### 30.9 Dedicated Flash Memory Programmer Communication (UART)

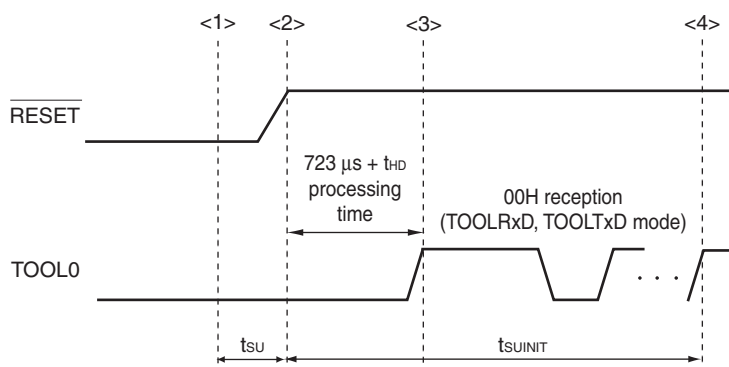
(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		During flash memory programming	115,200		1,000,000	bps

### 30.10 Timing Specs for Switching Flash Memory Programming Modes

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
How long from when an external reset ends until the initial communication settings are specified	t <sub>SUINIT</sub>	POR and LVD reset must end before the external reset ends.			100	ms
How long from when the TOOL0 pin is placed at the low level until an external reset ends	t <sub>SU</sub>	POR and LVD reset must end before the external reset ends.	10			μs
How long the TOOL0 pin must be kept at the low level after an external reset ends (excluding the processing time of the firmware to control the flash memory)	t <sub>HD</sub>	POR and LVD reset must end before the external reset ends.	1			ms



- <1> The low level is input to the TOOL0 pin.
- <2> The external reset ends (POR and LVD reset must end before the external reset ends.).
- <3> The TOOL0 pin is set to the high level.
- <4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

**Remark** t<sub>SUINIT</sub>: The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the resets end.

t<sub>SU</sub>: How long from when the TOOL0 pin is placed at the low level until an external reset ends

t<sub>HD</sub>: How long to keep the TOOL0 pin at the low level from when the external and internal resets end (excluding the processing time of the firmware to control the flash memory)